

CRYSTALLOGRAPHIC STUDIES IN THE V-P-AS-O SYSTEM

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ABSTRACT:

The crystal structures of VOP_2SiO_8 , $VO(PO_3)_2$, $V(PO_3)_3$, $(VO)_2P_2O_7$ and $VAsO_5$ have been determined with the help of x-rays, and are compared with the known structures in the V-P-As-O system. All the vanadium atoms in the mixed oxides are octahedrally coordinated and the $V^{+4}O_6$ and $V^{+5}O_6$ octahedra are all characterized by one short vanadyl bond. $V^{+3}O_6$ groups are nearly regular. The tetrahedral phosphorus is found in structural elements ranging from infinite metaphosphate chains ($V(PO_3)_3$, $VO(PO_3)_2$), to pyrophosphate groups ($(VO)_2P_2O_7$) to isolated tetrahedra ($VAsO_5$ and VOP_2SiO_8). Both structural and substitutional disordering is evident in the V-P-As-O system, and is discussed together with a detailed model for stacking faults in $VAsO_5$.

Some of the phases in the V-P-As-O system are known to catalyze the oxidation of butene to maleic anhydride, and certain structural features of the compounds are related to this catalytic activity. α - VPO_5 can be related to $(VO)_2P_2O_7$ through the formation of shears in a manner similar to shear formation in V_2O_5 , and such a mechanism is proposed as a means whereby an α - VPO_5 catalyst can change into $(VO)_2P_2O_7$, the known composition of the spent catalyst.

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CHAPTER 1

Introduction

§ 1.1 Scope and Perspective

Vanadium oxides and vanadium phosphorus oxides are known to act as heterogeneous catalysts in certain organic reactions such as the oxidation of butene to maleic anhydride¹. Such catalysis must depend on the crystal structures of these oxides and a study of their crystallography is therefore essential in order to understand the mechanism of the catalytic processes.

The crystal structures of most vanadium oxides are known²⁻¹⁰ and will be briefly reviewed. The crystal structures of three vanadium phosphorus oxides, $V^{+4}O(PO_3)_2$, $V^{+3}(PO_3)_3$ and $(V^{+4}O)_2P_2O_7$, will be presented and compared to the known crystal structures of the two forms of VP_2O_7 ^{11,12}. Many oxide catalysts are supported on silica gel and the crystal structure of $V^{+4}OP_2SiO_8$, readily formed from $VO(P_2O_7)_2$ and SiO_2 , will be described in order to determine the possible influence of a supporting medium. The question of possible substitution of arsenic for phosphorus in some of the phases of the V-P-O system will be raised, and the crystal structure of $V^{+5}AsO_5$ will be presented as well as evidence for a solid solution of the form $VP_xAs_{1-x}O_5$ over the range $0 \leq x \leq 1$. Certain features of these structures will be related to catalytic activity.

§ 1.2 The Vanadium Oxides

Systems containing vanadium and oxygen form a very diverse series of compounds. Not only can the vanadium exist in different oxidation

states, it is also found in a variety of coordinations. Pentavalent vanadium can be found tetrahedrally coordinated in isolated tetrahedra (i.e. the VO_4 tetrahedra are not connected to other VO_4 groups), but in vanadium oxides this coordination is usually found in infinite corner-sharing metavanadate chains, $(VO_3)_\infty$, (fig.1-1(a)) (e.g. $NaVO_3$ ¹³) and in pyrovanadate groups, $V_2O_7^{-4}$, (fig.1-1(b)) consisting of two corner-sharing tetrahedra (e.g. $Zn_2V_2O_7$ ¹⁴). Both V^{+5} and V^{+4} can exist in 5-fold and octahedral coordination. These groups usually have one V-O bond, often called the vanadyl bond, which is shorter than the other V-O bonds in the group, and which distorts the idealized polyhedral symmetry. The V-O bond trans to the vanadyl bond is generally very long (octahedral coordination, fig.1-1(c)), or missing (5-fold coordination, fig. 1-1(d)). This long bond is often formed to a vanadyl oxygen in another polyhedron. Trivalent vanadium also exists in octahedral coordination, but does not usually have the vanadyl geometry, the octahedra being nearly regular (fig. 1-1(e)). The 5 or 6-fold coordination polyhedra can be found isolated or condensed in 1,2, or 3 dimensions.

Dickens and Wiseman¹⁵ have reviewed the crystallography of oxide bronzes and related mixed valence oxides, and the crystallography of the vanadium oxides can best be described using their terminology. VO_6 octahedra can be found in corner-sharing chains (fig.1-2(a)), edge-sharing chains (rutile chains, fig.1-2(c)), or double chains composed of two edge-sharing octahedra sharing corners with two adjacent sets of edge-sharing octahedra (fig.1-2(b)). Adjacent octahedra can also share edges in a zigzag pattern to form a single ribbon as shown viewed from three perpendicular directions in figure 1-3(a). Double ribbons can be

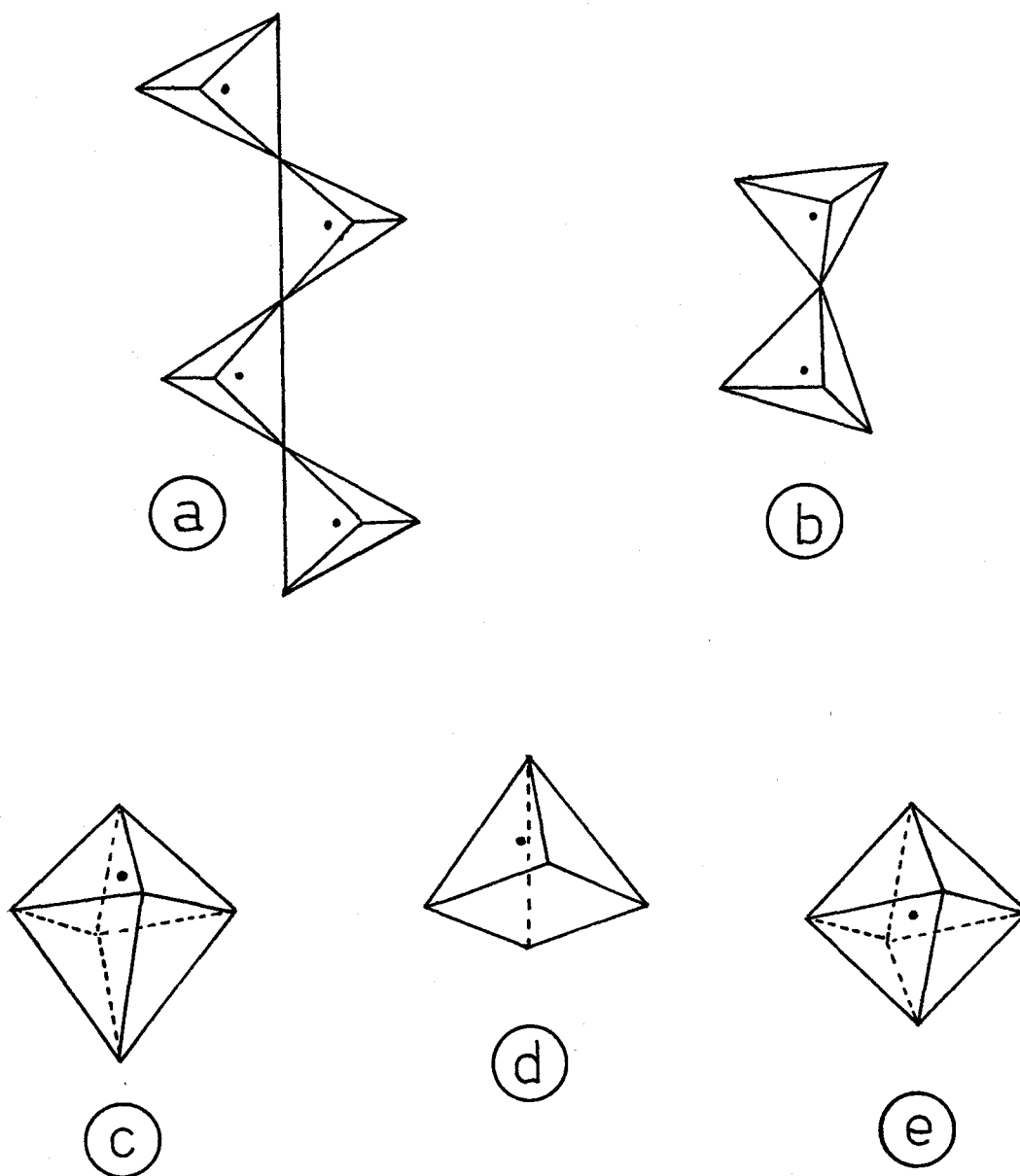


Figure 1-1. Structural elements found in vanadium oxides. The unconnected dot represents the position of the vanadium atom, and oxygen atoms are found at the apices of the polyhedra.
 (a) metavanadate chain, (b) pyrovanadate group,
 (c) octahedron with short vanadyl bond, (d) 5-fold coordinate group with vanadyl bond, (e) regular octahedron.

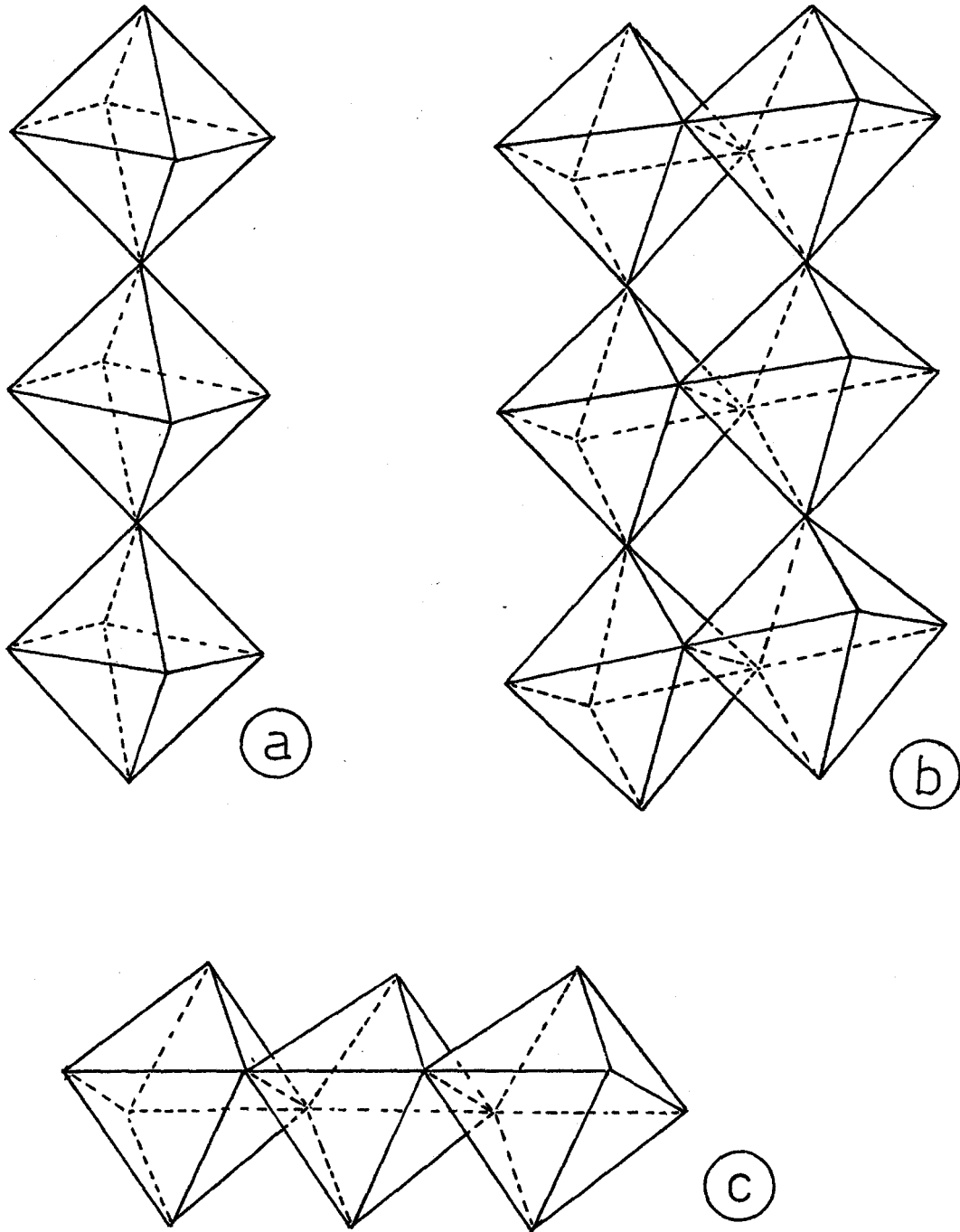


Figure 1-2. (a) Single corner-sharing octahedral chain
(b) Double corner-sharing octahedral chain
(c) Edge-sharing or rutile octahedral chain

formed by two such single ribbons sharing edges as shown in figure 1-3(b). If parallel adjacent single ribbons share corners they can form single sheets as shown head-on in figure 1-4(a). In a similar fashion double ribbons can share edges to form double sheets (figure 1-4(b)) or corners to form zig-zag sheets (fig. 1-4(c)).

Most vanadium oxides can be considered members of the series $V_n O_{2n+1}$ or $V_n O_{2n-1}$ with $n=2,3,4,6$ for the former and $n=2-7$ for the latter. VO_2 is one important vanadium oxide which does not fall in either of these series but bridges the two. Most of these oxides are mixed oxidation state compounds and, while it is often possible to assign integer oxidation numbers to individual vanadium atoms using the bond-valence parameters of Brown¹⁶, some V atoms appear to have partial valences.

V_2O_5 , the first member of the $V_n O_{2n+1}$ series, is known to exist in two polymorphic forms. α - V_2O_5 ², stable under ordinary conditions, consists of single octahedral sheets (fig.1-4(a)) stacked so that the vanadyl oxygens within one sheet form the long axial V-O bonds of the octahedra in an adjacent sheet. β - V_2O_5 ¹⁷, found at high pressures, consists of zig-zag sheets (fig.1-4(c)) which are not noticeably bonded together and thus readily slip to introduce stacking faults, giving rise to diffuse scattering in the diffraction pattern.

V_3O_7 ³ contains alternating double (fig.1-2(b)) and single (fig.1-2(a)) corner-sharing chains which are linked to each other at the corners by single ribbons (fig.1-3(a)). The single ribbons are essentially 5-fold rather than octahedrally coordinated.

V_4O_9 ⁴ contains single ribbons (fig.1-3(a)) which link to each other and to double ribbons (fig.1-3(b)). Like V_3O_7 , the polyhedra of the single

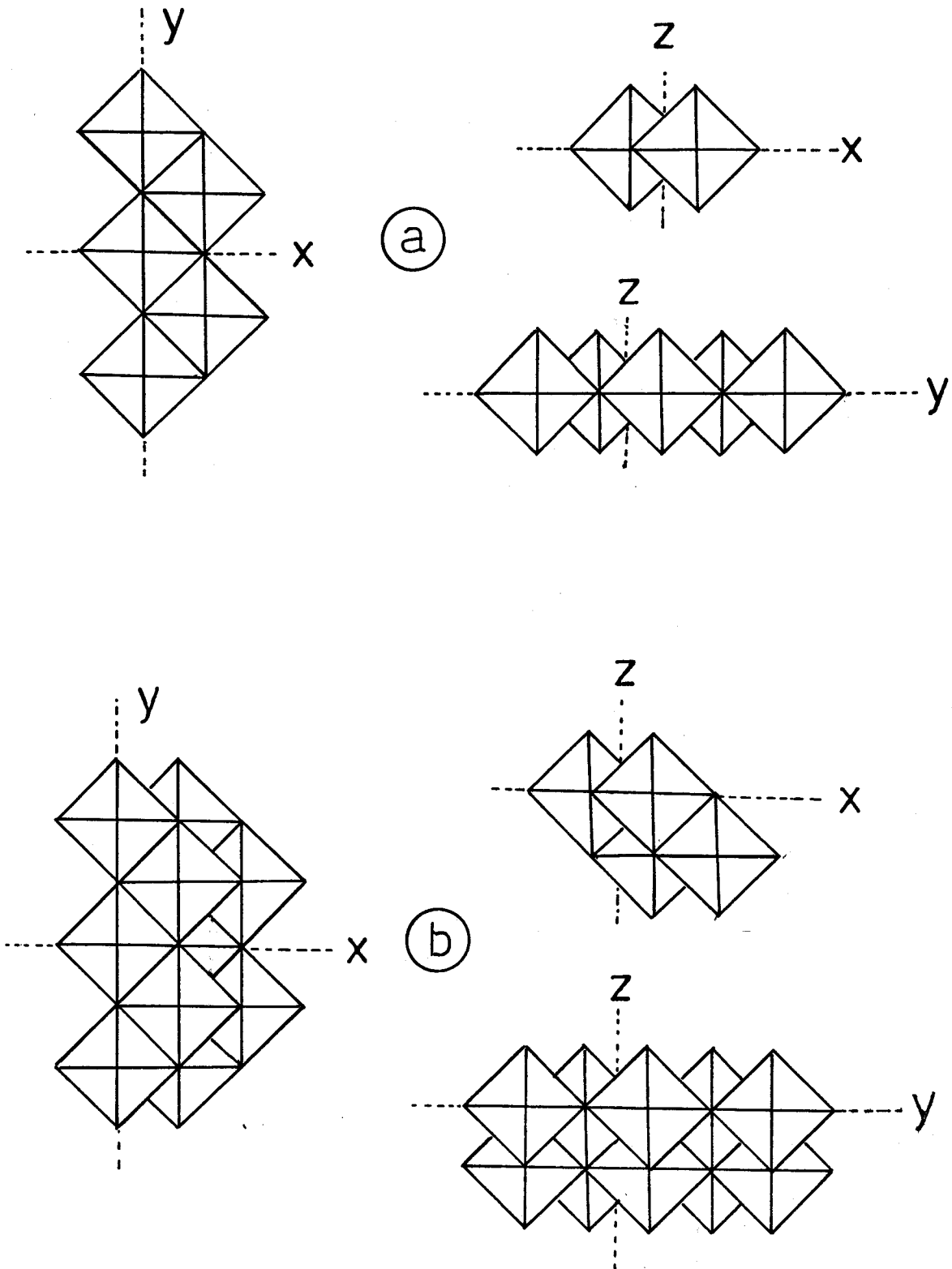


Figure 1-3. (a) Single octahedral ribbons and (b) Double octahedral ribbons as viewed from three perpendicular directions.

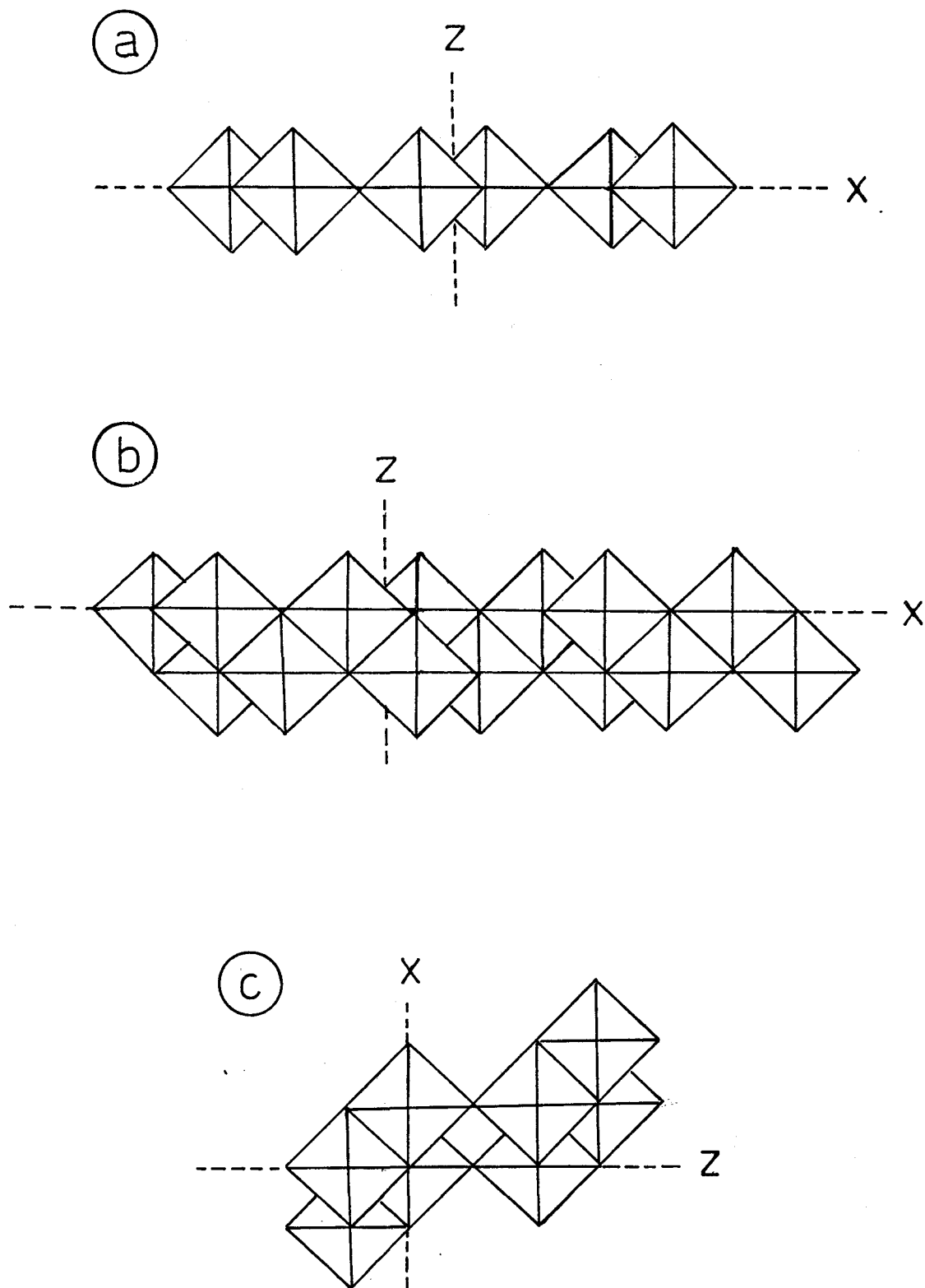


Figure 1-4. (a) Single octahedral sheet
(b) Double octahedral sheet
(c) Zig-zag octahedral sheet

ribbons are 5-fold coordinated. A second form of V_4O_9 has been reported¹⁸ but its structure is unknown.

The last structure of the V_nO_{2n+1} series, V_6O_{13} ⁵, contains alternating single (fig.1-4(a)) and double sheets (fig.1-4(b)) sharing corners at the vanadyl oxygens of the double sheets.

Vanadium dioxide, VO_2 , exists in at least two polymorphic forms. One structure consists of double sheets (fig.1-4(b)) sharing corners at the vanadyl oxygens of one sheet⁶, and is thus related to the V_nO_{2n+1} series. The other form is a distorted rutile structure containing edge-sharing (fig.1-2(c)) octahedral chains connected by corner-sharing⁷. As will be seen, this form is related to the V_nO_{2n-1} series.

The V_nO_{2n-1} ^{8,9,10} structures contain two parts. A corundum type structure, containing two octahedra sharing a face and each sharing an edge with neighbouring octahedra, is joined to the next corundum part by rutile chains. The length of the chains depends on n. When n=2, these chains are not present⁸, and they increase monotonically in length as n increases from 3^{9,10}. VO_2 ⁷ contains only rutile chains and may be regarded as a structure where $n \rightarrow \infty$.

Vanadium bronzes are compounds which in general have formulae $M_xV_yO_z$ where M is a metal, y and z are integers and x can be non-integral. The average oxidation state of the vanadium for particular y and z values changes over a range of x values without changing the basic structure. These bronzes have structural features similar to those of the vanadium oxides. $\gamma\text{-Li}_xV_2O_5$ ¹⁹ has $\alpha\text{-V}_2O_5$ -like octahedral sheets, $\delta\text{-Ag}_xV_2O_5$ ²⁰ has the double sheets seen in VO_2 , and $\theta\text{-Al}_xV_2O_5$ ²¹ has alternating single and double sheets as in V_6O_{13} . $\beta\text{-Na}_xV_6O_{15}$ ²² has double octahedral ribbons

sharing one corner each with two neighbouring double ribbons and being bridged to two more double ribbons by single ribbons. $\text{Li}_x\text{V}_3\text{O}_8^{23}$ has alternating single and double ribbons.

§ 1.3 The Phosphorus Oxides

Like vanadium, phosphorus exhibits multiple valences, but the P^{+5} form is the most stable form and does not reduce readily. Pentavalent phosphorus is only found tetrahedrally coordinated, but the tetrahedra can link to produce a variety of structural elements. As is the case for V^{+5}O_4 tetrahedra, P^{+5}O_4 groups can share corners to produce infinite metaphosphate chains (e.g. NaPO_3^{24}) and pyrophosphate groups (e.g. $\text{Zn}_2\text{P}_2\text{O}_7^{25}$). Rings of corner-sharing tetrahedra are also prevalent (e.g. $\text{Na}_3\text{P}_3\text{O}_9^{26}$ has rings of three phosphate groups, and $\text{Na}_4\text{P}_4\text{O}_{12}^{27}$ has rings of four phosphate groups). Substitution of vanadium for phosphorus (and vice versa) might be expected to occur in compounds where the coordination is tetrahedral. However, since the vanadium oxides have vanadium in 5-fold or octahedral coordination, the phosphorus oxides, or mixed phosphorus-vanadium oxides, are expected to have different structures from the corresponding vanadium oxides.

Phosphorus pentoxide exists in three crystalline forms. The H-Form²⁸ is the most common and contains four phosphate tetrahedra each of which shares a corner with each of the other three tetrahedra to form discrete P_4O_{10} groups of tetrahedral symmetry. The O-Form²⁹ contains rings of ten phosphate tetrahedra linked in a three-dimensional network. The O'-Form³⁰ contains sheets of linked six-membered rings.

§ 1.4 The Arsenic Oxides

Like phosphorus and vanadium, arsenic displays variable oxidation

states, but is most commonly found in the +5 state. Pentavalent arsenic is found tetrahedrally in structural elements similar to those of phosphorus. Meta-arsenate chains can be found in NaAsO_3 ³¹, rings in $\text{K}_3\text{As}_3\text{O}_9$ ³², and pyroarsenate groups in $\text{Mg}_2\text{As}_2\text{O}_7$ ³³. As^{+5} is also found octahedrally coordinated, but, unlike vanadium, the octahedra are usually quite regular and contain no bond analogous to the vanadyl bond. The AsO_6 octahedra are not found as highly condensed as the VO_6 octahedra, corner-sharing being the prevalent mode of joining neighbouring AsO_6 groups.

Although the crystal structure of hydrated arsenic pentoxide has been known for some time³⁴, the structure of anhydrous As_2O_5 has only been determined very recently³⁵. It consists of zig-zag chains of corner-sharing AsO_6 octahedra which are joined to neighbouring chains by AsO_4 tetrahedra in such a way that each tetrahedron shares corners with two octahedra in each of two chains. This intricate arrangement avoids edge-sharing polyhedra by having both tetrahedral and octahedral coordinations present. Both kinds of polyhedra are quite regular in shape.

§ 1.5 The V-P-As-O System

Pentavalent P, V and As can all be found tetrahedrally coordinated, and substitution of P^{+5} for V^{+5} in NaVO_3 ³⁶ and As^{+5} for P^{+5} in NaPO_3 ³⁷ has been found. However, substitution of one for any other does not often occur. This can be due to the preferred octahedral and 5-fold coordination of V^{+5} , thereby preventing P substitution, and the abundance of condensed octahedra and of vanadyl groups found for V and not for As. Mixed oxides can usually be expected to have different crystal structures from the single oxides of V, P and As, although to date very little is known about them.

In the early sixties, Nador³⁸ investigated the $V_2O_5-P_2O_5$ system and concluded that, on melting mixtures of these oxides, oxygen is liberated and some vanadium is reduced from V^{+5} to oxidation states of +4 and +3. A study of the electron spin resonances of samples with different stoichiometries allowed him to conclude that the $V_2O_5-P_2O_5$ system consisted of a single two-component system and two three-component systems with upper and lower boundaries as shown in figure 1-5. The boundaries established the existence of $(VO)_2P_2O_7$ and $V(PO_3)_3$, but no indication was given about the composition of other phases.

Ladwig³⁹ also noticed a reduction of all forms of $V^{+5}PO_5$ (formed from a 1:1 mixture of V_2O_5 and P_2O_5) at temperatures greater than $700^\circ C$, forming a V^{+4} compound. This observation was recently verified by Bordes and Courtine⁴⁰ and the reduction product was identified as $(VO)_2P_2O_7$. Bordes and Courtine⁴⁰ established the presence of $P_2O_7^{-4}$ and vanadyl groups in this compound from IR and UV spectra. The reduction of VPO_5 is contrary to the observations of Jordan and Calvo¹¹, who report no appreciable mass loss of $\alpha-VPO_5$ up to $1140^\circ C$, well beyond its melting point.

VPO_5 itself is found in several forms and has been rather extensively studied. The structures and properties of $\alpha-VPO_5$ ^{11,39,41}, $\beta-VPO_5$ ^{12,39,41} and the hydrates of VPO_5 ^{39,41} have all been reported. Since these compounds are fundamental to the V-P-As-O system, they will be briefly described.

The structure of $\alpha-VPO_5$ ¹¹ consists of layers containing alternating corner-sharing VO_6 octahedra and PO_4 tetrahedra (fig.1-6). The VO_6 octahedra contain the typical vanadyl oxygens perpendicular to the plane of figure 1-6, which form long bonds to VO_6 groups in the next layer. This is the only connection between layers. The layers may be disordered by

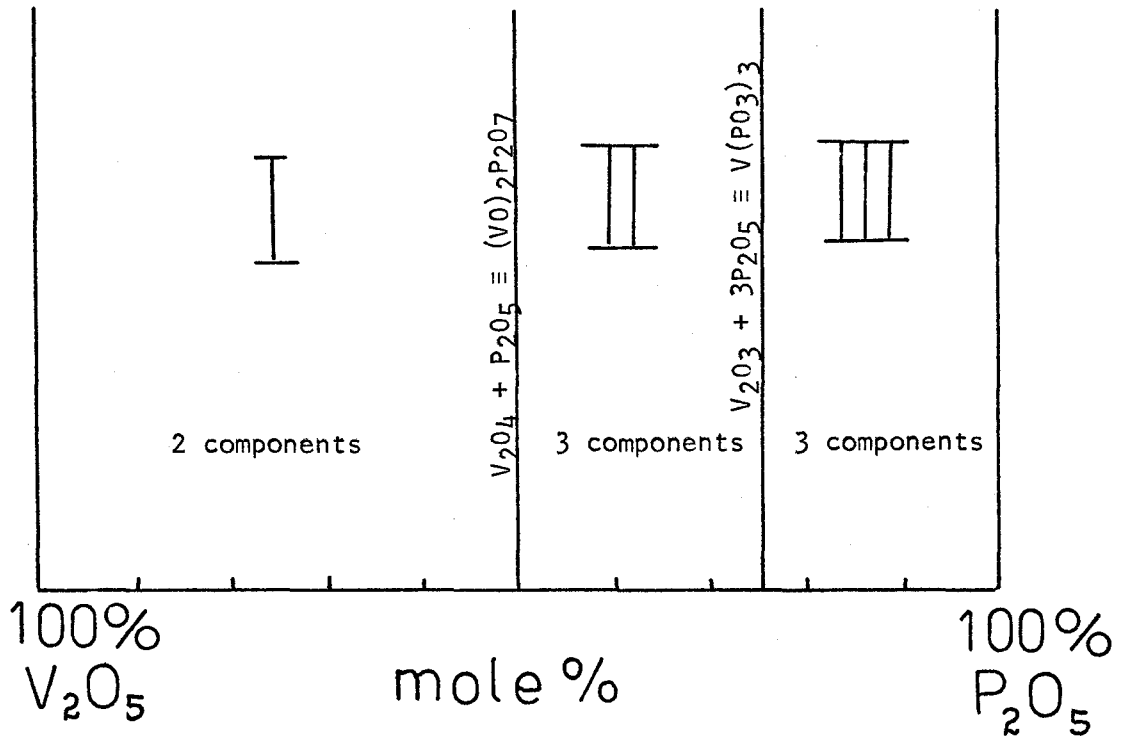


Figure 1-5. Regions in the vanadium phosphorus oxide system as proposed by Nador³⁸.

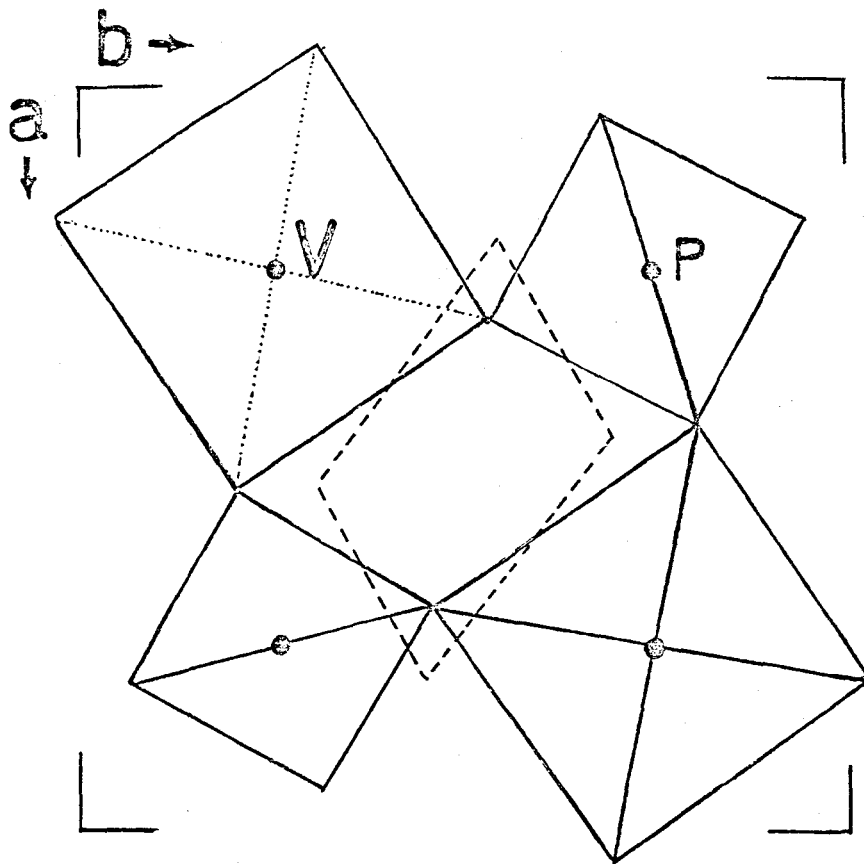


Figure 1-6. The crystal structure of $\alpha\text{-VP}_5\text{O}_{15}$ as projected down the c -axis. The disordered positions of the oxygens are at the apices of the dashed parallelogram.

a slight rotation about the direction of the vanadyl bonds as indicated in figure 1-6 by the dashed lines. Because of the layered structure, crystals of α -VPO₅ grow in mica-like sheets. Evidence for some vanadium substitution at the phosphorus site has been found⁴².

β -VPO₅¹² (figure 1-7) contains chains of VO₆ octahedra parallel to a arranged with the vanadyl oxygen of one group forming the long axial V-O bond of the next group. The pseudo 4-fold axes of the VO₆ groups are alternately tilted by +30° and -30° with respect to the direction of the chain. This tilting makes it possible for a phosphate group to share an oxygen with each of two VO₆ octahedra in one chain. The other two phosphate oxygens are shared with a VO₆ group in each of two other chains.

Ladwig³⁹ has described the production of VPO₅.2H₂O from a V₂O₅-phosphoric acid mixture and has shown that, on heating it slowly, VPO₅.H₂O is formed at 60-80°C and at 150°C α -VPO₅ is formed. He also noticed an expansion of the c-axis of α -VPO₅ on hydration. This led him to conclude that the structure of the hydrates must be the layered structure of α -VPO₅ with water molecules interstitially between the layers. No hydrates are known to form from β -VPO₅, nor is there any evidence for an $\alpha \rightarrow \beta$ transition.

A preparation for V⁺⁴O(PO₃)₂, its blue colour and its insolubility in most solvents were reported by Ladwig⁴³ in 1968. Preparations for this compound and V(PO₃)₃ have also been reported recently and separately by Lavrov, et al.⁴⁴ and Tofield, et al.⁴⁵. From IR data, Lavrov concluded that VO(PO₃)₂ is a metaphosphate and Tofield interpreted the diffuse transmission spectrum to show the existence of vanadyl groups. Both conclude V(PO₃)₃

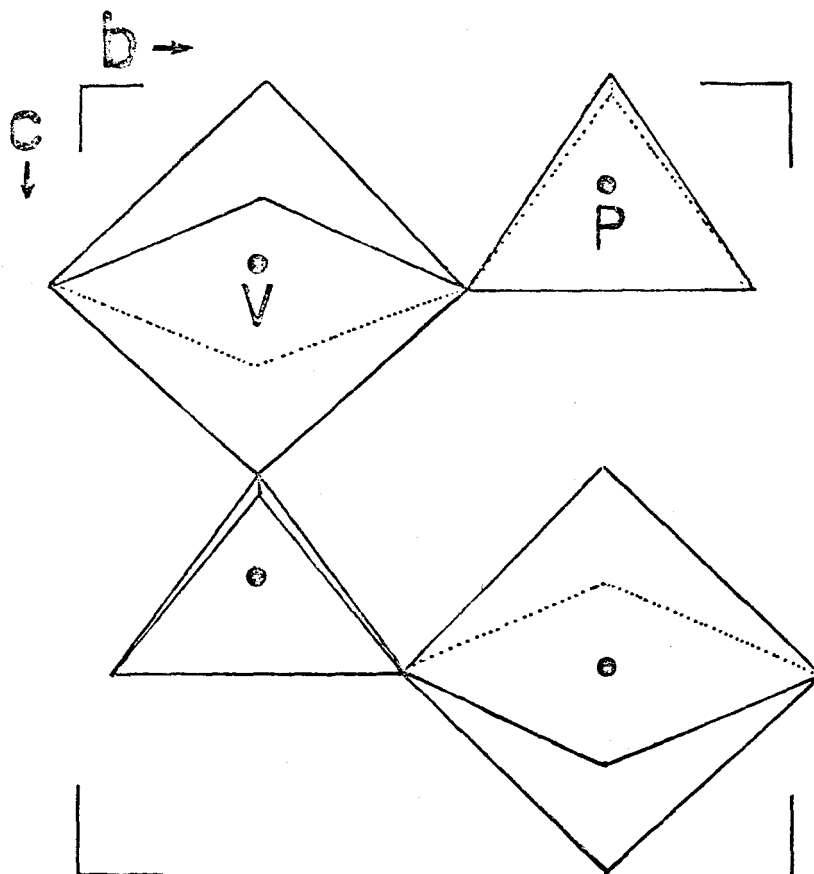


Figure 1-7. The crystal structure of $\beta\text{-VPO}_5$ projected down the a -axis. The second half of the cell can be generated from the one shown by a centre of symmetry at $(\frac{1}{2}, \frac{1}{2}, \frac{1}{2})$.

contain metaphosphate chains.

The crystal structure of VOP_2SiO_8 was solved independently by ourselves and Rice,et al⁴⁶ but their work appeared in print prior to ours⁴⁷.

Very little is known about the crystalline vanadium arsenic and phosphorus arsenic oxides. The existence of $VAsO_5$ and its hydrate has been reported^{48,49}, and a powder pattern of the anhydrous material appears to be the same as that of α - VPO_5 . No other vanadium arsenic oxides are known. Crystals of the form $As_xP_{2-x}O_5$ have been studied⁵⁰ and were found to be isostructural with As_2O_5 for $1 \leq x \leq 2$ from powder data.

§ 1.6 Reduction of Vanadium Oxides

V_2O_5 consists of single octahedral sheets, V_6O_{13} consists of alternating single and double octahedral sheets, and VO_2 consists of double octahedral sheets. If one sheet in the V_2O_5 structure is cooperatively moved along a shear plane as in figure 1-8(a), then a double sheet will be formed. By this mechanism, geometrically at least, conversion of V_2O_5 into V_6O_{13} ⁵¹ (fig.1-8(b)) can be accomplished by moving every third sheet of V_2O_5 in such a fashion, and conversion into VO_2 can be accomplished by moving every second sheet along the shear plane. Studies have been done to determine if such a reduction mechanism does in fact occur. Electron microscope studies, whereby carbon is deposited on the surface of a crystal and is thus capable of aiding reduction by forming CO and CO_2 , have failed to show VO_2 production from V_2O_5 , but have confirmed the conversion of V_6O_{13} into VO_2 ⁵² and a cooperative movement of octahedra as depicted in figure 1-9 has been suggested for the mechanism of this reduction. The reduction of V_2O_5 to V_6O_{13} under these conditions has been the subject of some controversy. Fiermans and Vennik⁵³ have noted

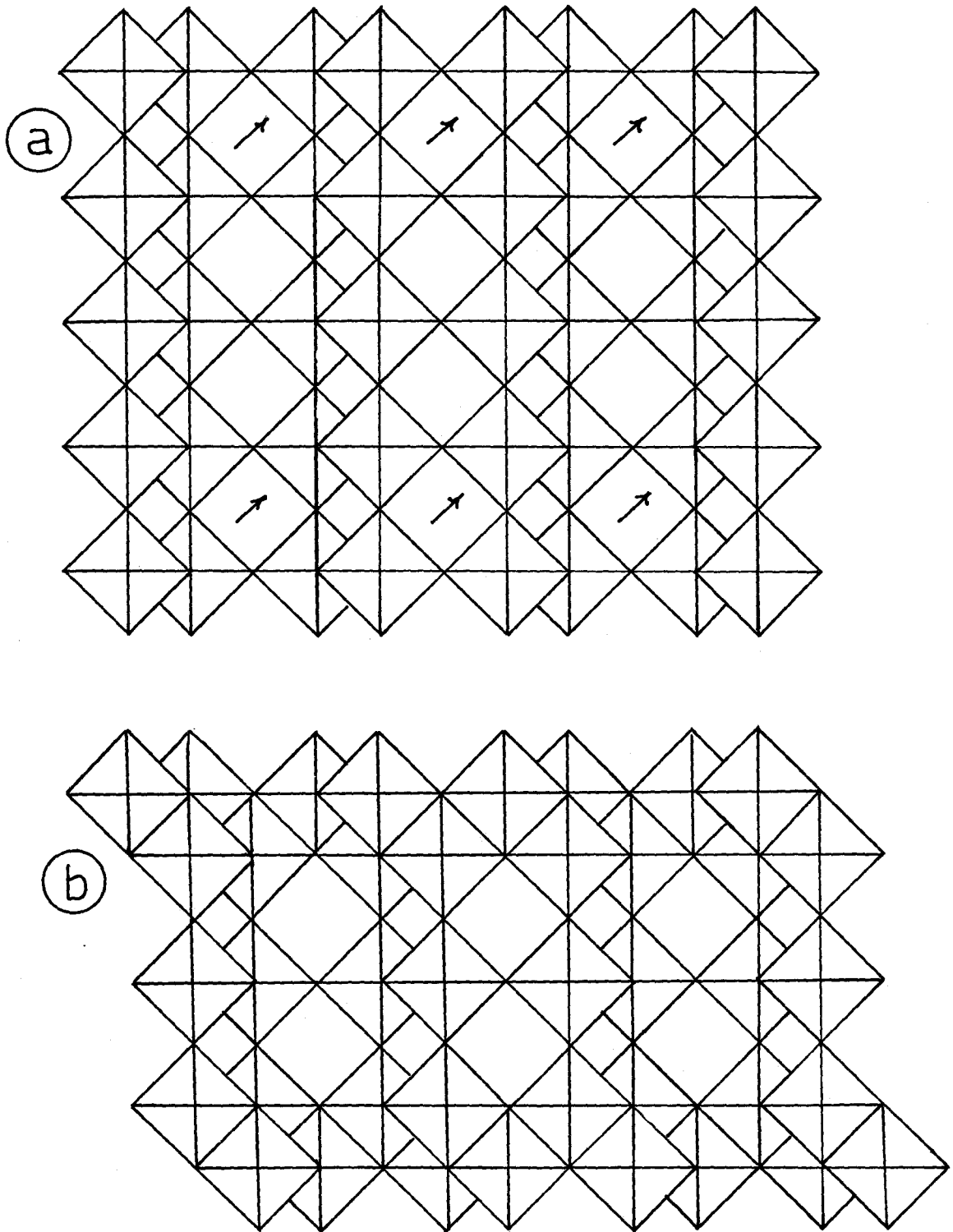


Figure 1-8. Schematic diagram of $V_{2,0_5}$ (a) forming $V_{6,0_{13}}$ (b) by a shear in the direction indicated by the arrows.

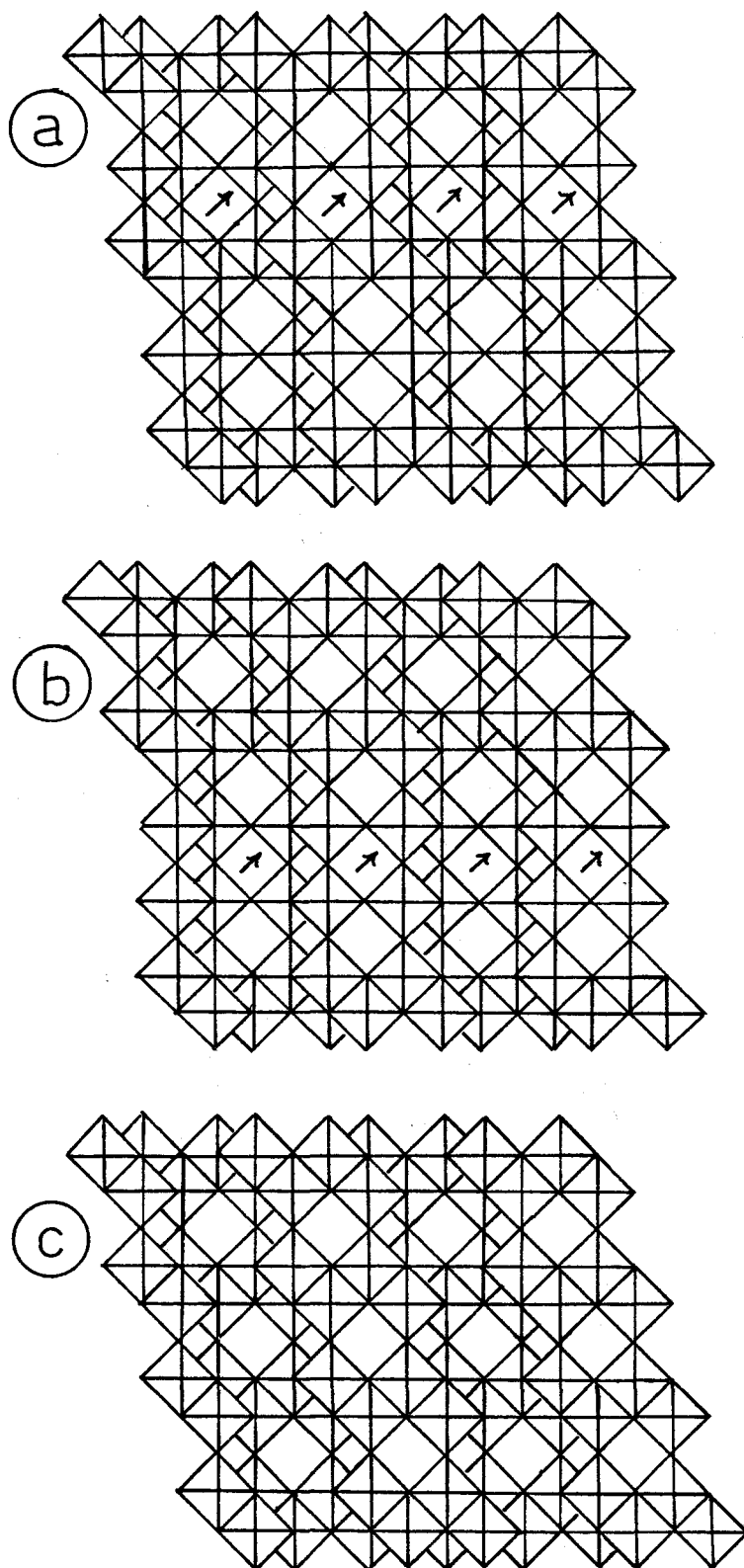


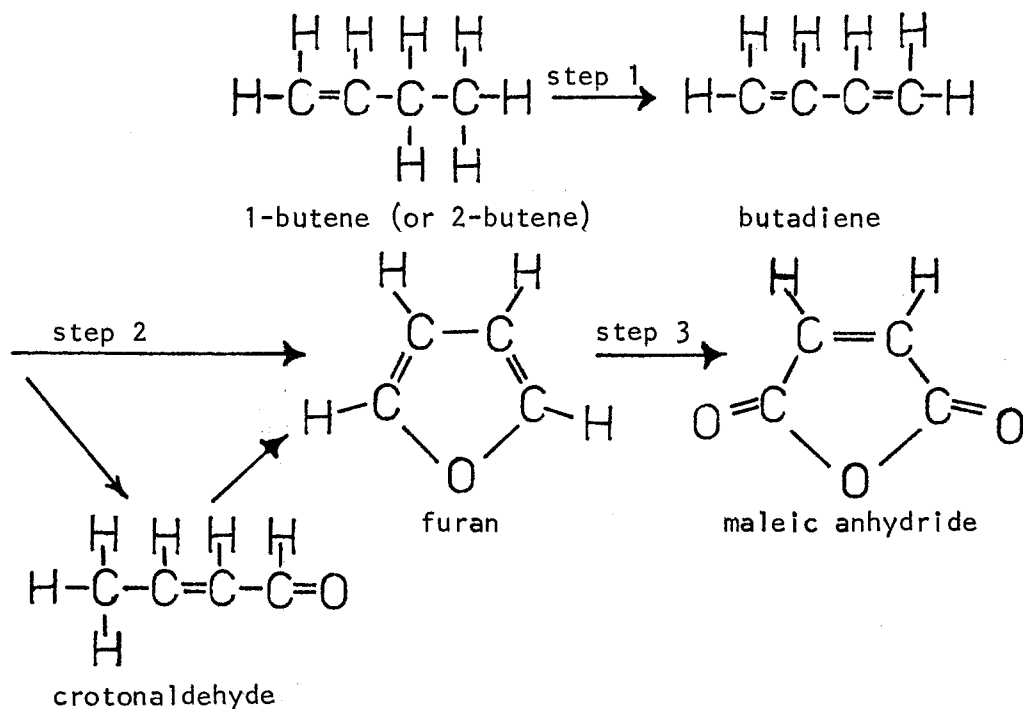
Figure 1-9. Formation of VO_2 (c) from V_6O_{13} (a) through the cooperative movement of octahedra ((a) and (b))

and studied this transition by low energy electron diffraction, but Tilley and Hyde⁵⁴ have found no evidence for such a shear using transmission electron microscopy. These authors did find a reduced vanadium oxide phase produced which was later identified as a new V_4O_9 phase by Grymonprez¹⁸, et al.

The possibility of V_2O_5 and V_6O_{13} reducing through the formation of shear structures and/or vacancy formation appears likely but has not been conclusively established. In each of the cases studied, the vanadyl oxygen is the oxygen which is removed. This is exactly the mechanism which is suggested for the action of a V_2O_5 catalyst in the oxidation of hydrocarbons by Sachtler⁵⁵ to account for the production of V^{+4} in spent catalysts. He suggested that the vanadyl oxygens exposed on the surface of V_2O_5 were removed during the catalytic process. The vacancies so created can diffuse into the bulk of the V_2O_5 catalysts. This is an easy process since the $V^{+4}O_5$ groups so established can have many configurations. When the vacancies are at the appropriate oxygen sites for a shear to occur, the V_6O_{13} configuration is formed. Although no direct structural evidence is available, there is evidence that the vanadium is reduced in the catalytic process and that the vanadyl oxygen is released^{56,57}.

§ 1.7 Vanadium Phosphate Catalysts

A great number of patents in the US, Japan, and Germany exist for the use of vanadium phosphate catalysts in the commercial production of maleic anhydride from butene, butane and other hydrocarbons, but very little academic literature is available. The oxidation of butene (either 1-butene or 2-butene) over vanadium phosphates is thought to proceed by the following steps^{58,59,60}.



Seeboth et al.^{59,60} found that crotonaldehyde was often an intermediate in step 2 as shown above.

Ai⁵⁸ found that, although the activity (i.e. the number of sites active in catalysis) decreased from pure vanadium oxide catalysts to vanadium phosphates, the selectivity of the butene \rightarrow maleic anhydride reaction (or the preferred production of the desired product rather than side-products) increased with phosphorus content. This has also been observed by several other workers^{40,56,59,61}. Ai considered each step in the reaction and found that phosphorus addition increased the selectivity in step 1 and step 2 and decreased it in step 3.

Ai and Suzuki⁶² found that the affinity of V_2O_5 catalysts for basic (i.e. electron donating) olefins decreases with P_2O_5 content, and hence the acid strength of vanadium phosphate catalysts must be smaller than that of V_2O_5 . They suggest that this lower acid strength enhances the probability of maleic acid production rather than side-products such

as acetic acid, acetaldehyde and carbon dioxide.

VPO_5 , when used as a catalyst, reduces to $(V^{+4}O)_x(V^{+5}O)_{1-x}PO_{4-x/2}$ ^{40,59,60} with the end-product being $VOPo_{3.5} \equiv (VO)_2P_2O_7$. Bordes and Courtine⁴⁰ found that on slow heating of VPO_5 to around 750°C, a metastable intermediate, $VPO_{4.75}$, was formed which reduced on further heating to $VPO_{4.5}$. In addition, both α and β - VPO_5 were found to reduce to $VPO_{4.5}$, but only α - VPO_5 was formed on re-oxidation.

Nakamura⁶¹ found that the yield of a catalyzed reaction decreased rapidly as the average oxidation number of the vanadium became less than 4.0. He concluded that the redox cycle between V^{+5} and V^{+4} is mainly responsible for the catalysis, and that the vanadyl bond was important in the process. He suggested a mechanism whereby oxygen from the air would add to the vanadium at the side opposite the vanadyl bond, thereby forming a sixth oxygen bond which is available for oxidation of the butene (fig.1-10). One supposes that at the surface the long V-O bond is missing, a not unreasonable assumption since charge conservation would require something of this sort. This mechanism was suggested for the P:V = 2:1 catalyst since Nakamura found it to be the most selective. Bordes and Courtine⁴⁰ however, found that $VO(PO_3)_2$ was not catalytically active.

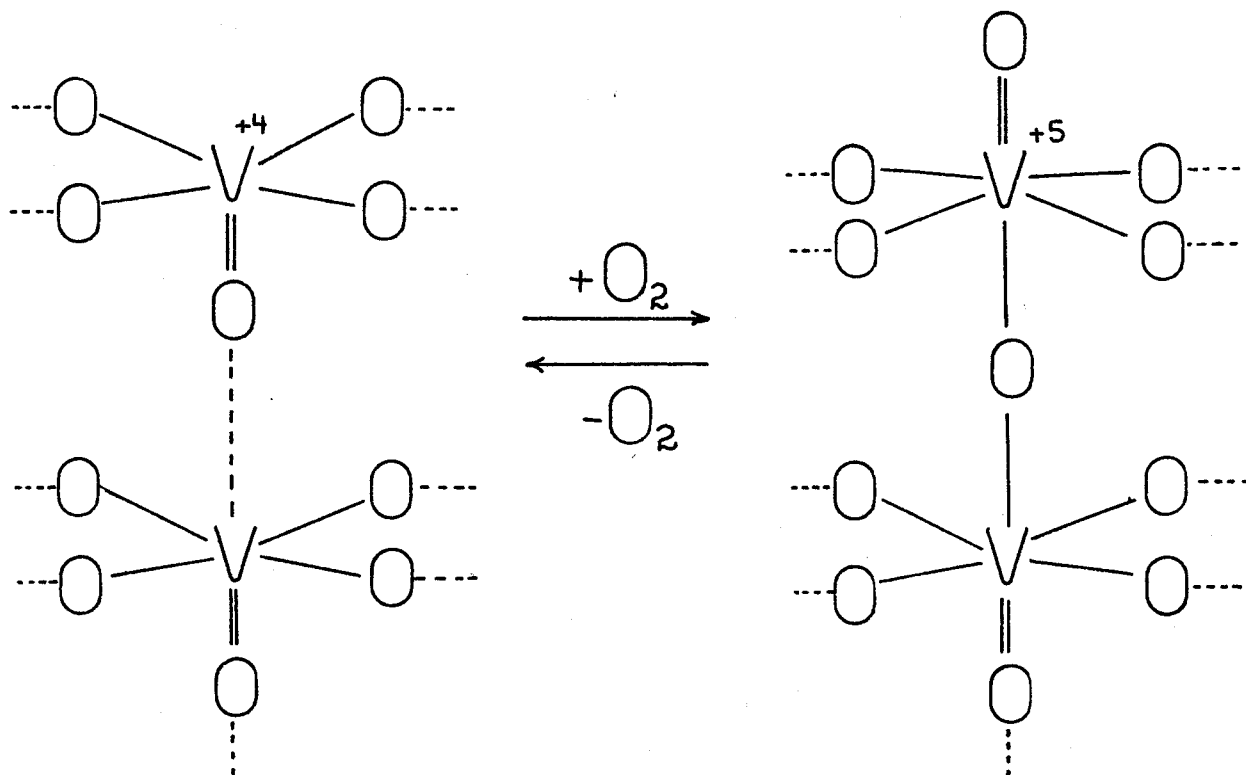


Figure 1-10. Redox mechanism occurring during catalysis using a vanadium phosphate catalyst as suggested by Nakamura⁶¹. The equatorial oxygen atoms are bonded to vanadium and phosphorus atoms. The axial atoms are only bonded to vanadium.

CHAPTER 2

The Theory of X-Ray Diffraction

§ 2.1 Scattering of X-Rays

X-rays fall in the short wavelength, high energy region of the electromagnetic spectrum, and, like all electromagnetic radiation, can be scattered from matter inelastically (Compton scattering) with a change in wavelength or elastically, without a change in wavelength. It is the elastic scattering that enables one to determine crystal structures.

Many good books have been written describing the theory of x-ray scattering^{*}; only the main ideas and those particularly relevant to this thesis will be summarized here.

If we consider an incident x-ray wave of wave-vector \underline{k}_0 scattered elastically from an electron at an arbitrary origin and one at a distance \underline{r} away, the amplitude of the resultant wave-vector \underline{k} will be proportional to $\exp(i\Delta\underline{k}\cdot\underline{r})$ where $\Delta\underline{k} = \underline{k}_0 - \underline{k}$. If instead the scattering occurs from an electron distribution with electron density $\rho(\underline{r})$, then the resulting amplitude will be

$$A(\Delta\underline{k}) = \int \rho(\underline{r}) \exp(i\Delta\underline{k}\cdot\underline{r}) dV, \quad (2-1)$$

where the integral is over the volume containing the charge density.

An ideal crystal has three-dimensional translational symmetry. If the repeating unit, i.e. the unit cell, is defined by the vectors \underline{a} , \underline{b} and \underline{c} , then for an ideal crystal, the electron density at a point \underline{r} is $\rho(\underline{r}) = \rho(\underline{r} + x\underline{a} + y\underline{b} + z\underline{c})$ for all integers x, y and z . Using this relationship,

^{*} see for example books by Zachariasen⁶³, Cowley⁶⁴, James⁶⁵ or Warren⁶⁶.

the amplitude in equation 2-1 now becomes, for an ideal crystal,

$$A(\underline{\Delta k}) = \sum_{xyz} \exp(i\underline{\Delta k} \cdot \underline{R}) \int_{u.c.} \rho(\underline{r}) \exp(i\underline{\Delta k} \cdot \underline{r}) dV, \quad (2-2)$$

where $\underline{R} = x\underline{a} + y\underline{b} + z\underline{c}$, and the integration is carried out over the volume of the unit cell, and the sum is over the dimension of the crystal.

For a crystal containing N_x , N_y and N_z unit cells in the x, y and z directions,

$$\begin{aligned} \sum_{xyz} \exp(i\underline{\Delta k} \cdot \underline{R}) &= \sum_{x=1}^{N_x} \exp(i\underline{\Delta k} \cdot x\underline{a}) \sum_{y=1}^{N_y} \exp(i\underline{\Delta k} \cdot y\underline{b}) \sum_{z=1}^{N_z} \exp(i\underline{\Delta k} \cdot z\underline{c}) \\ &= \frac{(1 - \exp(iN_x \underline{\Delta k} \cdot \underline{a}))}{(1 - \exp(i\underline{\Delta k} \cdot \underline{a}))} \cdot \frac{(1 - \exp(iN_y \underline{\Delta k} \cdot \underline{b}))}{(1 - \exp(i\underline{\Delta k} \cdot \underline{b}))} \cdot \frac{(1 - \exp(iN_z \underline{\Delta k} \cdot \underline{c}))}{(1 - \exp(i\underline{\Delta k} \cdot \underline{c}))}. \end{aligned} \quad (2-3)$$

The intensity of the scattered wave is

$$\begin{aligned} I &= A(\underline{\Delta k}) A^*(\underline{\Delta k}) \\ &= \sum_{xyz} \exp(i\underline{\Delta k} \cdot \underline{R}) \sum_{xyz} \exp(-i\underline{\Delta k} \cdot \underline{R}) \int_{u.c.} \rho(\underline{r}) \exp(i\underline{\Delta k} \cdot \underline{r}) dV \int_{u.c.} \rho(\underline{r}) \exp(-i\underline{\Delta k} \cdot \underline{r}) dV, \end{aligned} \quad (2-4)$$

where the designation (*) implies the complex conjugate of the expression.

Upon substitution of equation 2-3 into 2-4 and simplification of the sums,

$$\begin{aligned} I &= \int_{u.c.} \rho(\underline{r}) \exp(i\underline{\Delta k} \cdot \underline{r}) dV \int_{u.c.} \rho(\underline{r}) \exp(-i\underline{\Delta k} \cdot \underline{r}) dV \\ &\quad \cdot \frac{\sin^2(\frac{1}{2}(\underline{\Delta k} \cdot N_x \underline{a}))}{\sin^2(\frac{1}{2}(\underline{\Delta k} \cdot \underline{a}))} \cdot \frac{\sin^2(\frac{1}{2}(\underline{\Delta k} \cdot N_y \underline{b}))}{\sin^2(\frac{1}{2}(\underline{\Delta k} \cdot \underline{b}))} \cdot \frac{\sin^2(\frac{1}{2}(\underline{\Delta k} \cdot N_z \underline{c}))}{\sin^2(\frac{1}{2}(\underline{\Delta k} \cdot \underline{c}))}. \end{aligned} \quad (2-5)$$

Because N_x , N_y and N_z are very large numbers, this expression has sharp maxima at

$$\underline{\Delta k} = 2\pi \underline{H} = 2\pi(h\underline{a}^* + k\underline{b}^* + \ell\underline{c}^*), \quad (2-6)$$

where h, k and ℓ are integers and \underline{a}^* , \underline{b}^* and \underline{c}^* are called reciprocal lattice vectors and are defined as:

$$\underline{a}^* = \frac{\underline{b} \times \underline{c}}{\underline{a} \cdot \underline{b} \times \underline{c}} \quad \underline{b}^* = \frac{\underline{c} \times \underline{a}}{\underline{a} \cdot \underline{b} \times \underline{c}} \quad \underline{c}^* = \frac{\underline{a} \times \underline{b}}{\underline{a} \cdot \underline{b} \times \underline{c}}. \quad (2-7)$$

For very large N_x , N_y and N_z , the maxima are so sharp that the intensity is non-zero only for $\underline{k} = 2\pi\underline{H}$, and has a value N^2 where $N = N_x N_y N_z$. This is one formulation of Bragg's law, and shows that x-ray scattering from ideal crystals, rather than being a continuum, consists of a distinct number of "reflections" defined by condition 2-6.

Using Bragg's law, equation 2-2 now becomes

$$\begin{aligned} A(\underline{\Delta k}) &= A(\underline{H}) = N \int_{\text{u.c.}} \rho(\underline{r}) \exp(2\pi i \underline{H} \cdot \underline{r}) dV \\ &= NF, \end{aligned} \quad (2-8)$$

where N is the number of unit cells in the crystal and F , the structure factor, defined as equal to the integral in equation 2-8, is the Fourier transform of the electron density distribution $\rho(\underline{r})$.

In a crystal, the electron density can be considered as the sum of electron densities of individual atoms:

$$\text{i.e. } \rho(\underline{r}) = \sum_j \rho_j(\underline{r}' + \underline{r}_j), \quad (2-9)$$

where \underline{r}_j is the position vector of the centre of the j^{th} atom and \underline{r}' is a vector within this atom. Consequently, the structure factor for a crystal considering the different atoms in the unit cell separately becomes,

$$\begin{aligned} F(\underline{H}) &= \sum_j \int \rho_j(\underline{r}') \exp(2\pi i \underline{H} \cdot (\underline{r}' + \underline{r}_j)) dV \\ &= \sum_j f_j \exp(2\pi i \underline{H} \cdot \underline{r}_j), \end{aligned} \quad (2-10)$$

where the integral is now over the volume of one atom. f_j , the atomic scattering factor, is the Fourier transform of the electron density of the j^{th} atom.

$$f_j = \int \rho_j(\underline{r}') \exp(2\pi i \underline{H} \cdot \underline{r}') dV. \quad (2-11)$$

Atomic scattering factors have been calculated for theoretical free atoms using various types of wave-functions such as Hartree-Fock⁶⁷ and Slater⁶⁸ functions and are tabulated in the literature.

§ 2.2 Space Groups and Crystal Symmetry

Not only do crystals have three-dimensional translational symmetry with respect to the unit cell distances, the atoms within an individual unit cell can also be related by rotational and reflection symmetry. It can be shown⁶³ that all possible combinations of such symmetry operations can be classified in 230 space groups.

Some symmetry operations can restrict the values of h , k and l for the vector \underline{H} for which the intensity has a non-zero value. For example, a body-centred space group has an atom at $x+\frac{1}{2}$, $y+\frac{1}{2}$, $z+\frac{1}{2}$ for every atom at x , y , z . The structure factor for such a space group will be

$$\begin{aligned} F(\underline{H}) &= \sum_j f_j \exp(2\pi i \underline{H} \cdot \underline{r}_j) \\ &= \sum_m f_m \exp(2\pi i (hx+ky+lz)) + f_m \exp(2\pi i (hx+\frac{1}{2}h+ky+\frac{1}{2}k+lz+\frac{1}{2}l)) \\ &= \sum_m f_m \exp(2\pi i (hx+ky+lz)) (1+\exp(2\pi i (\frac{1}{2}h+\frac{1}{2}k+\frac{1}{2}l))), \end{aligned} \quad (2-12)$$

where the sum over m is over pairs of atoms related by body-centred symmetry. The last term in the expression will be zero if $h+k+l \neq 2n$ where n is an integer. Thus if all $h+k+l \neq 2n$ reflections for a particular crystal have zero intensity, that crystal has a body-centred space group.

Sets of reflections with zero-intensity (such as the $h+k+l \neq 2n$ ones for body-centred crystals) are called systematic extinctions. Systematic extinctions can be found for glide planes, screw axes and centering conditions. A careful examination of the systematic extinctions

for a particular crystal will often yield the space group for the crystal, or reduce the possible space groups to two or three that have the same extinctions.

§ 2.3 Deviations from Translational Periodicity

So far, it has been assumed that crystals have perfect translational symmetry in three dimensions. Real crystals in fact deviate from this periodicity in several ways. Atoms vibrate about an equilibrium position (thermal motion), and need not always be in phase with corresponding atoms in other unit cells; certain atoms may randomly occupy one of several possible positions in different unit cells (positional disorder), and sometimes different kinds of atoms may occupy the same position in different cells (substitutional disorder). In addition, unit cells may not be aligned exactly with respect to neighbouring cells. This misalignment can occur between blocks of perfectly aligned cells (mosaic spread), layers of cells (one-dimensional disorder or stacking faults), or chains of cells (two-dimensional disorder). Thermal motion occurs in all crystals. The other kinds of disorder may or may not occur to a significant extent depending on the crystal. Disorders considered in this thesis will be briefly discussed.

(a) Thermal motion

Atoms at any instant in time are located at $\underline{r}^i = \underline{r}_j + \underline{\delta}_j$ where \underline{r}_j is the position vector for the average position of atom j and $\underline{\delta}_j$ is the instantaneous displacement from this position. It is a function of time and of temperature, increasing as the latter increases. The structure factor thus becomes, formally,

$$F(\underline{H}) = \sum_j f_j \exp(2\pi i \underline{H} \cdot (\underline{r}_j + \underline{\delta}_j)), \quad (2-13)$$

and the intensity is

$$\begin{aligned}
 I &= N^2 \sum_{i,j} f_j f_i^* \exp(2\pi i \underline{H} \cdot (\underline{r}_j + \underline{\delta}_j)) \exp(-2\pi i \underline{H} \cdot (\underline{r}_i + \underline{\delta}_i)) \\
 &= N^2 \sum_{i,j} f_j f_i^* \exp(2\pi i \underline{H} \cdot (\underline{r}_j - \underline{r}_i)) \exp(2\pi i \underline{H} \cdot (\underline{\delta}_j - \underline{\delta}_i)). \quad (2-14)
 \end{aligned}$$

This is the instantaneous intensity at any one time. Experimentally, the time average of this value is observed. This time average is indicated by $\langle \dots \rangle$.

$$\langle I \rangle = N^2 \sum_{i,j} f_j f_i^* \exp(2\pi i \underline{H} \cdot (\underline{r}_j - \underline{r}_i)) \langle \exp(2\pi i \underline{H} \cdot (\underline{\delta}_j - \underline{\delta}_i)) \rangle. \quad (2-15)$$

For small displacements,

$$\begin{aligned}
 \langle \exp(2\pi i \underline{H} \cdot (\underline{\delta}_j - \underline{\delta}_i)) \rangle &= 1 + i \langle 2\pi \underline{H} \cdot (\underline{\delta}_j - \underline{\delta}_i) \rangle - \frac{1}{2} \langle (2\pi \underline{H} \cdot (\underline{\delta}_j - \underline{\delta}_i))^2 \rangle - \dots \\
 &\approx 1 - \frac{1}{2} \langle (2\pi \underline{H} \cdot (\underline{\delta}_j - \underline{\delta}_i))^2 \rangle \\
 &= \exp(-\pi \langle (\underline{H} \cdot (\underline{\delta}_j - \underline{\delta}_i))^2 \rangle) \\
 &= \exp(-\pi \langle (\underline{H} \cdot (\underline{\delta}_j - \underline{\delta}_i))^2 \rangle) \exp(-\pi \langle (\underline{H} \cdot (\underline{\delta}_j - \underline{\delta}_i))^2 \rangle) \\
 &\quad \cdot \exp(2\pi \langle (\underline{H} \cdot \underline{\delta}_j) (\underline{H} \cdot \underline{\delta}_i) \rangle), \quad (2-16)
 \end{aligned}$$

since odd powers average to zero and large powers in the Taylor series are negligible.

Thus the average intensity

$$\begin{aligned}
 I &= N^2 \sum_{i,j} f_j \exp(2\pi i (\underline{H} \cdot \underline{r}_j)) \exp(\pi \langle (\underline{H} \cdot \underline{\delta}_j)^2 \rangle) f_i^* \exp(2\pi i (\underline{H} \cdot \underline{r}_i)) \exp(\pi \langle (\underline{H} \cdot \underline{\delta}_i)^2 \rangle) \\
 &\quad \cdot (1 + \exp(2\pi \langle (\underline{H} \cdot \underline{\delta}_j) (\underline{H} \cdot \underline{\delta}_i) \rangle) - 1) \\
 &= N^2 \left| \sum_j f_j \exp(2\pi i (\underline{H} \cdot \underline{r}_j)) \exp(-2M_j) \right|^2 + \text{second term containing} \\
 &\quad \quad \quad (\exp(2\pi \langle (\underline{H} \cdot \underline{\delta}_j) (\underline{H} \cdot \underline{\delta}_i) \rangle) - 1)
 \end{aligned}$$

$2M_j$ is called the Debye-Waller factor and is equal to $\langle (\underline{H} \cdot \underline{\delta}_j)^2 \rangle \pi$. (2-17)

The first term in expression 2-17 has a sharp maximum intensity at the Bragg reflection. The second term will give rise to a small diffuse background called thermal diffuse scattering which is negligible in intensity compared to the Bragg reflection.

Thus, when taking thermal motion into account, the structure factor must be modified to

$$F(\underline{H}) = \sum_j f_j \exp(2\pi i (\underline{H} \cdot \underline{r}_j)) \exp(-2M_j). \quad (2-18)$$

It is customary to write

$$2M_j = \beta_{11}^j h^2 + \beta_{22}^j k^2 + \beta_{33}^j l^2 + \beta_{12}^j hk + \beta_{13}^j hl + \beta_{23}^j kl, \quad (2-19)$$

where the β are known as the anisotropic thermal coordinates and describe the ellipsoid of vibration of atom j at the temperature considered.

(b) Positional and Substitutional Disorder

Bragg's law will no longer be completely valid when disordering occurs, and equation 2-1 becomes

$$\begin{aligned} A(\underline{\Delta k}) &= \sum_{xyz} \exp(i\underline{\Delta k} \cdot \underline{R}) \int_{u.c.} \rho(\underline{r}) \exp(i\underline{\Delta k} \cdot \underline{r}) dV \\ &= \sum_{xyz} \exp(i\underline{\Delta k} \cdot \underline{R}) \sum_j f_j(\underline{\Delta k}) \exp(i\underline{\Delta k} \cdot \underline{r}_j) \\ &= \sum_{xyz} \exp(i\underline{\Delta k} \cdot \underline{R}) F'(\underline{\Delta k}), \end{aligned} \quad (2-20)$$

where \underline{R} , as before, is $x\underline{a} + y\underline{b} + z\underline{c}$, and where the F' may be different for each unit cell. They can differ in magnitude due to a difference in f_j values (substitutional disorder) or in phase due to a difference in \underline{r}_j values (positional disorder) or both.

Equation 2-20 can be re-arranged as

$$A(\underline{\Delta k}) = \sum_{xyz} (F_p + F_{np}) \exp(i\underline{\Delta k} \cdot \underline{R}), \quad (2-21)$$

where the F ' have been divided into a periodic part (F_p) which represents the "average" structure factor for the cells, and stays the same for all the cells, and a non-periodic part (F_{np}) which varies from cell to cell and represents the deviations from the average cell. The intensity using equation 2-21 now becomes

$$\begin{aligned}
 I = & \left| \sum_{xyz} \exp(i\Delta\mathbf{k}\cdot\mathbf{R}) F_p \right|^2 + \left| \sum_{xyz} \exp(i\Delta\mathbf{k}\cdot\mathbf{R}) F_{np} \right|^2 \\
 & + \sum_{xyz} \exp(i\Delta\mathbf{k}\cdot\mathbf{R}) F_p \sum_{xyz} \exp(-i\Delta\mathbf{k}\cdot\mathbf{R}) F_{np}^* \\
 & + \sum_{xyz} \exp(-i\Delta\mathbf{k}\cdot\mathbf{R}) F_p^* \sum_{xyz} \exp(i\Delta\mathbf{k}\cdot\mathbf{R}) F_{np} . \quad (2-22)
 \end{aligned}$$

$\sum_{xyz} \exp(i\Delta\mathbf{k}\cdot\mathbf{R}) F_p$ occurs in the first and last two terms of equation 2-22, and has a non-zero value only at the Bragg points defined by $\Delta\mathbf{k} = 2\pi\mathbf{H}$.

The intensity arising due to the first term is thus the Bragg intensity associated with the average cell. The sum of the non-periodic parts normally cancels out in the last two terms if the average cell has been properly chosen. The second term can be non-zero for any value of $\Delta\mathbf{k}$, its magnitude depending on the kind and extent of disorder. In general, this term represents a diffuse background for the Bragg reflection.

(c) Stacking Faults

When a crystal consists of a layered structure in such a way that one layer may be displaced from or be different in contents from the other layers, a one-dimensional disorder in the direction perpendicular to the layers is present. This disorder can be recognized in the diffraction pattern by the existence of streaks through the Bragg peaks in the \underline{c}^* direction for disorder in the \underline{c} direction. The diffraction intensities have been calculated generally for such disorders by Jagodzinski⁶⁹,

Kakinoki and Komura⁷⁰ and Cowley⁷¹. The resulting expressions and their derivations will not be reproduced here, but may readily be found in the literature. The intensity expressions usually do not yield to convenient calculations except for special cases where simplifications can be made. One such case will be discussed in chapter 8, and the intensity expression for it will be derived at that time. In general, the intensity can be broken up into terms of intensity produced due to layers stacked without faults, with one fault, with two faults, etc., and the total intensity is the sum of all these terms.

(d) Mosaic Spread

Crystals normally consist of many small "mosaic" blocks which contain cells in perfect alignment, but which are slightly misaligned with respect to each other. The amount of misalignment is called the mosaic spread of the crystal. The mosaic blocks are larger in dimension than the coherence length of x-rays, thus each block produces a diffracted beam independent of the others, and the total intensity of the diffracted beams is equal to the sum of the individual beams from each block. Since the mosaic spread is usually small compared to the reciprocal cell dimensions, the effect of the blocks is a slight broadening of the Bragg peak in the diffraction pattern.

When an x-ray beam is scattered from a reflecting plane, energy is transferred to the diffracted wave, thus reducing the incident beam intensity. When this effect occurs within one mosaic block, the integrated intensity of that block is lessened. This is known as primary extinction. Secondary extinction occurs when the incident beam is attenuated between the blocks before it reaches a particular block. The mosaic blocks are

normally small enough, or can be made small enough, so that the effect of primary extinction is negligible, but secondary extinction often has an appreciable effect on the intensities and is most noticeable with strong reflections. Zachariasen⁷² has worked out the value of the secondary extinction correction and Larson⁷³ has suggested it may be used to relate the observed and calculated intensities by means of the formula

$$F_{\text{obs}}^2 = F_{\text{calc}}^2 (1 - g\beta F_{\text{calc}}^2)^{-\frac{1}{2}}, \quad (2-23)$$

where F_{obs} and F_{calc} are the observed and calculated structure factors respectively, β is an effective absorption coefficient as derived by Zachariasen⁷² and g is a measure of the amount of secondary extinction. It is normally an experimentally determined parameter.

§ 2.4 Effect of Domain Size on Intensities

When disorder is present in a crystal, it becomes important to consider the distance between each kind of unit cell. If each kind of unit cell is grouped in a domain which has dimensions small compared to the coherence length of the x-rays, then the total scattering amplitude will be the sum of the amplitudes of each of the cell kinds. If the domain dimensions are much greater than the x-ray coherence length, the total intensity will be the sum of the intensities of each of the cell kinds. Thus,

$$F_{\text{total}} = F_a + F_b, \quad (2-24)$$

$$\text{or } I_{\text{total}} = |F_a + F_b|^2 \quad (2-25)$$

for a domain consisting of cells of type "a" and one consisting of type "b" cells, when the domain size is much smaller than the coherence length,

and,

$$I_{\text{total}} = |F_a|^2 + |F_b|^2, \quad (2-26)$$

when the domain size is much greater than the coherence length. Equations 2-25 and 2-26 may be combined to give

$$I_{\text{total}} = |F_a|^2 + |F_b|^2 + \alpha \{F_a F_b^* + F_a^* F_b\}, \quad (2-27)$$

where $0 \leq \alpha \leq 1$.

Coherence lengths of x-rays are of the order of one micron⁶⁴. Thus $\alpha=1$ when the domain dimensions are much less than a micron and $\alpha=0$ when the domain dimensions are much greater than a micron. It follows that, for domains about the length of a micron, α must have a value intermediate between 0 and 1.

§ 2.5 Intensity Corrections

Intensities will show the effects of absorption of some intensity by the crystal, polarization of the reflected x-rays, extinction, and in addition will be affected by the geometry of the apparatus used to diffract the x-rays from a crystal.

(a) Absorption

A certain amount of energy can be absorbed from the x-ray beam to produce electronic excitations and to remove electrons from atoms. Such absorption decreases the intensity of the scattered beam.

$$I/I_0 = \exp(-\mu_\lambda t), \quad (2-28)$$

where I is the transmitted intensity, I_0 is the incident intensity, t the path length, and μ_λ the linear absorption coefficient of the material for radiation of wave-length λ . This absorption coefficient can be expressed as

$$\mu_\lambda = d \sum_n x_n \mu_n, \quad (2-29)$$

where d is the density of the material, x_n is the fraction of atoms of type n in the unit cell, and μ_n is the mass absorption coefficient of atom n . It is listed in the International Tables for X-Ray Crystallography, Volume II⁷⁴ for all atoms. The atomic absorption coefficient increases with wavelength, atomic masses of the atoms, and density. Corrections for absorption become increasingly important as these effects increase in size. In practice, it is often useful to grind crystals into spheres or cylinders of known radii, since for such simple geometries it is easy to calculate the path length for various scattering angles.

(b) Polarization

An x-ray beam has an associated electric field which can be resolved into a component parallel (E_{\parallel}) and a component perpendicular (E_{\perp}) to the reflection plane. The intensity of the beam is equal to the square of the electric field. I.e. $I = E^2 = E_{\parallel}^2 + E_{\perp}^2$. The parallel component of the electric field reflects with 100% efficiency, but the perpendicular component reflects with an efficiency of $\cos^2\theta$:

$$\begin{aligned}(E_{\parallel})_{\text{reflected}} &= (E_{\parallel})_{\text{incident}}, \\ (E_{\perp})_{\text{reflected}} &= (E_{\perp})_{\text{incident}} \cos^2\theta.\end{aligned}\tag{2-30}$$

If the initial beam was unpolarized, then E_{\parallel}^2 and E_{\perp}^2 are each equal to $\frac{1}{2}E^2$. and the intensity of the reflected beam is

$$\begin{aligned}I &= E_{\text{reflected}}^2 = (E_{\parallel})_{\text{reflected}}^2 + (E_{\perp})_{\text{reflected}}^2 \\ &= (E_{\parallel})_{\text{incident}}^2 + (E_{\perp})_{\text{incident}}^2 \cos^2\theta \\ &= I_{\text{incident}} \left(\frac{1}{2} + \frac{1}{2}\cos^2\theta\right).\end{aligned}\tag{2-31}$$

If the initial beam was crystal monochromatized, then $E_{\parallel}^2 : E_{\perp}^2 = 1 : \cos^2 2\theta_c$

where θ_c is the Bragg angle for the monochromating crystal. Thus,

$$\begin{aligned} E_{II}^2 &= E(1 + \cos^2 2\theta_c) \quad \text{and} \\ E_{\perp}^2 &= E \cos^2 2\theta_c (1 + \cos^2 2\theta_c). \end{aligned} \quad (2-32)$$

This gives a reflected intensity of

$$I = I_{\text{incident}} \left(\frac{1 + \cos^2 2\theta_c \cos^2 2\theta}{1 + \cos^2 2\theta_c} \right). \quad (2-33)$$

(c) Lorentz effect

Since mosaic spread introduces a finite breadth to the Bragg peak, and since an x-ray beam is never perfectly collimated, intensities are usually integrated over a volume large enough to include deviations from the point at which the Bragg peak occurs. To do this integration, the crystal is usually rotated about an axis parallel to the reflecting plane and normal to the incident x-ray beam so that the total intensity from the whole range of possible contributions can be measured. This total intensity is

$$I_{\text{integrated}} = \iint R^2 I dt dA, \quad (2-34)$$

where dA is the element of area of the surface receiving the reflected beam at a distance R from the crystal. This surface will be normal to the reflected beam. dt is the time during which the crystal is in a reflecting position while it is being rotated through distance dL . dL must be perpendicular to the incident beam and in the plane of both the incident and reflected beams.

If the angular velocity is ω , then $dt = \omega dL$. dL makes an angle of $\pi/2 - 2\theta$ with the reflected beam, and thus $dL = (\cos(\pi/2 - 2\theta))^{-1} dx = (\sin 2\theta)^{-1} dx$ where dx is an element of length along the reflected beam. We thus have

$$dtdA = \omega dl dA = \omega(\sin 2\theta)^{-1} dx dA = \omega(\sin 2\theta)^{-1} dV, \quad (2-35)$$

where the element of volume dV is now independent of the Bragg angle.

The integrated intensity now is

$$I_{\text{integrated}} = \iiint_R \omega(\sin 2\theta)^{-1} dV = I_{\text{measured}} (\sin 2\theta)^{-1}. \quad (2-36)$$

Thus the total intensity depends upon $(\sin 2\theta)^{-1}$ for this kind of crystal rotation. The factor $(\sin 2\theta)^{-1}$ is known as the Lorentz factor. For different kinds of crystal rotations, the Lorentz factor will vary.

§ 2.6 The Phase Problem

Structure factors can be written in the form $F_H = |F_H| \exp(\alpha_H)$ where α_H is called the phase angle and $|F_H|$ is the amplitude of the structure factor. Since $\sqrt{I_H} = |F_H|$, only the amplitude can be determined from intensity measurements. The structure factor is the Fourier transform of the electron density. Therefore the electron density is

$$\rho(\underline{r}) = V^{-1} \sum_{\underline{H}} F_H \exp(-2\pi i \underline{H} \cdot \underline{r}). \quad (2-37)$$

This expression cannot be evaluated, and hence ρ cannot be calculated unless α_H is known. This is known as the "phase problem" of crystallography. Likely phases can be calculated by proposing models for the possible structure of the unit cell and comparing the moduli of the structure factors of such models with those measured experimentally.

§ 2.7 Methods of Solving the Phase Problem

(a) Isostructural Crystals

If the reflections of a particular crystal are similar in intensity to those of another crystal which has the same unit cell dimensions and a similar chemical formula (e.g. NaVO_3 and LiVO_3), then the crystals are likely isostructural, and the coordinates for one crystal represent a good model for the other crystal.

(b) The Patterson Function

The general Patterson function $P(\underline{u})$, is defined as the convolution of the electron density with itself.

$$\begin{aligned} P(\underline{u}) &= \rho(\underline{u}) * \rho(-\underline{u}) \\ &= \int_{-\infty}^{\infty} \rho(\underline{R}) \rho(\underline{R} + \underline{u}) d\underline{R}, \end{aligned} \quad (2-38)$$

where the convolution (*) is defined as shown.

For a crystal with translational symmetry, this becomes

$$\begin{aligned} P(\underline{u}) &= N \int_{\text{u.c.}} \rho(\underline{R}) \rho(\underline{R} + \underline{u}) d\underline{R} \quad (2-39) \\ &= N \int_{\text{u.c.}} \sum_{\underline{H}'} \sum_{\underline{H}} F_{\underline{H}'} \exp(-2\pi i \underline{H}' \cdot \underline{u}) \frac{F_{\underline{H}}}{V} \exp(-2\pi i \underline{H} \cdot (\underline{R} + \underline{u})) d\underline{R} \\ &= \frac{N}{V^2} \sum_{\underline{H}'} \sum_{\underline{H}} F_{\underline{H}'} F_{\underline{H}} \exp(-2\pi i \underline{H} \cdot \underline{u}) \int_{\text{u.c.}} \exp 2\pi i (\underline{H}' + \underline{H}) \cdot \underline{R} d\underline{R}. \end{aligned} \quad (2-39)$$

The integral is zero unless $\underline{H}' = -\underline{H}$ when it has a value equal to the volume of the unit cell. The volume of the unit cell multiplied by the number of unit cells is equal to the volume of the crystal. The Patterson simplifies to

$$\begin{aligned} P(\underline{u}) &= V^{-1} \sum_{\underline{H}} F_{\underline{H}} F_{-\underline{H}} \exp(-2\pi i \underline{H} \cdot \underline{u}) \\ &= V^{-1} \sum_{\underline{H}} |F_{\underline{H}}|^2 \exp(2\pi i \underline{H} \cdot \underline{u}). \quad (\text{since } F_{-\underline{H}} = F_{\underline{H}}^*) \end{aligned} \quad (2-40)$$

The variable \underline{u} represents the distance between two points, and when this distance is the distance between two atoms in the unit cell, the value for $P(\underline{u})$ will be large. Thus, by examining a map of a Patterson function distances between atoms may be determined, and these distances in turn may suggest possible structural models.

(c) Other Methods

Models may also be determined by direct methods, which involve the statistical evaluation of phases, or through the use of anomalous dispersion,

which introduces a shift in the peaks of the Patterson function for different radiations. This shift is related to the absorption of x-rays by the individual atoms and thus varies with the kind of atom. These methods were not used in this work and will not be discussed further.

§ 2.8 Crystal Structure Refinement

(a) Electron Density and Difference Maps.

An initial model of a crystal structure often includes only some of the atoms, or includes atoms in approximate positions. From such a model, however, structure factors may be calculated and hence phases may be proposed for the experimental structure factors. An electron density distribution can now be calculated, and, if the proposed phases are close to the correct ones, this distribution will have peaks at the atomic positions of all the atoms. These positions may now be used to calculate new structure factors which should be closer to the experimental ones. This procedure can be repeated until no further improvement in the agreement is found.

Instead of an electron density map, a difference map is often used. This is a plot of the function $\sum_H \Delta F \exp(i\alpha) \exp(-2\pi i \underline{H} \cdot \underline{r})$ where ΔF is the difference between the amplitude of the observed and calculated structure factors, and α is the phase determined from the model. This function is an electron density function which has the electron density of the model subtracted from the total electron density, and should show peaks which reflect positions of new atoms, or a combination of a positive and negative peak to reflect a corrected and incorrect position of an atom respectively.

(b) Least Squares Refinement

Improvement of a crystal structure model by repeated evaluation of electron density maps, or difference maps, is tedious and will not as a rule give thermal coordinates or small variations of atomic positions. A more convenient method of improving models is through the least squares refinement of the fit of the experimental structure factors to the calculated ones.

If a model for a crystal structure is described by the variables p_i , $i=1, \dots, \text{no. of variables } (n)$, which may be positional, temperature or scale parameters, then a better structure factor (i.e. one which is closer to the experimental one) can be expanded in terms of a Taylor series about the structure factors with parameters p_i :

$$kF_c = kF_c(p_i) + \sum_i \left(\frac{\partial kF_c}{\partial p_i} \right) p_i \Delta p_i + \dots, \quad (2-41)$$

where k is a scale factor which brings the structure factor on the same scale as the intensity.

This expansion is substituted into the function

$$D = \sum_H w(|F_O| - k|F_c|)^2, \quad (2-42)$$

where w is a weighting function which will be discussed in the next section.

If the model is reasonably close to the "true" structure, then second and subsequent terms in the Taylor expansion of kF_c are very small and may be neglected. Thus,

$$D = \sum_H w(|F_O| - k|F_c(p_i)| + \sum_i \left(\frac{\partial kF_c}{\partial p_i} \right) p_i \Delta p_i)^2. \quad (2-43)$$

D is now minimized with respect to all the variables.

$$\frac{\partial D}{\partial p_i} = 0 \quad i=1, \dots, n. \quad (2-44)$$

This produces upon simplification a set of n equations in the shifts

p_i of the form

$$a_{i1}\Delta p_1 + a_{i2}\Delta p_2 + \dots + a_{in}\Delta p_n = v_i, \quad (2-45)$$

where
$$a_{ij} = \sum_H w \frac{\partial |kF_c|}{\partial p_i} \cdot \frac{\partial |kF_c|}{\partial p_j}, \quad v_i = \sum_H w (|F_o| - k|F_c|) \frac{\partial |kF_c|}{\partial p_i}.$$

The set of these equations can be written in matrix form:

$$\underline{A}\underline{\Delta P} = \underline{V}, \quad (2-46)$$

where the a_{ij} are the elements of matrix A, the p_i elements of vector \underline{P} , and the v_i elements of vector \underline{V} .

Equation 2-46 can be solved:

$$\underline{\Delta P} = A^{-1}\underline{V}, \quad (2-47)$$

where A^{-1} is the inverse matrix of A. The values of Δp_i so found can be used as a correction to the model and the above procedure can be repeated with the corrected variables until further corrections are negligible.

If the elements of the inverse matrix A^{-1} are denoted by b_{ij} , the standard deviation for any parameter p_i is

$$\sigma_{p_i} = (b_{ii} (\sum_H w (|F_o| - |F_c|)^2 (m-n)^{-1})^{\frac{1}{2}}, \quad (2-48)$$

where m is the number of reflections.

The correlation between variables is measured by the correlation coefficient

$$\delta_{ij} = b_{ij} / b_{ii}^{\frac{1}{2}} b_{jj}^{\frac{1}{2}}, \quad (2-49)$$

which can vary between -1 and +1. For values close to +1 or -1, serious problems in refinement can result. These may be circumvented to a certain extent by treating one correlated variable as a constant during one cycle of refinement and the other variable as a constant during the next cycle

of refinement. Scheringer⁷⁵ discusses some of the correlation problems in detail.

The goodness of fit of the calculated structure factors compared to the observed structure factors is measured by the residual

$$R = \frac{\sum ||F_o| - |F_c||}{|F_o|}, \quad (2-50)$$

or the weighted residual

$$R_w = \left(\frac{\sum w |F_o| - |F_c||^2}{|F_o|^2} \right)^{\frac{1}{2}}. \quad (2-51)$$

§ 2.9 Weighting Schemes

All reflections are not measured with the same accuracy and they should be weighed in a structure refinement. These weights cannot be determined a priori since the errors in measurement are not well defined and, as a consequence, they present a rather controversial topic for crystallographers. One train of thought suggests that reflections should be weighted by the standard deviation of the photon count for the reflection. This scheme does not take into account machine errors, and is likely to give too large a weight to the very intense reflections. Cruickshank⁷⁶ suggests that a scheme of the form $(a+b|F_o|+c|F_o|^2)^{-1}$ be used. He argues that the variation of the difference between the observed and calculated structure factors is usually quadratic with respect to the observed structure factor, and hence, the weighting scheme should reflect this form. Too large a weight is usually given to the very weak reflections by these kind of schemes. In this work, weights of the form $(a+b|F_o|+c|F_o|^2+d(\sigma/|F_o|)^2)^{-1}$ have been used, incorporating both of the above ideas.

CHAPTER 3

The Preparation and X-Ray Intensities Collection for the Crystals

§ 3.1 Crystal Preparation

VPO_5 in either the α , β , or hydrated form can be used as a precursor for the growth of $VO(PO_3)_2$, $V(PO_3)_3$, VOP_2SiO_8 and $(VO)_2P_2O_7$ crystals. The first two can be prepared from any form of VPO_5 by varying the temperature and the amount of phosphoric acid required as illustrated in figure 3-1. $(VO)_2P_2O_7$ is a direct reduction product of VPO_5 heated to about $800^\circ C$ in an inert atmosphere. The VOP_2SiO_8 crystals can be prepared from VPO_5 , H_3PO_4 and quartz, although they are more easily prepared by vapour phase transport in iodine from $VO(PO_3)_2$ and SiO_2 ⁷⁷. Also, this material is very often found as a byproduct when V_2O_5 and P_2O_5 are mixed and heated in an evacuated quartz tube. The vanadium invariably appears to reduce under these conditions. $VAsO_5$ has no direct preparative relationship to the other compounds, but its study was undertaken to see the similarities and/or differences between the vanadium phosphate and vanadium arsenate compounds. Its preparation is similar to the preparation of VPO_5 from the melt. Although most of the crystals can be grown readily, preparations often produce glasses as by-products and in fact crystals of both VOP_2SiO_8 and $VO(PO_3)_2$ have been found which show some vitreous character on precession photographs.

(a) Preparation of VOP_2SiO_8 , $VO(PO_3)_2$ and $V(PO_3)_3$

A 1:1 $V_2O_5:P_2O_5$ mix was heated in a sealed, evacuated quartz tube to about $900^\circ C$. The sample was then cooled at a rate of $3^\circ/hr.$ to

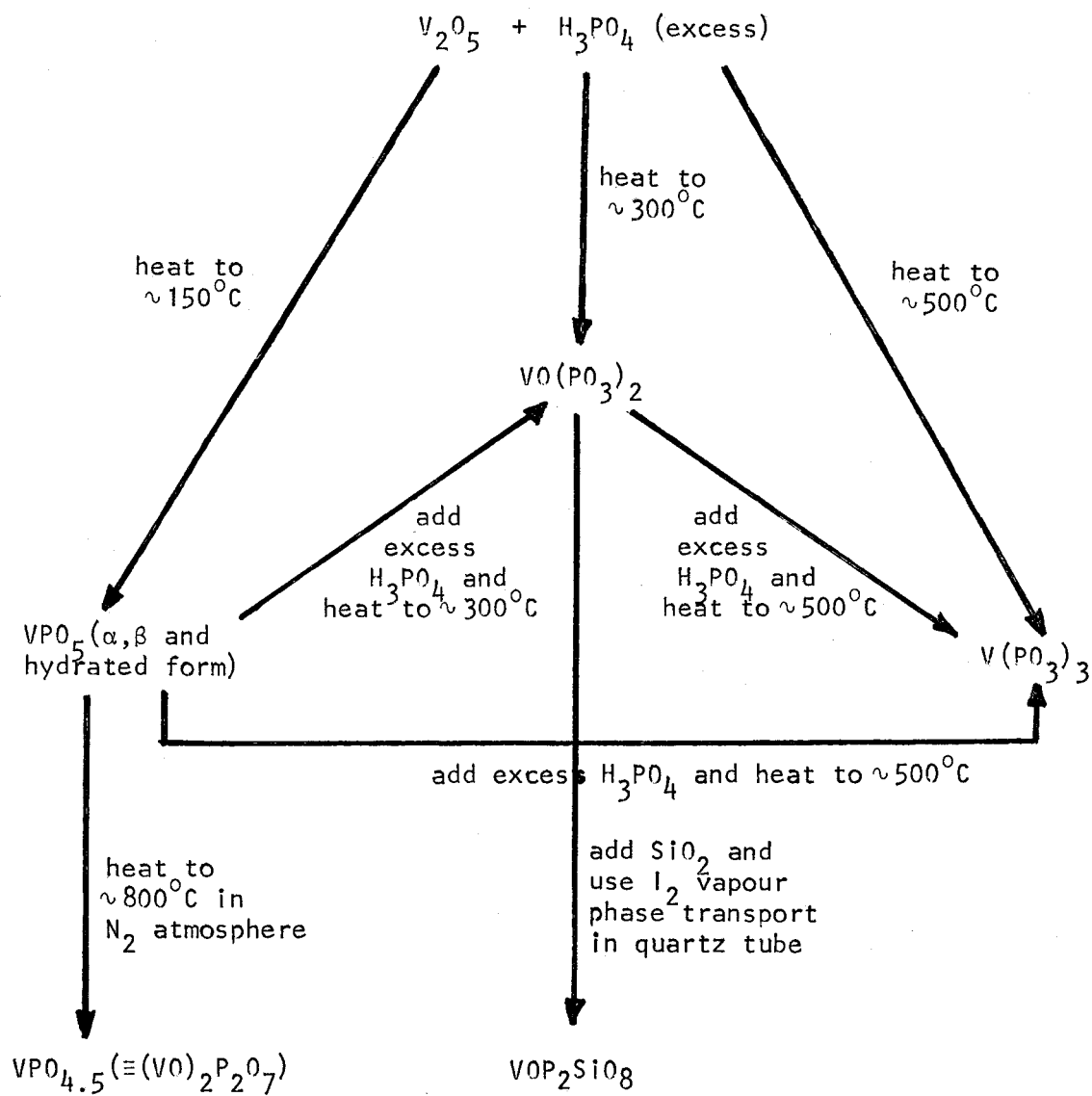


Figure 3-1. Relationship between the preparations of the various vanadium phosphorus oxides.

500°C. The furnace was turned off at this point and the sample was allowed to cool to ambient temperature. The resulting crystalline mixture contained crystals identified as being VOP_2SiO_8 , $VO(PO_3)_2$ and $V(PO_3)_3$, by comparison of their crystal parameters obtained from single crystal precession photographs to those of Tofield, *et al.*^{45,77}. At least one and possibly more than one unidentified crystalline phase was also present as indicated by the presence of lines not belonging to any of the identified crystals in a powder pattern taken of a bulk sample of the mixture. These crystals probably have a V:P ratio greater than one since the identified crystals are all phosphorus rich and the mixture was originally made with V:P being 1:1. Unfortunately, none of these unidentified crystals was suitable for x-ray structure analysis. It is likely that they contain reduced vanadium since no VPO_5 was found in the mixture and the colours of the crystals were all blue or green, which are the colours usually associated with V^{+4} and V^{+3} . A yellow colour is usually noted for V^{+5} . Crystals of VOP_2SiO_8 and $V(PO_3)_3$ from this mixture were found to be the best available crystals of their kind and were ground to spheres and used for structure determination.

The same preparation as described above was repeated with a cooling rate of 15°/hr. The resulting product consisted mostly of a glass and small crystals of VOP_2SiO_8 embedded on the surface away from the quartz container wall. Small crystals of $VO(PO_3)_2$ were found in the bottom of the tube. No other crystals were found. It was thought that the crystals of VOP_2SiO_8 and $VO(PO_3)_2$ could be vanadium rich with vanadium either replacing some of the silicon with V^{+4} or replacing some of the phosphorus with V^{+5} , since the lattice parameters for both these

crystals were slightly larger than found in other crystals of their kind. An analysis of the crystals and the glass was attempted by electron microprobe. Results (which will be discussed later) were inconclusive in showing non-stoichiometry in the crystals, and showed the glass to have a V:P ratio of 1:1 with at most 1% silicon.

Crystals of $V(PO_3)_3$ were also prepared using the method of Lavrov, et al.⁴⁴ and Tofield, et al.⁴⁵, by heating a 10:1 phosphoric acid: V_2O_5 mixture to 500°C overnight. The crystals which precipitated were of unequal dimensions and could not be ground easily into good spheres. They were not used to collect intensity measurements for solving the structure, but were used for all other experiments.

Crystals of $VO(PO_3)_2$ were prepared following the method of Tofield, et al.⁴⁵ using a 10:1 phosphoric acid: V_2O_5 mixture heated overnight to 300°C. The resulting crystals were very often twinned or compacted. Better crystals were obtained by heating VS_2O_5 in the stoichiometric amount of phosphoric acid required to give V:P = 1:2. These crystals were ground to spheres and used for intensity measurements. A powder pattern of $VO(PO_3)_2$ reported by Lavrov, et al.⁴⁴ could not be indexed for the cell parameters of the crystals produced above.

Details of the crystal appearance, crystal data and intensity measurements for these crystals are listed in table 3-1.

(b) Preparation of $(VO)_2P_2O_7$

Bordes and Courtine⁴⁰ report that $(VO)_2P_2O_7$ can be prepared by the reduction of VPO_5 (all forms) under nitrogen atmosphere at 800°C. VPO_5 was prepared by grinding together thoroughly a 1:1, V:P mixture of V_2O_5 and $NH_4H_2PO_4$, and heating it in a platinum crucible at a rate of

Table 3-1. Crystal Data

Crystal	$V^{+4}OP_2SiO_8$	$V^{+4}O(PO_3)_2$	$V^{+3}(PO_3)_3$	$(V^{+4}O)_2P_2O_7$	$V^{+5}AsO_5$
Appearance	blue rectangular plates - max 3mm long, 0.3mm thick	blue rods with diameters up to 0.2mm, lengths up to 1.5mm	green rods with diameters up to 0.5mm, lengths up to 3mm	green, rhombic roughly equi-dimensional up to 1 mm in length	yellow, mica-like layers of indefinite length, max. thickness 0.05 mm
Crystal used for Intensity Measurements	ground sphere radius 0.125 mm	ground sphere radius 0.1 mm	ground sphere radius 0.1 mm	ground sphere radius 0.15 mm	rod length 0.12 mm width 0.05 mm
Crystal System	tetragonal	tetragonal	monoclinic	orthorhombic	monoclinic
Lattice Parameters					
a (Å)	8.723(1)	10.960(1)	10.615(2)	9.571(4)	6.35(3)
b (Å)			19.095(4)	7.728(5)	6.32(3)
c (Å)	8.151(1)	4.2529(4)	9.432(1)	16.568(6)	8.256(5)
β (or γ) (°)			$\beta=97.94(1)$		$\gamma=90(1)$
Z	4	4	12	8	4
Systematic Extinctions	hk0, $h+k \neq 2n$ 0kl, $l \neq 2n$ hhl, $l \neq 2n$	Ok l , $k+l \neq 2n$ h0l, $h+l \neq 2n$ 00l, $l \neq 4n$ $h+k+l \neq 2n$	Ok l , $k \neq 2n$ h0l, $l \neq 2n$ $h+k+l \neq 2n$	Ok l , $k \neq 2n$ h0l, $l \neq 2n$	hk0, $h+k \neq 2n$ 00l, $l \neq 2n$
Possible Space Groups	P4/ncc	I $\bar{4}$ 2d or I $\bar{4}$ ₁ md	Ic or I2/c	Pbcm or Pbc2 ₁	P2 ₁ /n (c ₁ unique)

table 3-1. cont.

Crystal	VO_2SiO_8	$\text{VO}(\text{PO}_3)_2$	$\text{V}(\text{PO}_3)_3$	$(\text{VO})_2\text{P}_2\text{O}_7$	VAsO_5
Diffractometer used	Syntex P $\bar{1}$	Syntex P2 $_1$	Syntex P2 $_1$	Syntex P $\bar{1}$	Syntex P $\bar{1}$
Scan rate	variable scan rate between 2 and 24 $^\circ$ /min depending on the peak intensity. The fastest rate is used for the strongest peaks, and the slowest for the weakest peaks				
Maximum 2 θ (Mo K $_\alpha$ radiation)	65	70	60	65	65
No. of symmetry independent non-zero reflections	571	336	2467	1900	1118
μ (cm $^{-1}$)	24	26	12	38	134
Density (g/cc) calculated	3.05	2.92	3.03	3.34	4.1
measured	insufficient material	2.9 \pm 0.1	3.0 \pm 0.1	insufficient material	4.0 \pm 0.1

50°C/hr. to about 500°C. After two hours, the product was removed from the furnace, allowed to cool and ground to a fine powder. This mixture was placed in a platinum dish and heated to 800°C overnight in a nitrogen atmosphere. The temperature was then raised to 1000°C (i.e. above the melting point of $(VO)_2P_2O_7$), kept there for about an hour and then lowered at a rate of 6°/hr. to 600°C. The furnace was shut off at this point and the crystals allowed to cool to room temperature at which time the nitrogen atmosphere was removed. The resulting product consisted of a mixture of glass and $(VO)_2P_2O_7$ crystals. A roughly equidimensional crystal was ground to a sphere and used for x-ray intensity measurements.

(c) Preparation of $VAsO_5$ (and $VAs_xP_{1-x}O_5$)

Equimolar amounts of V_2O_5 and As_2O_5 were weighed and ground together. This sample was heated to about 300°C for several hours and then allowed to cool. The ground mixture was heated in a platinum crucible to 900°C and then allowed to cool through the melting point of $VAsO_5$, estimated by comparison with VPO_5 to be about 800°C, at a rate of 5°/hr. There was no sample in the crucible when cooled, and investigation showed that the material volatilized before melting. A sample was prepared the same way as before but sealed under air in a quartz tube before heating to 900°C. Air was kept in the tube in an effort to prevent possible reduction of the vanadium, as occurs for vanadium-phosphorus oxide mixes in vacuo. The sample was cooled at a rate of 5°/hr. to 300°C after which the furnace was switched off and the sample allowed to cool by itself to room temperature. The resulting crystals existed in thin, mica-like sheets. It was not possible to grind a crystal to a sphere since the sheets were too thin, so a rod was used for x-ray intensity measurements.

Crystals of $\text{VAs}_x\text{P}_{1-x}\text{O}_5$ were grown in a quartz tube under air as above using samples prepared from the appropriate amounts of V_2O_5 , As_2O_5 and $\text{NH}_4\text{H}_2\text{PO}_4$. No crystals suitable for single-crystal work were prepared but powder patterns were taken of these samples and showed the structures to be similar to, if not the same as, that of $\alpha\text{-VPO}_5$.

§ 3.2 Measurement of X-Ray Diffraction Intensities

For each crystal, preliminary photographs (precession or Weissenberg) were taken to determine the lattice parameters and possible space groups (through the use of the International Tables, Vol. I⁷⁸) from the diffraction symmetry. The crystal was then centred on an automatic diffractometer and accurate lattice parameters were determined by least squares fitting to 15 reflections accurately centred at both positive and negative 2θ values, with the average taken to be the diffraction angle.

The uncorrected intensity measurements were corrected for background, Lorentz, polarization and absorption effects. Only intensities with values greater than the background were considered. Spherical absorption corrections (International Tables, Vol. II⁷⁴) were applied to all intensity measurements except those for VAsO_5 . The latter had cylindrical⁷⁴ absorption corrections applied. Standard deviations were estimated automatically by the computer based on the counting statistics of the intensity measurements. The intensities of three standard reflections were measured every fifty reflections in order to make sure that the crystal was still in its proper position and that the intensity of the x-ray source was constant. After all corrections were applied, equivalent reflections were averaged, and the square roots of the intensities were taken in order to give the absolute value of the structure factors.

§ 3.3 Solution of Crystal Structures

Refinement of atomic and thermal coordinates was carried out using full-matrix least-squares methods for all crystals. A secondary extinction parameter, as suggested by Zachariasen⁷² and Larson,⁷³ was refined for each crystal. Atomic scattering factors for free atoms were obtained from Cromer and Mann⁶⁷. Unless otherwise indicated, substitutional and positional disorder was treated by refining the parameters (co-ordinates and occupation) for an average cell. I.e. only the first term in equation 2-22 is considered significant.

CHAPTER 4

The Crystal Structure and Substitutional Disorder of VOP_2SiO_8

§ 4.1 Solution of the Crystal Structure

Two isostructural crystals of VOP_2SiO_8 were studied. The first had lattice parameters $a=8.723(1) \text{ \AA}$, $c=8.151(1) \text{ \AA}$ and was found together with other crystalline phases grown from a V_2O_5 - P_2O_5 melt in an evacuated silica tube. The second crystal, found at the surface of a V-P oxide glass prepared in an evacuated silica tube, had lattice parameters of $a=8.733(2) \text{ \AA}$ and $c=8.185(2) \text{ \AA}$. The structure was solved for crystal I, and the final atomic and thermal co-ordinates obtained were used as starting parameters in the least-squares refinement for crystal II.

From the systematic extinctions, $(hk0, h+k \neq 2n; 0k\ell, \ell \neq 2n; h\ell\ell, \ell \neq 2n)$ the space group was uniquely determined to be $P4/ncc$. Since general positions in this space group are sixteen-fold, and there are only 4, 8 and 4 atoms of V, P, and Si respectively in a unit cell, these atoms must lie on special positions of 4, 8 and 4-fold symmetry respectively. From the Patterson function, a peak at $(0.36, 0.36, 0)$ was assigned to the distance between two phosphorus atoms at positions $x, x, \frac{1}{4}$ and $-x, -x, \frac{1}{4}$ with $x=0.18$. A peak at $(0.32, -0.18, 0.10)$, determined to be the P-V vector, placed V at $\frac{1}{2}, 0, 0.35$, and thus Si had to be at the origin as verified by the Patterson map. The remaining oxygen atoms were found from a difference Fourier map. All coordinates were refined using full-matrix least-squares methods. Anisotropic thermal coordinates were refined after the positional coordinates stopped changing significantly.

The refined coordinates for crystal II were not much different from those for crystal I, but the Si-O distance was found to be slightly larger. This suggested vanadium was substituting at the silicon site, and the occupation number of silicon was varied in the least-squares refinement of both crystals to allow for some substitution of vanadium. No substitution was indicated for crystal I, but the refinement for crystal II showed 5% substitution of V for Si. The substituted vanadium is most likely to be V^{+4} (although this oxidation state is not normally found tetrahedrally coordinated) or V^{+5} . The latter would require charge compensation at the other sites, probably V^{+3} substituted at the V^{+4} site or Si^{+4} substituted at the P^{+5} site. None of the above substitutions could be substantiated by refinement of the occupation of V and P, since the scattering factors for Si and P and for V^{+4} and V^{+3} are not sufficiently different to distinguish such small amounts of substitution.

Weighting schemes for both crystal refinements were chosen so that $\langle w\Delta F^2 \rangle$ was essentially independent of $\langle F_o \rangle$. The final R-factors were $R = 0.032$ and $R_w = 0.026$ ($w = (0.62 - 0.0175|F| + 0.000315|F|^2 + 775(\sigma/F)^2)^{-1}$) for crystal I and $R = 0.048$ and $R_w = 0.038$ ($w = (1.26 - 0.034|F| + 0.0007|F|^2 + 800(\sigma/F)^2)^{-1}$) for crystal II. Final coordinates are listed in table 4-1 (crystal I) and table 4-2 (crystal II).

§ 4.2 Description of the Structure

Like $\alpha\text{-VPO}_5$ ¹¹ and the isostructural $\alpha\text{-VSO}_5$ ⁷⁹, the structure consists of chains of VO_6 octahedra along four-fold axes which are bridged to neighbouring chains by corner-sharing PO_4 tetrahedra (fig. 4-1 and 4-2). The vanadium atom is displaced 0.37 Å from the equatorial plane of the $V^{+4}O_6$ octahedron, thereby forming a short axial (vanadyl) and a long axial

Table 4-1. Positional and thermal coordinates of VOP_2SiO_8 (crystal I). Values for the thermal coordinates are multiplied by 10^4 . Standard deviations are given within parentheses.

Atom	x	y	z	[†] $U_{11}(\text{\AA}^2)$	$U_{22}(\text{\AA}^2)$	$U_{33}(\text{\AA}^2)$	$U_{12}(\text{\AA}^2)$	$U_{13}(\text{\AA}^2)$	$U_{23}(\text{\AA}^2)$
V	$\frac{1}{2}$	0	0.35298(7)	60(3)	U_{11}	92(2)	0	0	0
P	0.17901(9)	x	$\frac{1}{4}$	61(3)	U_{11}	85(2)	4(2)	0(3)	0(3)
Si	0	0	0	80(4)	U_{11}	68(3)	0	0	0
O(1)	$\frac{1}{2}$	0	0.5480(3)	134(12)	U_{11}	113(9)	0	0	0
O(2)	0.6523(2)	0.1620(2)	0.3077(2)	89(6)	74(5)	174(5)	-23(4)	-8(5)	46(5)
O(3)	0.6390(2)	0.4392(2)	0.3889(2)	105(5)	126(5)	113(5)	3(4)	27(5)	-33(5)

[†] The U_{ij} and β_{ij} are related by $\beta_{ij} = 2\pi^2 b_i b_j U_{ij}$ where the b_i are the magnitudes of the corresponding reciprocal lattice vectors.

Table 4-2. Positional and thermal coordinates of VOP_2SiO_8 (crystal II). Values for the thermal coordinates are multiplied by 10^4 . Standard deviations are given within parentheses.

Atom	x	y	z	$U_{11}(\text{\AA}^2)$	$U_{22}(\text{\AA}^2)$	$U_{33}(\text{\AA}^2)$	$U_{12}(\text{\AA}^2)$	$U_{13}(\text{\AA}^2)$	$U_{23}(\text{\AA}^2)$
V	$\frac{1}{2}$	0	0.3527(1)	65(5)	U_{11}	110(4)	0	0	0
P	0.1795(1)	x	$\frac{1}{4}$	62(5)	U_{11}	87(4)	1(3)	0(3)	0(3)
Si	0	0	0	79(9)	U_{11}	62(6)	0	0	0
O(1)	$\frac{1}{2}$	0	0.5464(5)	127(18)	U_{11}	117(14)	0	0	0
O(2)	0.6529(2)	0.1614(2)	0.3068(2)	102(10)	77(9)	178(8)	-27(6)	-10(7)	41(7)
O(3)	0.6395(2)	0.4386(2)	0.3886(2)	107(8)	133(9)	113(7)	3(7)	26(7)	-35(7)

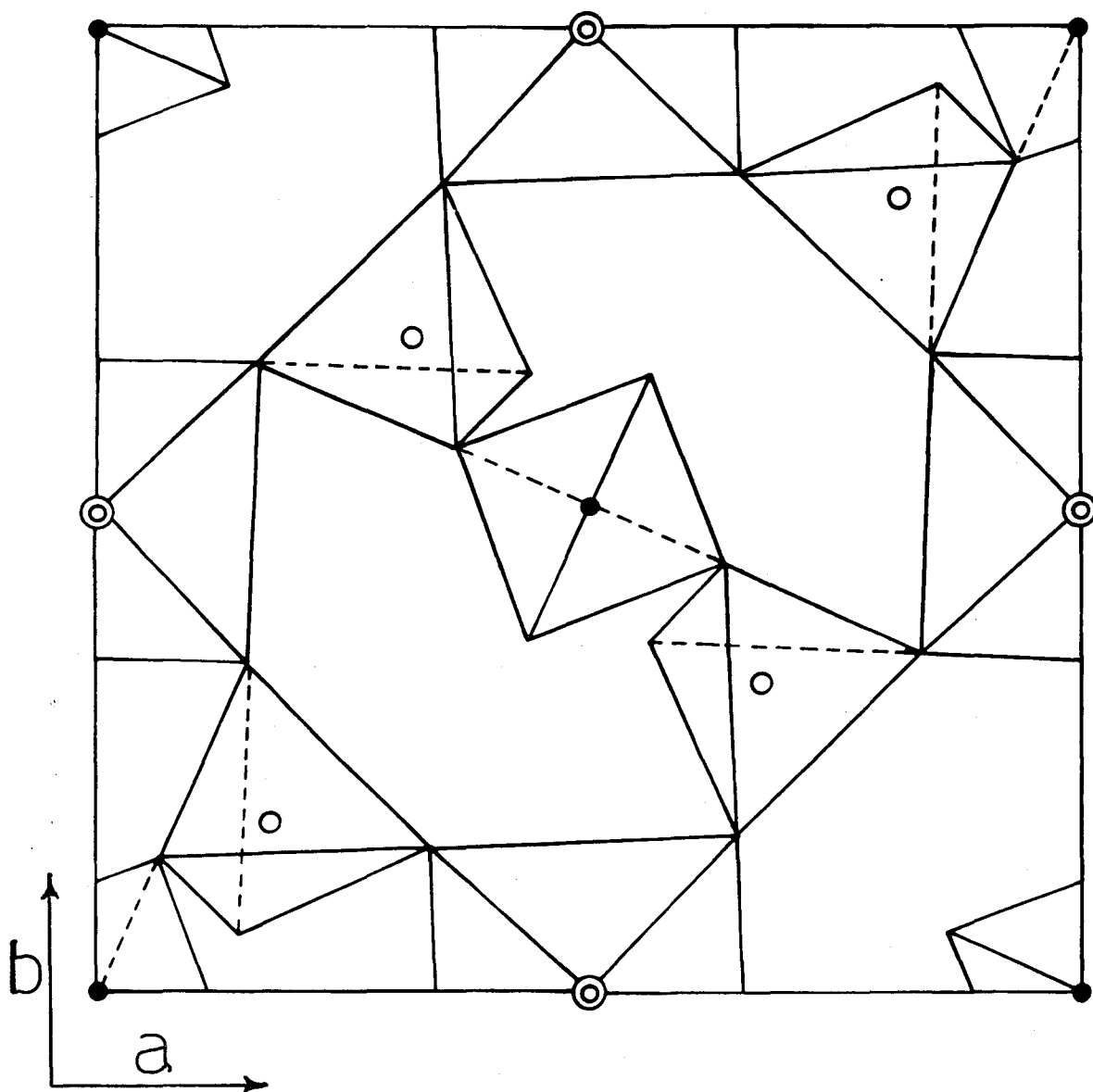


Figure 4-1. A half-cell projection of the structure of VOP_2SiO_8 . The remainder of the cell can be generated by a $\frac{c}{2}$ glide plane parallel to the face diagonal.

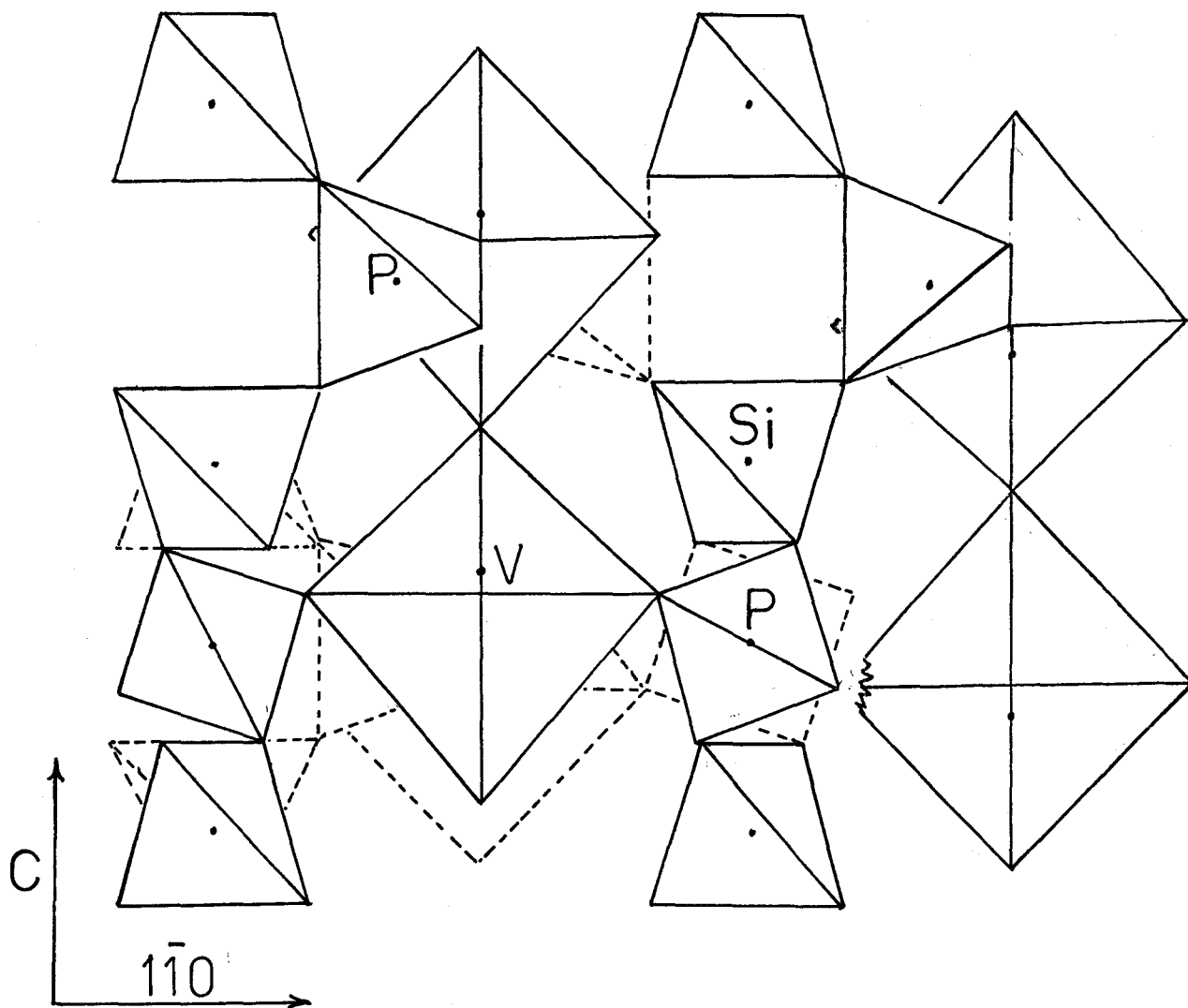


Figure 4-2. The structure of VOP_2SiO_8 as projected on the $1\bar{1}0$ plane.

V-O bond. The oxygens around V^{+4} form an almost regular octahedron with O-O distances of 2.743, 2.757 and 2.871 Å (equatorial-equatorial, short axial-equatorial, long axial-equatorial distances respectively)

Linked PO_4 and VO_6 groups lie in planes perpendicular to c . These planes are joined by the axial vanadyl bonds as well as SiO_4 tetrahedra which join adjacent planes by corner-sharing with two phosphate groups in each plane (fig.4-2). This is in contrast to α - VP_2O_8 where distinct layers exist, held together only by the long and short axial bonds.

The phosphate group has C_2 symmetry with the longer bonds involving the P-O-Si bridge and the shorter ones the P-O-V bridge. Baur's⁹⁴ bond order distance relationships and Brown's¹⁶ bond-valences predict this trend but predict differences of 0.036 and 0.146 Å respectively compared with the actual value of 0.088 Å.

The SiO_4 group forms an almost perfect tetrahedron with an Si-O bond-length in the range normally reported for silicon containing minerals⁸⁰. Compounds of this type of structure with phosphorus in the silicon position are not expected to occur since phosphate groups are not known to link four other phosphate groups in this fashion.

Rice, et al.⁴⁶ independently reported essentially the same structure for VOP_2SiO_8 . Their bond lengths and angles and those of crystal I and crystal II do not differ significantly (table 4-3).

§ 4.3 Substitutional Disorder

Substitutional disorder is one possible explanation for the discrepancy in the lattice parameters shown in table 4-4. The two crystals in this work were compared with respect to composition (from electron

Table 4-3. Bond angles ($^{\circ}$) and distances (\AA) for $\text{VO}_2\text{Si}_x\text{V}_{1-x}\text{O}_8$.
Estimated standard deviations are indicated in parentheses.

<u>VO_6 group</u>	crystal I $x = 1.00(1)$	crystal II $x = 0.95(1)$	Rice, <u>et al.</u> ⁴⁶
bond			
$\text{V}-\text{O}(1)^{\text{i}}$	1.590(3)	1.585(4)	1.591(2)
$\text{V}-\text{O}(1)^{\text{ii}}$	2.486(3)	2.508(4)	2.492(1)
$\text{V}-\text{O}(2)^{\text{i}} \quad \times 4$	1.974(2)	1.978(2)	1.977(1)
angle			
$\text{O}(1)^{\text{i}}-\text{V}-\text{O}(2)^{\text{i}}$	100.77(7)	100.97(7)	100.81(3)
$\text{O}(2)^{\text{i}}-\text{V}-\text{O}(2)^{\text{iii}}$	88.00(8)	87.93(8)	87.98(2)
$\text{O}(2)^{\text{i}}-\text{V}-\text{O}(2)^{\text{iv}}$	158.45(7)	158.07(9)	158.37(7)
<u>SiO_4 group</u>			
bond			
$\text{Si}-\text{O}(3)^{\text{v}} \quad \times 4$	1.604(2)	1.614(2)	1.610(1)
angle			
$\text{O}(3)^{\text{v}}-\text{Si}-\text{O}(3)^{\text{vii}}$	111.23(9)	111.17(11)	111.58(7)
$\text{O}(3)^{\text{v}}-\text{Si}-\text{O}(3)^{\text{vi}}$	108.60(9)	108.63(11)	108.43(4)
<u>PO_4 group</u>			
bond			
$\text{P}-\text{O}(2)^{\text{v}} \quad \times 2$	1.483(2)	1.483(2)	1.492(1)
$\text{P}-\text{O}(3)^{\text{v}} \quad \times 2$	1.571(2)	1.572(2)	1.572(1)
angle			
$\text{O}(2)^{\text{iii}}-\text{P}-\text{O}(2)^{\text{v}}$	113.23(9)	113.07(12)	113.04(8)
$\text{O}(2)^{\text{iii}}-\text{P}-\text{O}(3)^{\text{iii}}$	110.52(9)	110.69(10)	110.48(5)
$\text{O}(2)^{\text{iii}}-\text{P}-\text{O}(3)^{\text{v}}$	109.47(9)	109.35(12)	109.44(5)
$\text{O}(3)^{\text{iii}}-\text{P}-\text{O}(3)^{\text{v}}$	103.17(9)	103.25(11)	103.56(8)

Table 4-3 cont.

angles at bridging oxygens

angle	Crystal I	Crystal II	Rice, <u>et al.</u>
V-O(2)-P	146.56(8)	146.40(10)	146.36(6)
P-O(3)-Si	142.36(8)	142.50(10)	142.21(6)

Symmetry code

i)	x	y	z	iv)	-x	-y	z
ii)	-x	y	$\frac{1}{2}+z$	v)	$\frac{1}{2}+x$	$\frac{1}{2}-y$	$\frac{1}{2}-z$
iii)	$\frac{1}{2}-y$	$\frac{1}{2}+x$	z	vi)	$\frac{1}{2}-y$	$\frac{1}{2}-x$	$\frac{1}{2}+z$
			vii)	$\frac{1}{2}-x$	$\frac{1}{2}+y$	$\frac{1}{2}-z$	

Table 4-4. Lattice parameters for $\text{VO}_2\text{Si}_x\text{V}_{1-x}\text{O}_8$

a	c	Reference
8.723(1)	8.151(1)	This work, crystal I for $x = 1.00(1)$
8.733(2)	8.185(3)	This work, crystal II for $x = 0.95(1)$
8.697(8)	8.119(8)	Tofield, <u>et al.</u> ⁷⁷ from powder pattern
8.747(2)	8.167(2)	Rice, <u>et al.</u> ⁴⁶ from single crystal

microprobe analysis), lattice parameters and bond lengths. The electron microprobe analysis gave molar ratios of V:Si:P = 1.0(1):1.0(1):2.0 for crystal I and ratios of V:Si:P = 1.05(10):0.95(9):2.0 for crystal II. The lattice parameters for the second crystal are larger as are the Si-O bond-lengths (table 4-3). This evidence, together with the least-squares refinement of the occupation number of the silicon for crystal II, suggests vanadium substitution at the silicon site. The electron microprobe data alone are inconclusive, but the additional information available leads one to suggest that the errors in these data may perhaps be smaller than estimated and the differences may be significant.

Crystals of the form $VOP_xSi_yV_zO_8$ can probably be prepared with various values of x, y and z. However, the solid solution behaviour of this system remains to be investigated; the presently available data merely suggest that substitution and/or vacancy formation is possible.

CHAPTER 5

Crystal Structure and Disorder in $\text{VO}(\text{PO}_3)_2$

§ 5.1 Solution of Structure

The structure was determined for two isostructural tetragonal crystals. Crystal I was prepared from VSO_5 and H_3PO_4 (p.45) and has cell parameters $a=10.960(1) \text{ \AA}$, $c=4.253(1) \text{ \AA}$. Crystal II, grown in a vanadium rich atmosphere (p.44) has cell parameters $a=10.975(3) \text{ \AA}$, $c=4.253(1) \text{ \AA}$. The structure was first solved for crystal I, and the coordinates obtained were used as starting coordinates in the least-squares refinement for crystal II.

The space group was established as either $I4_1md$ or $I\bar{4}2d$ from the systematic extinctions ($0k\ell$, $k+\ell \neq 2n$; $h0\ell$, $h+\ell \neq 2n$; 00ℓ , $\ell \neq 4n$; $h+k+\ell \neq 2n$). Since there are only four vanadium atoms per unit cell, they must necessarily lie on the 4_1 or $\bar{4}$ axes for the respective space groups. From the Patterson function, the phosphorus atom can be placed $(\frac{1}{2}, 0.16, 0)$ from V, and an oxygen atom (denoted $O(V)$), bonded axially to V, at a point $(0, 0, 0.38)$ away. This gives the following trial models:

A: for $I4_1md$, V at $0, 0, 0$
 P at $0.25, 0.16, 0.0$
 $O(V)$ at $0, 0, 0.38$ or $0, 0, -0.38$

The phosphorus position is sixteen-fold and, since there are only eight phosphorus atoms, these atoms will have to be disordered, each position having half occupancy.

B: for $I\bar{4}2d$,
 V at 0,0,0
 P at $\frac{1}{4}, 0.16, 0$
 O(V) at 0,0,0.38

Again the phosphorus has to be disordered as for model A, and so does the O(V) atom.

C: for $I\bar{4}2d$, an alternative model is
 V at 0,0,0.12
 P at $\frac{1}{4}, 0.16, -1/8$
 O(V) at 0,0,0.5

This alternative will require the V and O(V) atoms to be disordered, occupying with half-occupancy positions at 0,0, $\pm z$. The phosphorus atom here will not be disordered since it sits on an 8-fold special position.

All the foregoing models were tried. The remaining oxygen atoms were found from difference maps, and were disordered for each model where the phosphorus positions were disordered. The completely refined (by full-matrix least-squares) models gave R-factors of 0.23, 0.21 and 0.097 for models A, B and C respectively. Model C was therefore assumed to be the correct one. Since the two disordered positions for O(V) were $\frac{1}{4}A$ or less apart, only the isotropic thermal coordinate was refined for this atom, and the position was determined by successively placing the atom at $z = 0.47, 0.475, 0.48, 0.485, 0.49$ and 0.495 , and picking the position which yielded the lowest R-factor. Since the R-factor for model C was still high, refinement of this model was tried in each of the sub-groups of $I\bar{4}2d$ ($I\bar{4}$, Fdd2, and $I2_12_12_1$). The first sub-group would require the glide-plane extinctions to be accidental, while the last two sub-groups, which are orthorhombic, would require the equivalence

of a and b to be accidental. None of these lower symmetry sub-groups improved the agreement significantly.

A final difference map gave residual peaks at $0.16, \frac{1}{4}, -1/8$ and its symmetry related points. This, together with the quite high R-factors, suggests further disordering. Possible models for this disordering will be discussed later but, when they were refined, no significant improvement was noted in the agreement. Final coordinates for crystal I are in table 5-1, and for crystal II in table 5-2.

Since the second crystal has a larger value for a, and the P-0(2) bond length is 0.02 \AA larger than that for the first crystal (table 5-3), the possibility of vanadium substitution at the phosphorus site was investigated. The occupation for the phosphorus atom in both crystals was varied in the least-squares refinement to allow for vanadium substitution. The refinement showed no significant change for crystal I, and 6% substitution of V for P in crystal II. This amount is suggestive, but far from conclusive, of substitution of V for P in crystal II. The occupational refinement is probably not very accurate since the phosphate chain may be disordered, thereby making the occupation of any individual phosphorus position less than one.

The 0,2,2 reflection had a large difference between F_o and F_c and, since it was by far the strongest reflection, it was assumed to be greatly affected by extinction and was given zero weight in the refinement for both crystals. A weighting scheme $((19.9 - 0.906|F| + 0.0154|F|^2 + 1000(\sigma/F)^2)^{-1})$ was used with crystal I to give final $R=0.097$ and $R_w=0.114$. The R-values for crystal II are $R=0.12$ and $R_w=0.14$ ($w=(15.5 - 0.15|F| + 0.0162|F|^2 + 1000(\sigma/F)^2)^{-1}$).

Table 5-1. Positional and thermal coordinates for $\text{VO}(\text{PO}_3)_2$ (crystal I). Values for the thermal coordinates are multiplied by 10^4 . Estimated standard deviations are in parentheses.

Atom	x	y	z	$U_{11}(\text{\AA}^2)$	$U_{22}(\text{\AA}^2)$	$U_{33}(\text{\AA}^2)$	$U_{12}(\text{\AA}^2)$	$U_{13}(\text{\AA}^2)$	$U_{23}(\text{\AA}^2)$
V	0	0	0.0960(20)	130(20)	110(20)	130(20)	20(20)	0	0
P	1/4	0.1614(3)	-1/8	100(20)	70(20)	120(20)	0	40(20)	0
O(1)	0.1901(9)	1/4	5/8	110(40)	150(40)	160(40)	0	0	10(40)
O(2)	0.1486(7)	0.0934(7)	0.0300(20)	170(30)	170(30)	250(40)	-80(30)	-60(30)	10(30)
O(V)	0	0	0.4750(50)	140(30) [†]					

[†] Isotropic thermal coordinate

Table 5-2. Positional and thermal coordinates for $\text{VO}(\text{PO}_3)_2$ (crystal II). Values for the thermal coordinates are multiplied by 10^3 . Estimated standard deviations are in parentheses.

Atom	x	y	z	$U_{11}(\text{\AA}^2)$	$U_{22}(\text{\AA}^2)$	$U_{33}(\text{\AA}^2)$	$U_{12}(\text{\AA}^2)$	$U_{13}(\text{\AA}^2)$	$U_{23}(\text{\AA}^2)$
V	0	0	0.089(2)	17(3)	11(3)	12(2)	7(2)	0	0
P	1/4	0.161(1)	-1/8	11(2)	9(2)	13(2)	0	7(2)	0
O(1)	0.190(1)	1/4	5/8	11(6)	20(5)	30(7)	0	0	16(7)
O(2)	0.149(1)	0.093(1)	0.039(3)	22(5)	20(5)	22(5)	-4(4)	-7(4)	6(4)
O(V)	0	0	0.475(5)	18(5) [†]					

[†] Isotropic thermal coordinate

Table 5-3. Bond angles ($^{\circ}$) and distances (\AA) for the two crystals of $\text{VO}(\text{PO}_3)_2$. Estimated standard deviations are indicated in parentheses.

VO_6 group

bond	crystal I	crystal II	angle	crystal I	crystal II
V-O(V)	1.62(1)	1.64(1)	$\text{O(V)}-\text{V}-\text{O(V)}^{\text{i}}$	180	180
V-O(V)^{i}	2.63(1)	2.61(1)	$\text{O(V)}-\text{V}-\text{O(2)}$	98.3(3)	96.4(4)
$\text{V-O(2)} \times 2$	1.944(8)	1.94(1)	$\text{O(V)}-\text{V}-\text{O(2)}^{\text{i}}$	105.6(3)	105.7(4)
$\text{V-O(2)}^{\text{i}} \times 2$	1.997(8)	2.00(1)	$\text{O(2)}-\text{V}-\text{O(2)}^{\text{i}}$	87.8(3)	88.3(5)
			$\text{O(2)}-\text{V}-\text{O(2)}^{\text{ii}}$	163.5(5)	167.2(7)
			$\text{O(2)}^{\text{i}}-\text{V}-\text{O(2)}^{\text{iii}}$	148.8(5)	148.5(6)

PO_4 group

bond	crystal I	crystal II	angle	crystal I	crystal II
$\text{P-O(1)} \times 2$	1.582(5)	1.584(6)	$\text{O(1)}-\text{P}-\text{O(2)} \times 2$	107.1(5)	107.5(6)
$\text{P-O(2)} \times 2$	1.492(9)	1.510(12)	$\text{O(1)}-\text{P}-\text{O(2)}^{\text{iv}} \times 2$	108.6(4)	108.0(7)
			$\text{O(1)}-\text{P}-\text{O(1)}^{\text{v}}$	104.4(3)	104.2(4)
			$\text{O(2)}-\text{P}-\text{O(2)}^{\text{iv}}$	120.0(5)	120.5(7)

bridging angles

angle	crystal I	crystal II
$\text{V-O(2)}-\text{P}$	162.0(4)	158.9(6)
$\text{V-O(2)}^{\text{vi}}-\text{P}^{\text{vi}}$	138.2(4)	136.8(6)
$\text{P-O(1)}-\text{P}$	131.0(4)	130.9(5)

Symmetry operations

i) $x \quad -y \quad -z$	iv) $\frac{1}{2}-x \quad y \quad \frac{3}{4}-z$
ii) $-x \quad -y \quad z$	v) $\frac{1}{2}-x \quad \frac{1}{2}-y \quad \frac{1}{2}+z$
iii) $-x \quad y \quad -z$	vi) $-y \quad x \quad -z$

§ 5.2 Description of the Structure

Like VOP_2SiO_8 and $\alpha-VPO_5$, the vanadium atom has one long and one short axial bond directed along a 4-fold axis. These bonds join adjacent VO_6 groups to form chains in the \underline{c} direction. The V^{+4} atom is displaced by about 0.4 \AA along the $\bar{4}$ axis from the centre of the VO_6 octahedron. Unlike VOP_2SiO_8 and $\alpha-VPO_5$, the equatorial oxygen atoms do not lie in a plane. $\bar{4}$ symmetry places two diagonally opposite oxygen atoms about $1/8 \text{ \AA}$ above the $z=0$ plane, and the other two about $1/8 \text{ \AA}$ below this plane. Neighbouring VO_6 chains are parallel, but corresponding octahedra are displaced by $+\frac{1}{4}\underline{c}$ or $-\frac{1}{4}\underline{c}$ from neighbouring groups.

The VO_6 chains are corner-shared with phosphate tetrahedra which are linked together to make up infinite $(PO_3)_\infty$ metaphosphate chains. Each of the metaphosphate chains links four VO_6 chains (figs. 5-1 and 5-2). The phosphate groups within a chain are related by a 2_1 axis in the (001) direction at $(\frac{1}{4}, \frac{1}{4}, z)$. The chains are related to their four neighbouring chains by a $\bar{4}$ axis at the origin parallel to \underline{c} . The two distinct P-O(-V) and P-O(-P) bond lengths of 1.492(9) and 1.582(5) have a difference of 0.090 \AA falling between the values predicted by Brown¹⁶ (0.146 \AA) and Baur⁹⁴ (0.065 \AA). A complete table of bond-lengths and angles is given in table 5-3.

This structure is different from that of any of the three known polymorphs of SiP_2O_7 ^{81,82,83} even though stoichiometrically the two structures are similar ($VO(PO_3)_2$ could be written as VP_2O_7). All the polymorphs of SiP_2O_7 consist of P_2O_7 groups joined by SiO_6 octahedra. Each octahedron shares corners with six P_2O_7 groups. Structures of the form MP_2O_7 (isostructural to a cubic polymorph of SiP_2O_7 according to powder

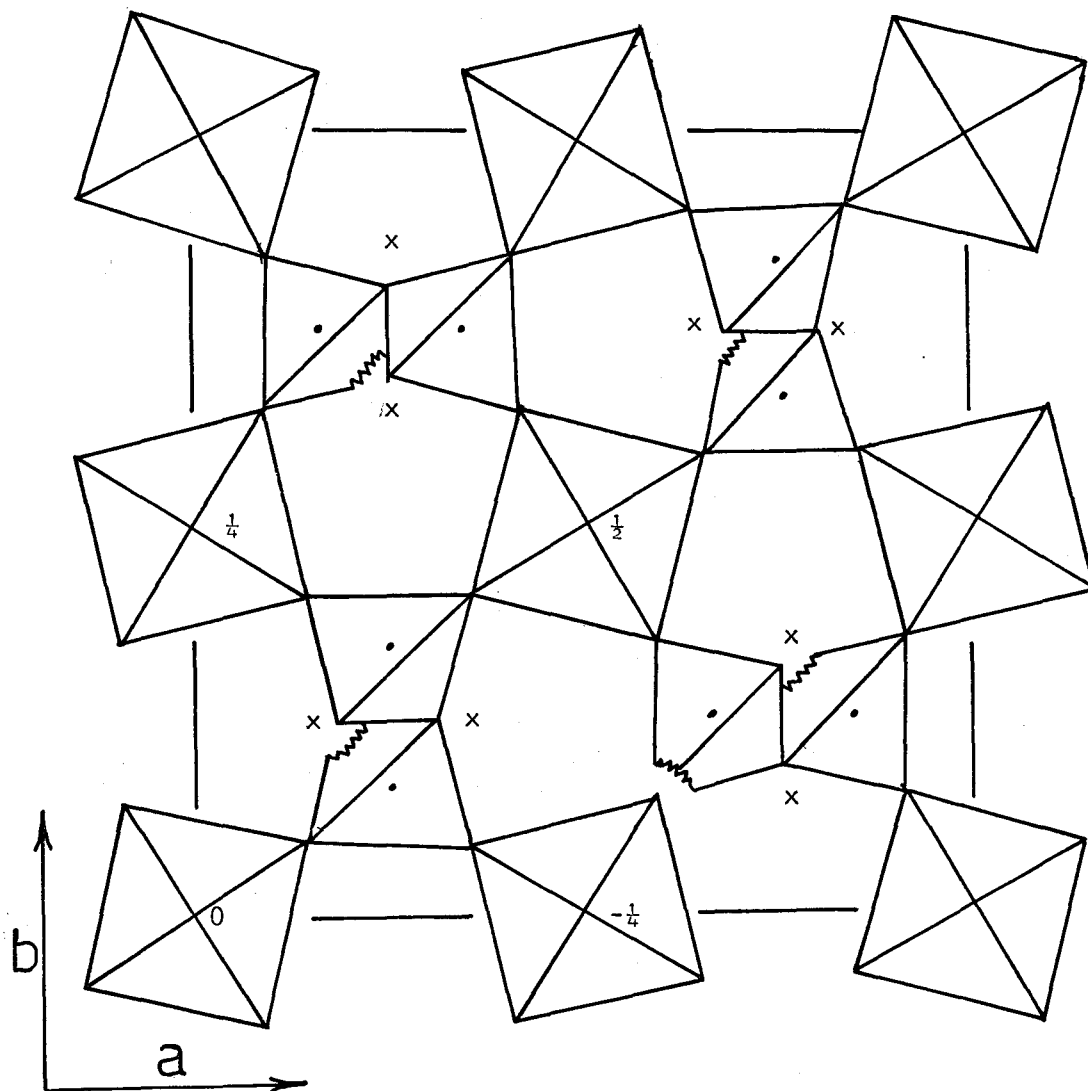


Figure 5-1. The crystal structure of $V_0(P_0_3)_2$ projected down the c axis. The vanadium atoms are disordered being located approximately ± 0.096 above and below the z -values indicated on the diagram. The positions of residual density are indicated by (x).

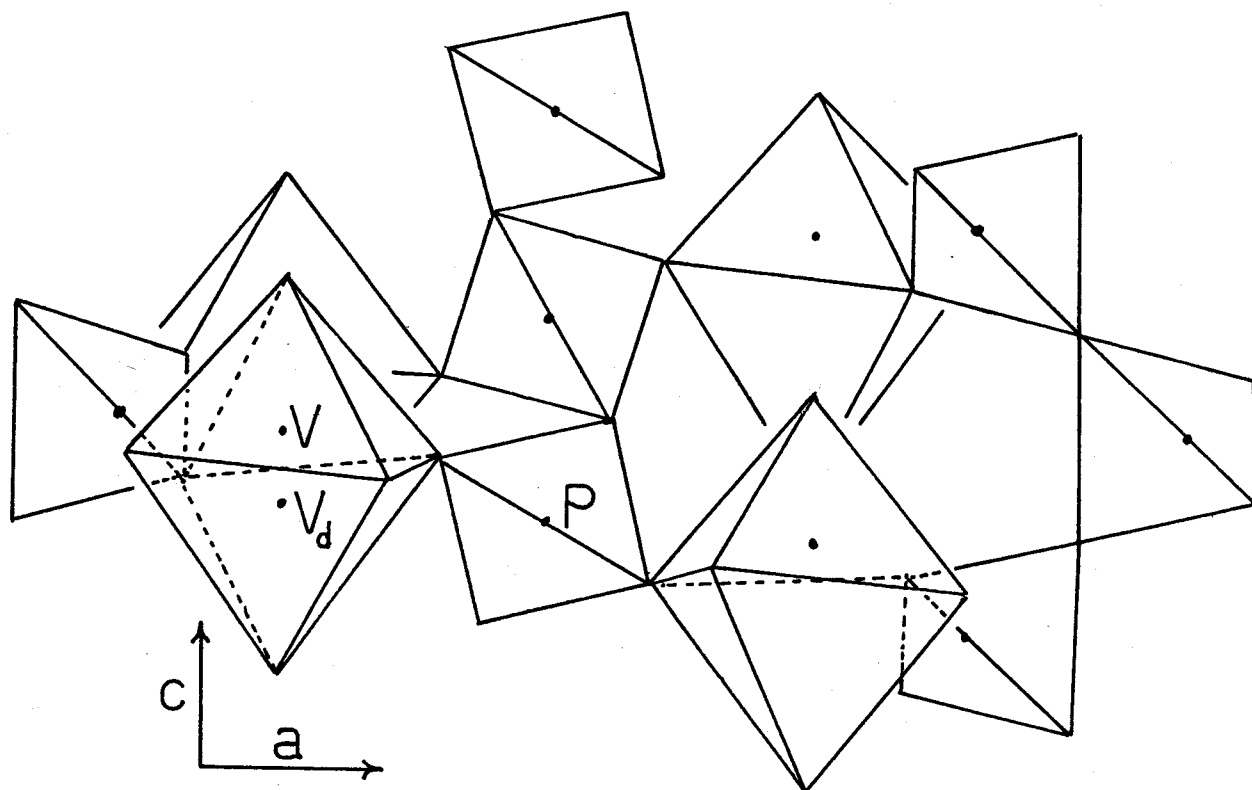


Figure 5-2. The crystal structure of $\text{VO}(\text{PO}_3)_2$ projected along the b -axis. The two possible positions of the vanadium atom are indicated as V and V_d within one of the octahedra.

patterns) also exist for $M = \text{Si}^{81}, \text{Ge}^{84}, \text{Sn}^{85}, \text{Zr}^{86}, \text{Pb}, \text{Ti}, \text{Hf}, \text{Ce}$ and $\text{U}^{87,88}$. It is likely that the difference in structures arises from the characteristic vanadyl and long axial V-O bonds which occur in all known structures containing V^{+4} , but are unknown for most of the other cations. The short V-O bond has a bond valence of 1.6, and it would be difficult for a PO_4 group to share such an oxygen atom.

§ 5.3 Substitutional Disorder

Bordes and Courtine⁴⁰ have reported the preparation of powders all having the same powder pattern and having the composition $\text{VO}(\text{P}_x\text{V}_{1-x}\text{O}_3)_2$ over the range $1 \leq x \leq 0.9$. It is reasonable to assume that such crystals are substitutionally disordered with V^{+5} at the phosphorus site. The crystals studied in this thesis fall within the range found by Bordes and Courtine according to the least-squares refinement of occupations. Other evidence for either crystal being substitutionally disordered is not very good. Electron microprobe analysis gave a value of $x=1.0(1)$ for crystal I and $x=0.9(1)$ for crystal II. The differences in bond lengths, as shown in table 5-3, are also within the standard error. It is possible that the errors in both structures are over-estimated, but no real conclusion can be drawn as to the extent of substitutional disordering.

§ 5.4 Positional Disorder

The vanadium atoms with their corresponding vanadyl oxygens can exist in one of two positions as determined from the refinement. The VO_6 chains can consequently have the vanadyl bonds pointing either along \underline{c} or $-\underline{c}$. Such disordering would produce diffuse lines through the Bragg reflections parallel to \underline{a}^* and \underline{b}^* . Two-week-long exposures of

the $h0\ell$ and $0k\ell$ photographs showed such diffuse lines as illustrated schematically in figure 5-3. They are very weak since only a change in the vanadium atom position contributes significantly to the disordering; the change of position for $O(V)$ being of negligible magnitude. The diffuse streaks appear to be of uniform intensity indicating the disorder is perfectly random. Thus, any one VO_6 chain can have the vanadyl bonds point in the $+\underline{c}$ or $-\underline{c}$ direction, and its neighbouring chains all have an equal probability of being oriented in either direction.

The residual peaks found in the final difference map suggest that additional disorder may be present. Three possible models for such disordering were considered.

- A. The structure is reflected in the $1\bar{1}0$ plane. This would introduce additional disordered vanadium atoms at the points $0, \frac{1}{2}, 3/4 \pm 0.096$ and $\frac{1}{2}, 0, \frac{1}{4} \pm 0.096$.
- B. The structure is rotated about $(\pm \frac{1}{4}, \pm \frac{1}{4}, z)$. This would introduce vanadium atoms displaced by $-\frac{1}{4}$ in z from the original positions.
- C. The metaphosphate chains undergo a 4_1 rotation at $(\pm \frac{1}{4}, \pm \frac{1}{4}, z)$. This would require no further disordering of the vanadium positions.

All three of these models were tested as follows. The atoms were assumed to partially occupy the positions in the basic structure and partially the positions in the disordered structure in such a way that the total occupation is equal to the number of atoms in the chemical formula. A least-squares refinement of the occupations (keeping the total occupation constant) using observed and calculated structure factors was then carried out. All such refinements invariably increased the R-factor. It was then felt that perhaps the domain size was large enough to make

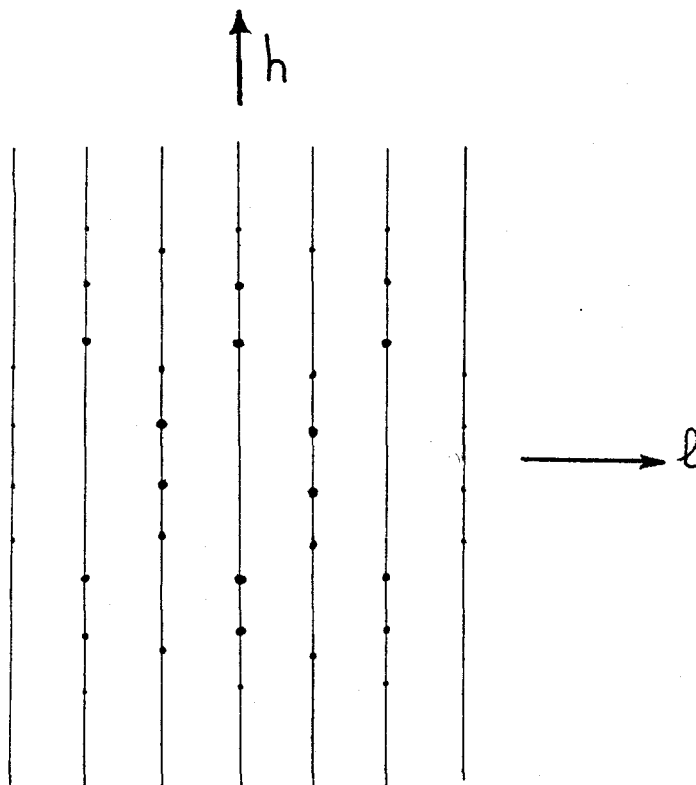


Figure 5-3. A schematic representation of the $h0l$ projection of $\text{VO}(\text{PO}_3)_2$ showing the diffuse streaks going through the Bragg diffraction spots. The intensity of the streaks has been greatly exaggerated.

the structure factors of the basic and disordered structures no longer additive. A least-squares refinement was then carried out on the parameter α and the occupation, x , in $I_{\text{obs}} = |F_1|^2 + |xF_2|^2 + \alpha(xF_1F_2^* + xF_1^*F_2)$ where F_1 is the structure factor for the basic structure, F_2 is the structure factor for the disordered positions, F_i^* is the complex conjugate of F_i , and I_{obs} is the observed intensity. The absolute values of F_1 and F_2 are nearly the same, but their phases differ. No convergence was found for $0 < \alpha < 1$ which is the range possible for α (see p.32). The domain size, therefore, does not seem to be a factor preventing a suitable solution of the disordering.

One of the problems with the foregoing models is that a reorientation of the VO_6 groups is required, which is large enough to introduce considerable strain. Such strain could be avoided if the disorder represents a cooperative reorientation within a complete plane perpendicular to \underline{c} . Such a model would produce streaks along \underline{c}^* which were not observed. Another means of minimizing such a strain is the introduction of an average VO_6 orientation at the boundaries between two structural positions. E.g. if for one structure the bridging V-O-P oxygen is located at (0.15,0.09,0.03) and for the disordered structure it is located at (0.09,0.15,0.03) as in model C, then the boundary bridging oxygens could be located at (0.12,0.12,0.03) and the corresponding points determined by the $\bar{4}$ operation. This would keep the geometry of the VO_6 group reasonable and would introduce some strain in the metaphosphate chain which can be easily compensated for by a slight rotation. If the domains are small enough, boundary effects can be considerable, and the models tested will not work unless all these effects have been considered.

An attempt was made to see if the disordering would disappear at

lower temperatures. hkl reflections were compared at room temperature and at -150°C . No significant changes in intensities were observed.

CHAPTER 6

The Crystal Structure and Thermal Behaviour of $V(\text{PO}_3)_3$

§ 6.1 Solution of the Crystal Structure

The structure determination was begun by Dr. F.C. Hawthorne with a unit cell of $a=10.615\text{\AA}$, $b=6.365\text{\AA}$, $c=9.432\text{\AA}$; $\beta=97.9^\circ$ and space group is $1c$ or $12/c$. He solved the structure in $12/c$ and refined it to an R-factor of about 20% from the Patterson function. Some of the bond-lengths and angles in his solution were unsatisfactory.

Subsequently, I took a week-long-exposure precession photograph of $V(\text{PO}_3)_3$ which showed that the b-axis is triple that of Hawthorne, but the possible space groups remain the same. Only $k=3n$ reflections have strong intensities. The structure must consist of three of Hawthorne's cells, with small structural variations from one to the next. This is only possible in the non-centrosymmetric space group $1c$. Tofield, et al.⁴⁵ also selected $1c$ as the space group on the basis of second harmonic generation, and found the lattice parameters of the tripled cell.

A difference map from the $k=3n$ reflections based on the atomic positions in the large cell (supercell) that correspond to those of Hawthorne's cell (subcell) failed to yield any structural variations from the substructure. The heavy atoms were displaced from the substructure positions by 0.01 in different directions, one at a time, and a least-squares refinement was carried out varying only the coordinates in the third of the cell containing the atom for which the initial displacement was made. If the R-factor decreased, this displacement was allowed: if

it increased, another displacement was tried. This process was continued in conjunction with a lowering R-factor until all the positions were simultaneously varied, at which point the isotropic thermal coordinates were also included in the least squares refinement. Computer limitations prevented anisotropic thermal coordinates from being refined. Final coordinates are listed in table 6-1. Since there was no a priori reason for assuming any direction for the shifts from the average cell, the possibility of a false minimum in the least squares fit exists.. A β^{89} synthesis, which is a Fourier sum of terms of the form $(|F_o|^2/|F_c|)\exp(i\phi_c)$, where F_o is the observed structure factor, F_c the calculated structure factor, and ϕ_c the calculated phase angle, was calculated based on the vanadium and phosphorus atom positions. This synthesis is an electron density map which applies the weight F_o/F_c to the structure factors. If $F_c \gg F_o$, at least some of the atomic co-ordinates which contribute significantly to the value for F_c must be wrong. The weight, F_o/F_c , will be small, and hence peaks which would result from incorrectly placed atoms will be depressed. If $F_c \ll F_o$, unknown atomic positions must contribute significantly to F_c . The weight for such a structure factor will be large and peaks indicating unknown atom positions will therefore be enhanced. No solutions different from the one refined were found from the β map. Recently, the structure of $Al(PO_3)_3$ has been determined⁹⁰. It is isostructural with the model of $V(PO_3)_3$ proposed here, suggesting that this structure is correct.

The final R and R_w were 0.091 and 0.065 respectively ($w=(46-0.53|F|+0.0023|F|^2+1000(\sigma/F)^2)^{-1}$). The agreement for only the $k \neq 3n$ reflections was $R=0.134$ and $R_w=0.094$. The larger values are not unreasonable since

Table 6-1. Positional and thermal coordinates for $V(\text{PO}_3)_3$.
 Estimated standard deviations are indicated in parentheses.

Atom	x	y	z	$U(\text{\AA}^2)$
V(a)	$\frac{1}{4}$	0.0798(2)	$\frac{1}{4}$	0.0057(5)
V(b)	0.2529(5)	0.4115(2)	0.2479(6)	0.0049(5)
V(c)	0.2308(3)	0.7549(2)	0.2631(4)	0.0056(6)
P(1)	0.9756(6)	0.1442(3)	0.7657(7)	0.0059(8)
P(2)	0.0156(5)	0.4803(2)	0.7409(6)	0.0063(8)
P(3)	0.0027(5)	0.8142(2)	0.7476(6)	0.0043(7)
P(4)	0.1026(5)	0.3018(2)	0.4404(6)	0.0051(8)
P(5)	0.0967(5)	0.6370(2)	0.4420(6)	0.0050(8)
P(6)	0.1168(6)	0.9681(3)	0.4363(7)	0.0073(9)
P(7)	0.8791(6)	0.6965(2)	0.5748(7)	0.0056(9)
P(8)	0.8809(6)	0.3629(2)	0.5710(6)	0.0036(8)
P(9)	0.8961(5)	0.0267(3)	0.5561(6)	0.0056(8)
O(a,2)	0.9033(10)	0.5190(6)	0.7784(13)	0.0106(21)
O(a,3)	0.0884(10)	0.1321(5)	0.2112(12)	0.0062(19)
O(a,6)	0.1501(12)	0.9981(6)	0.2994(14)	0.0068(22)
O(a',6')	0.2262(13)	0.0544(7)	0.0417(16)	0.0120(26)
O(a,7)	0.8502(11)	0.6635(6)	0.7091(13)	0.0092(20)
O(a,8)	0.7808(10)	0.6097(6)	0.9585(13)	0.0051(20)
O(b,2)	0.1211(11)	0.4803(7)	0.1862(13)	0.0114(22)
O(b,3)	0.8865(12)	0.8371(7)	0.8006(15)	0.0145(24)
O(b,4)	0.1266(12)	0.3577(6)	0.3473(15)	0.0159(24)

table 6-1 cont.

Atom	x	y	z	$U(\text{\AA}^2)$
O(b,5)	0.2044(11)	0.3651(6)	0.0631(13)	0.0085(20)
O(b,9)	0.8769(11)	0.9686(6)	0.6562(13)	0.0049(19)
O(b',9')	0.8011(11)	0.9652(6)	0.9295(13)	0.0045(20)
O(c,1)	0.0930(13)	0.8251(7)	0.2191(15)	0.0112(24)
O(c',1')	0.8775(11)	0.1913(6)	0.8121(13)	0.0057(21)
O(c,4)	0.2022(12)	0.7099(7)	0.0734(15)	0.0130(24)
O(c,5)	0.1070(10)	0.6876(5)	0.3255(12)	0.0086(19)
O(c,7)	0.7683(11)	0.2840(6)	0.9689(14)	0.0083(21)
O(c,8)	0.8414(10)	0.3298(6)	0.6975(13)	0.0106(21)
O(4,3)	0.0835(10)	0.2294(6)	0.3723(12)	0.0068(19)
O(4,8)	0.9695(10)	0.6892(6)	0.0056(13)	0.0091(20)
O(5,2)	0.0776(10)	0.5603(5)	0.3814(11)	0.0058(18)
O(5,7)	0.9679(11)	0.3545(6)	0.0103(14)	0.0136(22)
O(6,1)	0.0125(13)	0.9079(7)	0.3906(16)	0.0091(25)
O(6,9)	0.0360(11)	0.9765(6)	0.0181(13)	0.0062(21)
O(7,3)	0.9673(11)	0.7633(6)	0.6137(13)	0.0095(21)
O(8,2)	0.9770(12)	0.4235(7)	0.6178(15)	0.0139(24)
O(9,1)	0.9072(12)	0.0973(7)	0.6453(15)	0.0115(25)

these are the weaker reflections and have a smaller relative accuracy.

§ 6.2 Description of the Structure

The structure of the average cell is shown in figure 6-1. It consists of tetrahedral $(\text{PO}_3)_\infty$ chains which zig-zag in the c direction. VO_6 octahedral are found between these chains and are bridged to neighbouring VO_6 groups in the a direction by a phosphate tetrahedron in each of two chains, and in the c direction by two phosphate groups in each of two chains. The structure differs from VPO_5 , and $\text{VO}(\text{PO}_3)_2$ in the lack of vanadyl bonds, and VO_6 chains.

As can be seen from figure 6-2, the major differences between each third of the cell along b lie in the orientations of the polyhedra. There do not appear to be large differences between the corresponding bond lengths and angles for the polyhedra in the three parts of the cell (table 6-2).

The different types of bonds and angles are summarized in table 6-3. The P-O(-P) bond lengths are consistently larger than the P-O(-V) bond lengths, the average difference of 0.10 Å falling between the values predicted by Baur⁹⁴(0.08Å) and Brown¹⁶(0.15Å). The (V-)-O-P-O(-P) angle is consistently the largest angle in all the PO_4 tetrahedra, and the angle (P-)O-P-O(-P) is consistently the smallest, although the (P-)O-P-O(-V) angle of one phosphate group is sometimes smaller than the (P-)O-P-O(-P) angle in another. The VO_6 octahedra are close to being regular since the maximum difference between V-O bonds in any one group is 0.07(2) Å, and the axial and equatorial angles at the vanadium atoms are close to 180° and 90° respectively.

Table 6-4 gives the distances between corresponding atoms in

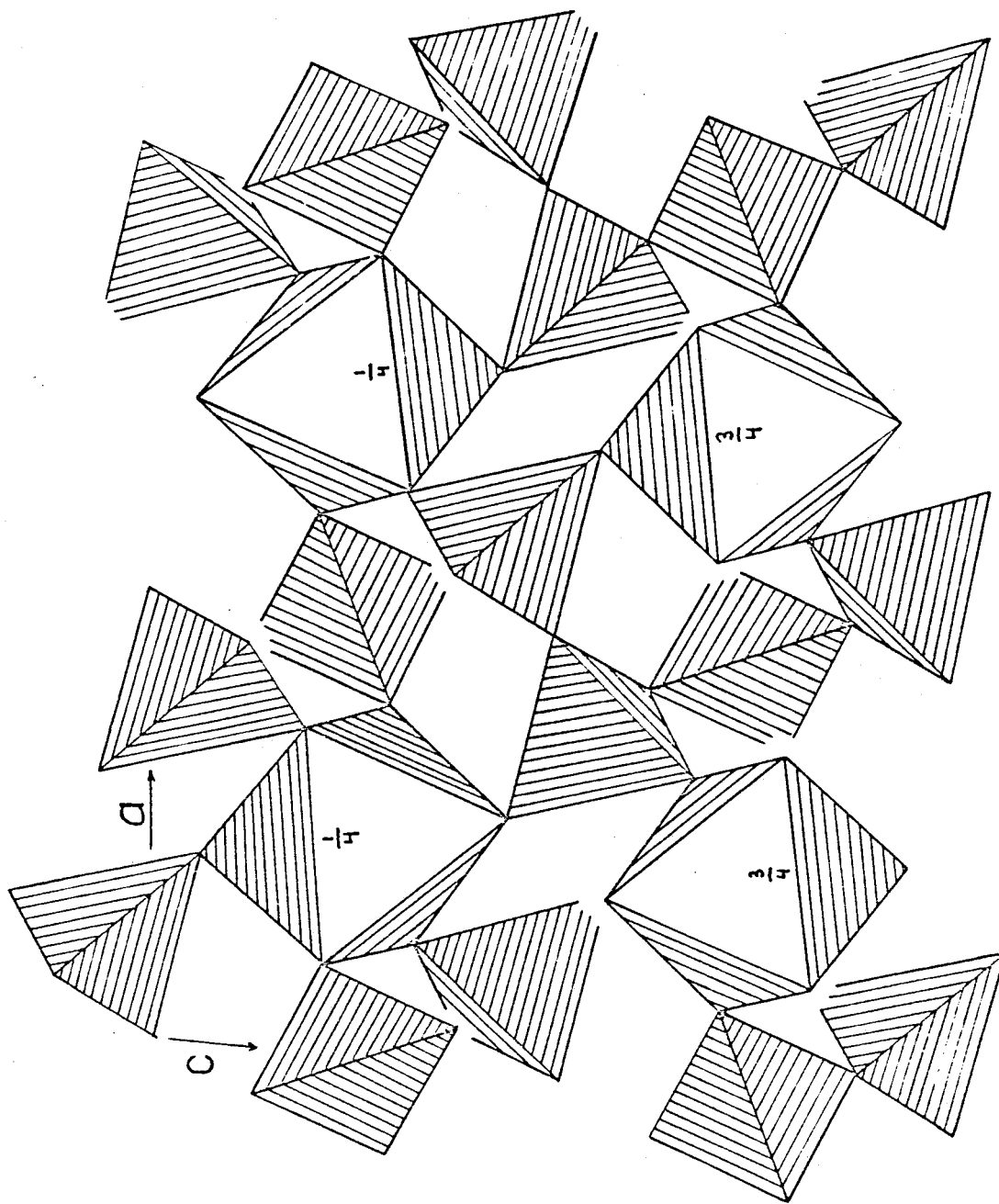


Figure 6-1. The average structure of $V(P0)_3$ projected down the b axis. The approximate y coordinates of the V^{+3} atoms are shown with respect to the small cell. Phosphorus atoms lie within the tetrahedra.

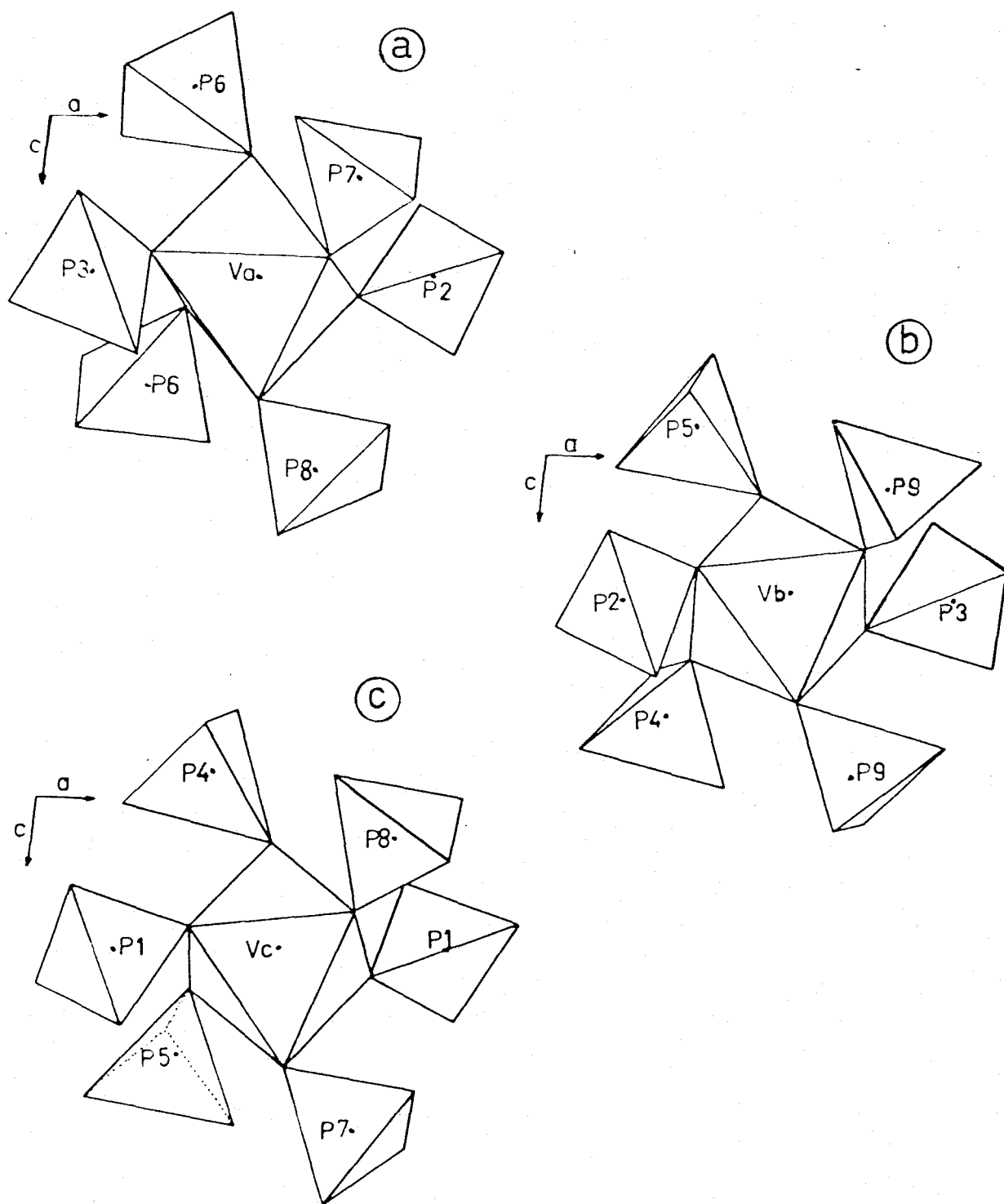


Figure 6-2. The environments about the vanadium atoms near $x, z = \frac{1}{4}, \frac{1}{4}$ for the three ranges (a) $0 \leq y < \frac{1}{3}$, (b) $\frac{1}{3} \leq y < \frac{2}{3}$ (c) $\frac{2}{3} \leq y \leq 1$.

Table 6-2. Bond Geometry in $V(PO_3)_3$. The oxygen atoms are listed sequentially counterclockwise as they appear in diagram 5-2. They are labelled according to the atoms they bridge. Estimated standard deviations are in parentheses.

VO_6 groups - bonds are of the type $V(x)-O(x,y)$

distances (Å) for $V(a)O_6$			distances (Å) for $V(b)O_6$			distances (Å) for $V(c)O_6$		
x	y	distance	x	y	distance	x	y	distance
a	2	1.99(1)	b	3	2.02(1)	c'	1'	1.98(1)
a	7	1.99(1)	b'	9'	2.00(1)	c	8	2.00(1)
a'	6'	2.01(2)	b	5	1.96(2)	c	4	1.97(2)
a	3	1.98(1)	b	2	1.95(1)	c	1	1.98(1)
a	6	1.98(1)	b	4	2.02(1)	c	5	1.99(1)
a	8	2.03(2)	b	9	2.00(2)	c	7	2.01(2)

angles are of the type $O(x,y)-V(x)-O(x,z)$

angles (°) for $V(a)O_6$				angles (°) for $V(b)O_6$				angles (°) for $V(c)O_6$			
x	y	z	angle	x	y	z	angle	x	y	z	angle
a	2	7	92.6(5)	b	3	9'	90.5(5)	c	1'	8	92.0(5)
a	2	6'	88.9(6)	b	3	5	89.4(7)	c	1'	4	87.8(6)
a	2	3	172.6(6)	b	3	2	176.5(9)	c	1'	1	175.4(6)
a	2	6	87.9(5)	b	3	4	90.9(5)	c	1'	5	93.7(5)
a	2	8	90.8(6)	b	3	9	93.6(7)	c	1'	7	84.2(6)
a	7	6'	90.1(6)	b	9'	5	88.3(6)	c	8	4	93.1(6)
a	7	3	91.1(5)	b	9'	2	89.5(5)	c	8	1	84.3(5)
a	7	6	177.5(6)	b	9'	4	177.2(6)	c	8	5	174.3(5)
a	7	8	86.8(6)	b	9'	9	89.1(5)	c	8	7	93.2(6)
a	6'	3	84.6(6)	b	5	2	87.1(7)	c	4	1	95.1(7)
a	6'	6	92.3(6)	b	5	4	94.2(6)	c	4	5	87.8(6)
a	6'	8	176.9(5)	b	5	9	176.0(6)	c	4	7	170.0(6)

table 6-2 cont.

angles ($^{\circ}$) for V(a) 0_6				angles ($^{\circ}$) for V(b) 0_6				angles ($^{\circ}$) for V(c) 0_6			
x	y	z	angle	x	y	z	angle	x	y	z	angle
a	3	6	88.7(5)	b	2	4	89.3(5)	c	1	5	90.0(5)
a	3	8	95.8(5)	b	2	9	89.9(6)	c	1	7	93.3(7)
a	6	8	90.8(6)	b	4	9	88.4(6)	c	5	7	86.8(6)

P 0_4 groups - bonds are of the type P(x)-O(y,x)

distances (\AA) for P(2) 0_4			distances (\AA) for P(3) 0_4			distances (\AA) for P(1) 0_4		
x	y	distance	x	y	distance	x	y	distance
2	a	1.49(1)	3	b	1.46(1)	1	c'	1.49(1)
2	5	1.60(2)	3	4	1.59(2)	1	6	1.55(2)
2	b	1.49(1)	3	a	1.48(1)	1	c	1.50(1)
2	8	1.60(2)	3	7	1.60(2)	1	9	1.55(2)

angles are of the type O(x,y)-P(y)-O(z,y)

angles ($^{\circ}$) for P(2) 0_4				angles ($^{\circ}$) for P(3) 0_4				angles ($^{\circ}$) for P(1) 0_4			
x	y	z	angle	x	y	z	angle	x	y	z	angle
a	2	5	107.2(8)	b	3	4	107.3(9)	c'	1	6	106.1(9)
a	2	b	119.6(7)	b	3	a	118.5(7)	c'	1	c	119.6(7)
a	2	8	112.1(9)	b	3	7	109.6(9)	c'	1	9	106.8(9)
5	2	b	106.7(8)	4	3	a	106.9(8)	6	1	c	110.0(9)
5	2	8	108.0(8)	4	3	7	108.1(7)	6	1	9	103.3(9)
b	2	8	102.6(8)	a	3	7	106.0(8)	c	1	9	109.7(9)

distances (\AA) for P(6) 0_4			distances (\AA) for P(5) 0_4			distances (\AA) for P(4) 0_4		
x	y	distance	x	y	distance	x	y	distance
6	a'	1.48(2)	5	b	1.50(2)	4	c	1.48(2)
6	a	1.50(2)	5	c	1.48(1)	4	b	1.48(2)

table 6-2 cont.

distances (Å) for P(6)O ₄				distances (Å) for P(5)O ₄				distances (Å) for P(4)O ₄			
x	y	distance		x	y	distance		x	y	distance	
6	1	1.61(2)		5	2	1.58(1)		4	3	1.56(1)	
6	9	1.62(1)		5	7	1.60(1)		4	8	1.59(1)	
angles (°) for P(6)O ₄				angles (°) for P(5)O ₄				angles (°) for P(4)O ₄			
x	y	z	angle	x	y	z	angle	x	y	z	angle
a'	6	a	115.6(8)	b	5	c	117.2(7)	c	4	b	117.9(9)
a'	6	1	114.7(9)	b	5	2	107.4(9)	c	4	3	109.0(9)
a'	6	9	106.6(10)	b	5	7	107.3(7)	c	4	8	105.4(8)
a	6	1	106.1(10)	c	5	2	110.9(9)	b	4	3	110.9(9)
a	6	9	111.3(7)	c	5	7	113.0(7)	b	4	8	112.4(7)
1	6	9	101.8(6)	2	5	7	99.6(6)	3	4	8	100.8(6)
distances (Å) for P(8)O ₄				distances (Å) for P(9)O ₄				distances (Å) for P(7)O ₄			
x	y	distance		x	y	distance		x	y	distance	
8	a	1.49(2)		9	b'	1.46(2)		7	c	1.48(2)	
8	c	1.46(2)		9	b	1.49(1)		7	a	1.49(2)	
8	2	1.57(2)		9	1	1.59(2)		7	3	1.60(1)	
8	4	1.55(1)		9	6	1.58(1)		7	5	1.54(1)	
angles (°) for P(8)O ₄				angles (°) for P(9)O ₄				angles (°) for P(7)O ₄			
x	y	z	angle	x	y	z	angle	x	y	z	angle
a	8	c	118.4(7)	b'	9	b	117.2(8)	c	7	a	116.3(7)
a	8	2	108.3(8)	b'	9	1	109.7(8)	c	7	3	109.9(8)
a	8	4	110.7(9)	b'	9	6	112.6(9)	c	7	5	111.4(10)
c	8	2	109.8(10)	b	9	1	107.7(9)	a	7	3	109.1(10)
c	8	4	107.7(7)	b	9	6	109.3(7)	a	7	5	106.1(8)
2	8	4	100.3(6)	1	9	6	98.7(7)	3	7	5	103.1(6)

Table 6-3. Average bond geometry in $V(PO_3)_3$

Bond	Length(Å)		
	Maximum	Minimum	Average
V - O	2.03(1)	1.95(1)	1.99
P - O(-P)	1.62(1)	1.54(1)	1.58
P - O(-V)	1.50(1)	1.46(1)	1.48

Angle	Angle(°)		
	Maximum	Minimum	Average
O-V-O(axial)	177.5(5)	170.0(5)	175.2
O-V-O	95.8(5)	84.2(5)	90.0
(P-)O-P-O(-P)	108.1(6)	98.7(7)	102.6
(P-)O-P-O(-V)	114.7(8)	102.6(8)	108.8
(V-)O-P-O(-V)	119.6(7)	115.6(8)	117.7

Table 6-4. Distances between corresponding atoms in figure 6-2 when those in 6-2(b) are translated by $-\underline{b}/3$ and those in 6-2(c) are translated by $-2\underline{b}/3$. Oxygen atoms for each polyhedron are listed sequentially starting at the oxygen bridging the P and V atoms and going counterclockwise. Values are in Å.

Atom a from diag. 6-2(a)	Atom b from diag. 6-2(b)	Atom c from diag. 6-2(c)	distance between a and b	distance between a and c	distance between b and c
V(a)	V(b)	V(c)	0.05	0.30	0.35
P(2)	P(3)	P(1)	0.16	0.52	0.36
O(a,2)	O(b,3)	O(c,1')	0.41	0.46	0.43
O(5,2)	O(4,3)	O(6,1)	0.12	0.76	0.83
O(b,2)	O(a,3)	O(c,1)	0.49	0.51	0.53
O(8,2)	O(7,3)	O(9,1)	0.16	0.83	0.74
P(6)	P(5)	P(4)	0.23	0.21	0.10
O(a,6')	O(b,5)	O(c,4)	0.54	0.47	0.24
O(a,6)	O(c,5)	O(b,4)	0.70	0.74	0.28
O(6,1)	O(5,2)	O(4,3)	0.76	0.83	0.12
O(6,9)	O(5,7)	O(4,8)	1.12	1.12	0.06
P(8)	P(9)	P(7)	0.23	0.04	0.28
O(a,8)	O(b,9')	O(c,7)	0.62	0.20	0.61
O(c,8)	O(b,9)	O(a,7)	0.79	0.13	0.81
O(8,2)	O(9,1)	O(7,3)	0.83	0.16	0.74
O(4,8)	O(6,9)	O(5,7)	1.12	0.06	1.12

figure 6-2 when those in 6-2(b) and 6-2(c) are translated by $-b/3$ and $-2b/3$ respectively. As can be seen, two of the vanadium atoms nearly superimpose, and the third, V_c , is displaced only by about $1/3 \text{ \AA}$. The phosphorus atoms, similarly, are quite close to superposition, the biggest difference being about $\frac{1}{2} \text{ \AA}$ between P(1) and P(3). The largest displacement of the oxygen atoms from superposition is 1.2 \AA , the average is 0.6 \AA . This is quite a substantial difference when we consider that a P-O bond has an average value of 1.53 \AA . The angles subtended at the oxygen atoms by the cations to which they bond range from 135° to 151° (9 values) when both cations are phosphorus and from 133° to 158° (18 values) otherwise. No strong correlation exists between these angles and the distortions of the polyhedra.

It is conceivable that some V^{+5} could substitute for P^{+5} in the phosphate groups, and this could be the source of some of the polyhedral distortions. The occupations for V^{+5} at the tetrahedral site were not significantly different from zero when varied in the least-squares analysis.

§ 6.3 Thermal Behaviour of $V(PO_3)_3$

In an effort to determine if the differences between the sub and super cells increase or decrease with temperature, the intensities of five strong $k=3n$ reflections and the 25 strongest $k \neq 3n$ reflections were measured at room temperature, 300°C and 500°C . These intensities were normalized to the room temperature ones. The results, shown in figure 6-3, indicate that, although the errors are large, the $k \neq 3n$ reflection intensities become substantially weaker with increasing temperature while those for $k=3n$ only weaken slightly. Error bars represent the standard deviations of the intensity ratios.

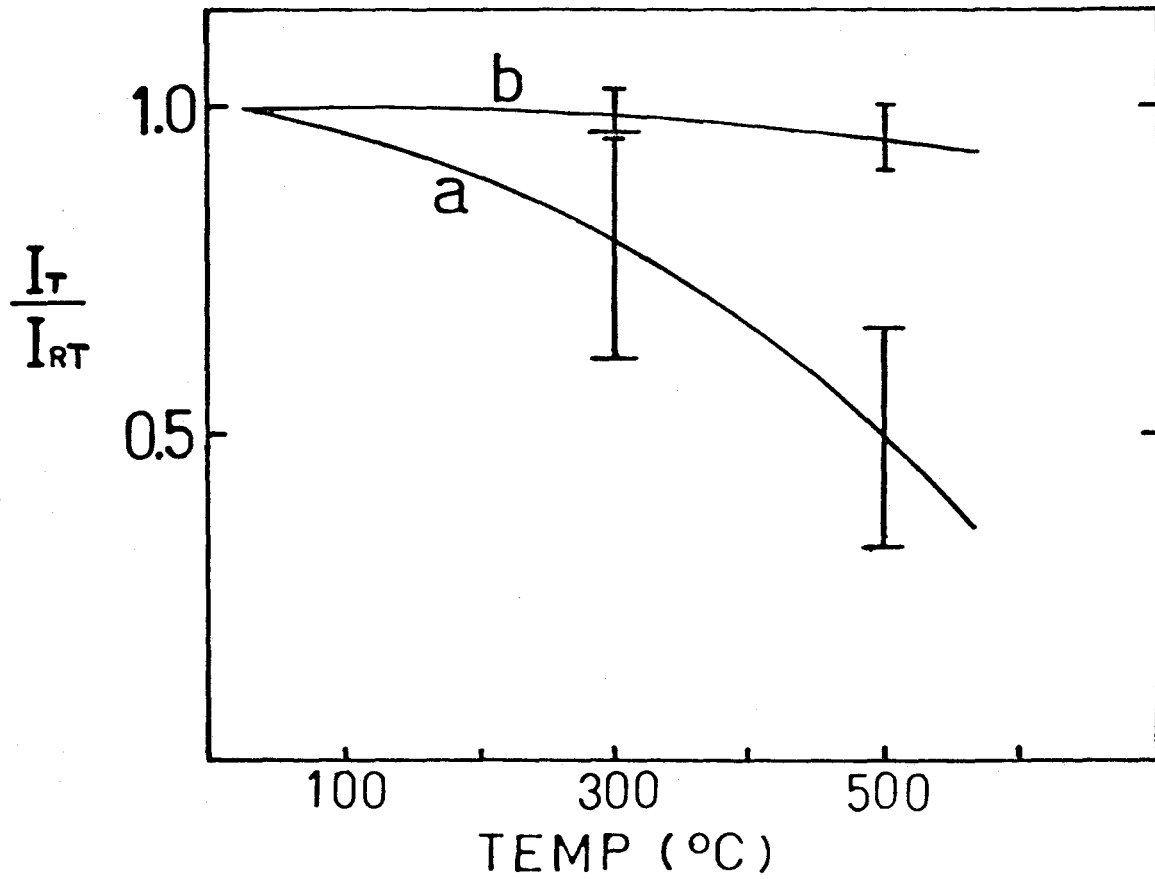


Figure 6-3. The ratio of the intensity at various temperatures compared to room temperature for (a) 25 strongest reflections with $k \neq 3n$ and (b) 5 strong reflections with $k = 3n$.

The relative decrease in intensity of the $k\neq 3n$ reflections indicates a breakdown of the superstructure. Each third of the cell will more closely resemble the other two thirds as the temperature increases. In fact, one might predict that, at about 650°C (by extrapolating the graph in figure 6-3), each third of the supercell will have the same structure, which is likely to be different from the room temperature substructure since the latter has some unlikely bond lengths and angles.

A second order phase transition to the subcell structure is predicted to occur around 650°C . Lavrov, et al.⁴⁴ found no evidence for a phase transition between room temperature and 1000°C by DTA; a result which was confirmed by us. However, second order phase transitions will not show up in DTA experiments.

$\text{Cr}(\text{PO}_3)_3$ is known to exist in six polymorphic forms^{91,92}, one of which has a powder pattern like $\text{V}(\text{PO}_3)_3$. No evidence has been found that $\text{V}(\text{PO}_3)_3$ can exist in or change to any other polymorphic form. Trimetaphosphates for the trivalent metal ions of Al, Ti, Fe and Mo^{92,93,95,96} have also been reported to be structurally the same (from powder patterns) as $\text{V}(\text{PO}_3)_3$. None of these show the extensive polymorphism of $\text{Cr}(\text{PO}_3)_3$.

The crystal structure and thermal behaviour of $\text{V}(\text{PO}_3)_3$ has been published in the Canadian Journal of Chemistry⁹⁷.

CHAPTER 7

Crystal Structure of $(VO)_2P_2O_7$

§ 7.1 Solution of the Structure

From the systematic extinctions ($h0\ell$, $\ell \neq 2n$ and $0k\ell$, $k \neq 2n$), the space group was determined to be centrosymmetric $Pbcm$, or non-centrosymmetric $Pbc2_1$. The latter is an unconventional setting of $Pca2_1$ chosen to make conversion from the centrosymmetric space group easier. Precession photographs showed reflections with $(h+\frac{1}{2}\ell) \neq 2n$ and with $k \neq 2n$ to be weak, indicating a pseudo-translational symmetry of $\frac{1}{2}\underline{a}+\frac{1}{4}\underline{c}$ and a similarity of structure at $y=\frac{1}{2}$ and $y=0$ respectively. Examination of the Patterson function corroborated these conclusions, and suggested the vanadium positions of $(0.5,0.0,0.1)$ and $(0.0,0.0,0.35)$ for the centrosymmetric space group, as well as the phosphorus positions of $(0.2,0.05,0.0)$ (or $(0.2,-0.05,0.0)$) and $(0.3,0.05,0.25)$ (or $(0.3,-0.05,0.0)$). A Patterson peak at $0.4\underline{b}$ indicated that the phosphorus atoms are contained in P_2O_7 groups with the P-P vectors parallel to \underline{b} . This placed two more phosphorus atoms at a distance of about $0.4\underline{b}$ from the previous phosphorus positions. Each of the two distinct P_2O_7 groups can be either above or below the plane at $y=0$. All of the four possible combinations of these placements were tried as models and the one with the lowest R-factor was chosen. In the centrosymmetric space group, these models refined to give P-P distances of about 3.6 \AA , and R-factors ranging from 0.52 to 0.48. Refining the same partial models in $Pbc2_1$ eliminated the problem of the long P-P distances as well as giving substantially better R-factors

(0.35 for the best model). All further refinements were carried out in the non-centrosymmetric space group. The vanadyl oxygen positions were readily identified from a difference Fourier map based on the phosphorus and vanadium positions, but three oxygen atoms for each phosphate tetrahedron were indicated on this map at positions in the $y=0$ plane which gave P-O distances that were too short. In addition, residual peaks were found at positions related by a mirror plane at $y=0$ to the phosphorus positions. Placing the phosphate oxygen atoms in their most probable positions failed to give acceptable geometries on refinement.

Bordes and Courtine⁴⁰ found antiphase boundaries prevalent in $(VO)_2P_2O_7$ electron micrographs. Such boundaries could explain the phosphorus mirror peaks and would give an average of two possible positions for each phosphate oxygen atom related by the symmetry of the antiphase boundary, if these positions are close to each other and the antiphase boundaries are plentiful. Possible antiphase boundaries will be discussed later.

In addition to the pseudo-symmetry already mentioned, the pyrophosphate, P_2O_7 , groups have two pseudo-mirror planes: one in the P-O-P plane and one perpendicular to this through the bridging oxygen. The large amount of pseudo-symmetry makes the correlation coefficients between positional coordinates large (values as high as 0.9 were found) and tends to prevent least-squares convergence to the actual atomic coordinates. In an effort to obtain the most accurate starting positions for the refinement of the oxygen coordinates, the P_2O_7 group positions were refined by rigid group least-squares refinement. The P-O bond lengths in the phosphate tetrahedra were predicted using Baur's⁹⁴ and Brown's¹⁶ models (table 7-1). Since the actual bond lengths for the phosphate groups

Table 7-1. Predicted bond lengths in the phosphate tetrahedra of $(VO)_2P_2O_7$. O_b is the oxygen atom bridging the two tetrahedra in the P_2O_7 group, O_1 is the oxygen atom which is bonded to the two vanadium atoms, and O_2 and O_3 are the oxygen atoms bonded to one vanadium atom each.

Bond	Predicted value based on Brown's ¹⁶ model (Å)	Predicted value based on Baur's ⁹⁴ model (Å)	Average predicted value (Å)
P- O_b	1.62	1.595	1.61
P-01	1.55	1.60	1.575
P-02	1.50	1.53	1.515
P-03	1.50	1.53	1.515

considered in the previous chapters were mid-way between the predicted values based on Brown's and Baur's models, the averages of these predicted values for the $(VO)_2P_2O_7$ structure were the ones used in the rigid group refinement. In addition, it was assumed that the four oxygen atoms were at the corners of a regular tetrahedron with the phosphorus atom placed to give the calculated bond lengths. The position and orientation of each of the tetrahedra were refined until shifts per error ceased to be significant. The R-factor was 0.26 at this point. The resulting coordinates, when used as initial parameters in the least-squares refinement of the individual atomic positions, still failed to converge to values which yielded satisfactory geometries.

Two models for antiphase boundaries were then tried as follows:
Model I - For each pyrophosphate group, a second group, related by a mirror plane at $y=0$ to the first, was added to the model, and the occupation of the groups was refined so that the total occupancy remained 1.0. Convergence was obtained at an occupancy of 0.5 for each group. The positional and isotropic thermal coordinates were then refined.
Model II - For each P_2O_7 group, a second group related by a mirror plane at $x=0$ to the first, was added to the model, and the occupation of the groups and the coordinates were then refined as for model I.
Both Model I and Model II gave the same structure (within the standard errors), but the estimated standard deviations of the coordinates were very large. Positional and thermal coordinates are given in table 7-2 and bond geometries in table 7-3. The standard deviations of the intensities were used as weights since the models were not accurate enough to determine a weighting scheme based on Cruickshank coefficients. The

Table 7-2. Positional and Isotropic Thermal coordinates for $(VO)_2P_2O_7$
 Estimated standard deviations are in parentheses.

Atom	x	y	z	U(A ²)
V1	0.5150(9)	0.035(1)	0.963	0.013(1)
V2	0.4991(8)	-0.044(1)	-0.0938(8)	0.006(1)
V3	0.0043(9)	0.042(1)	0.3457(8)	0.009(1)
V4	-0.0006(8)	0.0501(8)	-0.3437(7)	0.005(1)
P1	0.205(2)	0.030(3)	0.002(2)	0.005(3)
P2	0.203(2)	0.422(3)	0.003(2)	0.007(3)
P3	0.287(2)	-0.031(3)	0.262(2)	0.004(3)
P4	0.295(2)	0.576(3)	0.254(2)	0.006(3)
O1	0.375(6)	0.008(10)	-0.005(5)	0.008(10)
O2	0.150(7)	-0.060(9)	-0.078(4)	0.011(10)
O3	0.151(7)	-0.068(9)	0.079(5)	0.014(10)
O4	0.166(6)	0.230(8)	-0.006(4)	0.008(11)
O5	0.350(8)	0.461(9)	0.014(5)	0.012(11)
O6	0.139(6)	0.484(10)	0.078(4)	0.007(11)
O7	0.145(7)	0.499(10)	-0.072(4)	0.006(12)
O8	0.141(6)	0.004(10)	0.253(4)	0.004(11)
O9	0.356(7)	-0.002(10)	0.177(4)	0.004(11)
O10	0.360(7)	0.078(9)	0.322(4)	0.010(10)
O11	0.290(6)	-0.221(8)	0.291(4)	0.009(10)
O12	0.129(7)	0.544(8)	0.252(5)	0.006(10)

Table 7-2 cont.

Atom	x	y	z	$U(\text{Å}^2)$
013	0.366(7)	0.495(10)	0.323(4)	0.006(11)
014	0.361(8)	0.589(10)	0.185(5)	0.017(12)
0V1	0.517(4)	0.248(7)	0.093(3)	0.024(8)
0V2	0.536(3)	-0.228(4)	-0.090(2)	0.005(7)
0V3	0.009(6)	0.263(7)	0.341(3)	0.020(9)
0V4	0.021(3)	0.250(5)	-0.339(2)	0.005(7)

Table 7-3. Bond Geometries for $(VO)_2P_2O_7$. Estimated standard deviations are indicated in parentheses, and all values are in angstroms, or degrees.

Bond Lengths

Bond	Length	Bond	Length	Bond	Length	Bond	Length
V1-01	2.15(8)	V2-01	1.94(7)	V3-08	2.04(7)	V4-08	2.14(7)
V1-05	1.96(8)	V2-05	2.30(8)	V3-012	2.02(7)	V4-012	2.14(7)
V1-09	2.05(7)	V2-010	1.96(7)	V3-02	1.95(7)	V4-03	1.93(8)
V1-014	1.94(8)	V2-013	1.92(7)	V3-07	1.94(7)	V4-06	1.88(7)
V1-0V1	1.64(5)	V2-0V2	1.47(5)	V3-0V3	1.71(6)	V4-0V4	1.56(4)
V1-0V1	2.24(5)	V2-0V2	2.47(5)	V3-0V3	2.16(6)	V4-0V4	2.33(4)
P1-01	1.64(7)	P2-05	1.46(8)	P3-08	1.43(7)	P4-012	1.61(7)
P1-02	1.59(8)	P2-06	1.47(8)	P3-09	1.57(7)	P4-013	1.47(8)
P1-03	1.56(8)	P2-07	1.48(8)	P3-010	1.48(7)	P4-014	1.34(8)
P1-04	1.60(7)	P2-04	1.53(7)	P3-011	1.58(7)	P4-011	1.56(7)
P1-P2	3.02(3)			P3-P4	3.05(3)		

Bond Angles

Bonds	Angles	Bonds	Angles
0V1-V1-01	95(3)	0V2-V2-01	108(3)
0V1-V1-05	105(3)	0V2-V2-05	81(3)
0V1-V1-09	100(3)	0V2-V2-010	75(3)
0V1-V1-014	79(3)	0V2-V2-013	113(3)
01-V1-05	81(3)	01-V2-05	78(3)
01-V1-09	92(3)	01-V2-010	174(3)
01-V1-014	173(3)	01-V2-013	96(3)
05-V1-09	154(3)	05-V2-010	97(3)

Table 7-3 cont.

Bonds	Angles	Bonds	Angles
05-V1-014	101(3)	05-V2-013	167(3)
09-V1-014	89(3)	010-V2-013	89(3)
0V3-V3-08	95(3)	0V4-V4-08	104(3)
0V3-V3-012	89(3)	0V4-V4-012	103(3)
0V3-V3-02	89(3)	0V4-V4-03	94(3)
0V3-V3-07	100(3)	0V4-V4-06	95(3)
08-V3-012	80(3)	08-V4-012	75(3)
08-V3-02	170(3)	08-V4-03	93(3)
08-V3-07	93(3)	08-V4-06	160(3)
012-V3-02	91(3)	012-V4-03	161(3)
012-V3-07	170(3)	012-V4-06	93(3)
02-V3-07	95(3)	03-V4-06	95(3)
01-P1-02	103(4)	05-P2-06	103(4)
01-P1-03	109(4)	05-P2-07	113(4)
01-P1-04	109(4)	05-P2-04	116(4)
02-P1-03	110(4)	06-P2-07	115(4)
02-P1-04	106(4)	06-P2-04	108(4)
03-P1-04	118(4)	07-P2-04	103(5)
08-P3-09	107(4)	012-P4-013	115(4)
08-P3-010	115(5)	012-P4-014	118(5)
08-P3-011	103(4)	012-P4-011	98(4)
09-P3-010	109(4)	013-P4-014	119(5)
09-P3-011	108(4)	013-P4-011	102(4)
010-P3-011	114(4)	014-P4-011	101(4)

final R and R_w were both 0.18.

§ 7.2 Description of the Structure (figure 7-1)

$(VO)_2P_2O_7$ contains chains parallel to \underline{b} consisting of two edge-sharing VO_6 octahedra, corner-sharing axial oxygens to two more octahedra above and below. The axial oxygens form the typical vanadyl bond to one vanadium and long bond to the other vanadium. The two edge-sharing octahedra have vanadyl bonds which point in opposite directions along the \underline{b} axis. Pyrophosphate groups are found parallel to these chains with each half of these groups sharing an edge-shared oxygen of one double chain and an unshared equatorial oxygen of each of two other double chains.

Both pyrophosphate groups are in eclipsed configuration with equal P-O-P angles of 150° . These angles are larger than the normal bridging angle range of $127-138^\circ$ for eclipsed configurations⁹⁸. This could be due to the lack of any additional long range bonding to the bridging oxygen atom which is often found for the eclipsed configuration, or due to the O-O spacing in the double VO_6 chains. The P_2O_7 groups are very symmetric, containing two pseudo-mirror planes, one perpendicular to \underline{c} through the two phosphorus atoms, and one perpendicular to \underline{b} through the bridging oxygen.

The standard deviations for the bond lengths and angles are too large to allow meaningful comparisons. However, the average P-O bonds for the bridging, two-coordinate and three-coordinate oxygens respectively are 1.57(4), 1.50(3) and 1.54(4) they equal within the errors the predicted values in table 7-1. The average equatorial V-O bond lengths for the two and three-coordinated oxygens are 1.95(3) and 2.09(3)

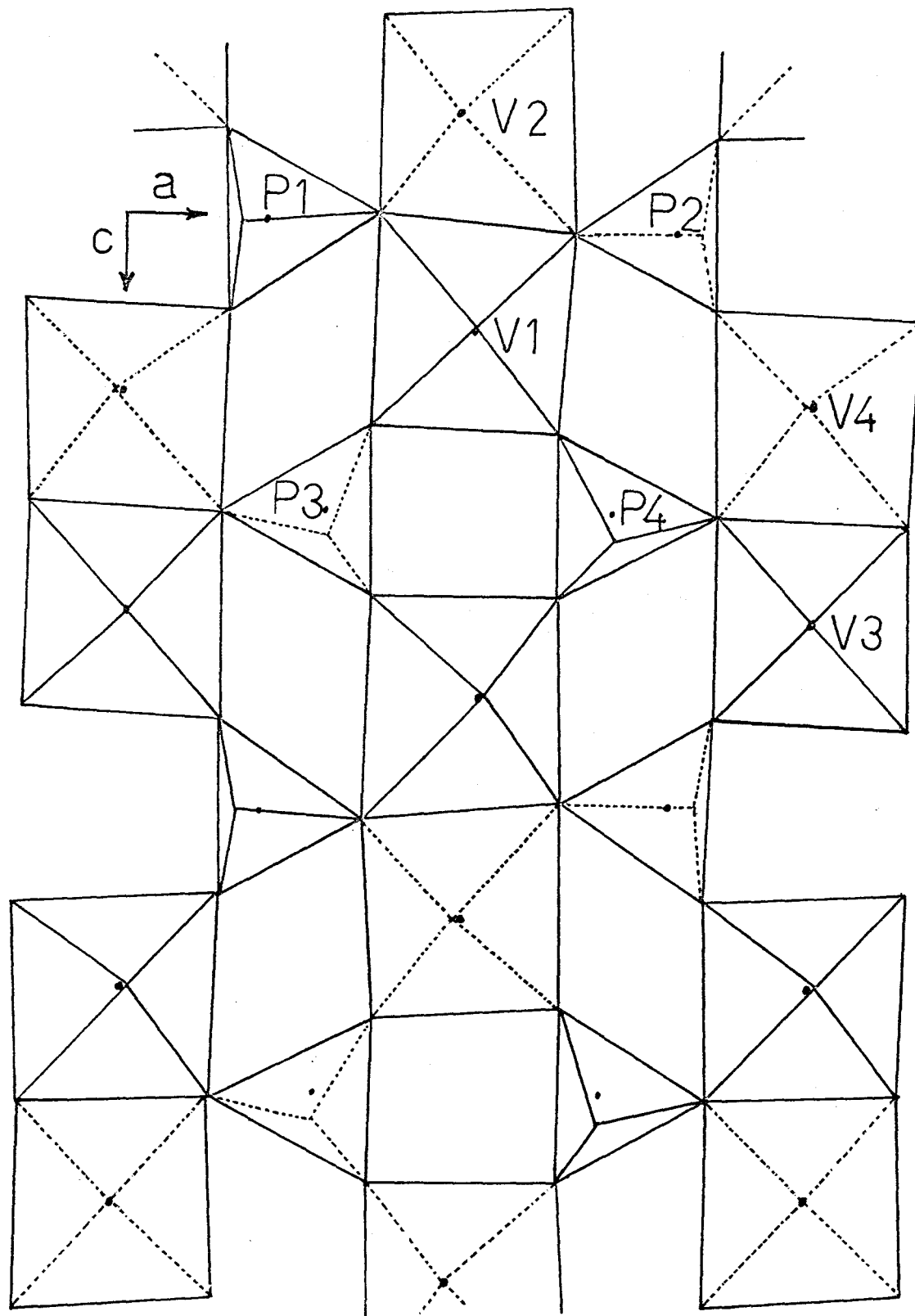


Figure 7-1. The crystal structure of $(VO)_2P_2O_7$ as projected down the \underline{b} -axis. Only half the structure is shown. The remaining part of the cell may be generated by a \underline{b} -glide.

They compare favourably with the predicted values based on Brown's¹⁶ (1.95 and 2.11) and Baur's⁹⁴ model (1.94 and 2.08). The average vanadyl bond length of 1.60(3) is also in the range of those found for $V^{+4}O_6$ octahedra. The O-V-O angles between the vanadyl oxygen and the equatorial oxygen atoms should all be greater than 90° since the vanadyl bond is by far the strongest bond in the octahedron. The fact that some of these bond angles are substantially smaller than 90° probably reflects inaccuracies in the structure determination.

§ 7-3 Validity of the Structure

Since the R-factors and standard deviations of the positional coordinates are very large, some of these coordinates may be wrong. The general topology of the crystal structure contains no undesirable features, and, as will be seen in chapter 9, accounts for the conversion of VP_2O_7 to $(VO)_2P_2O_7$. In addition, Bordes and Courtine⁴⁰ have confirmed the presence of P_2O_7 groups. Thus, it is unlikely that the topology is in error. It is possible that one of the P_2O_7 groups is actually reflected in a mirror plane perpendicular to \underline{b} , but such a reversal would likely introduce more angles less than 90° in the VO_6 octahedra. Antiphase boundaries possibly exist perpendicular to \underline{b} , but they introduce the necessity of three joined PO_4 tetrahedra at the boundaries. Antiphase boundaries perpendicular to \underline{a} are more likely since they do not require such a feature.

CHAPTER 8

Crystal Structure and Disorder for VAsO_5

§ 8.1 Solution of the Structure

The unit cell for VAsO_5 has $a = 6.35(3)\text{\AA}$, $b = 6.32(3)\text{\AA}$, $c = 8.256(5)\text{\AA}$, $\gamma \approx 90(1)^\circ$, $Z = 4$, space group $P2_1/n$ (c-axis unique). The unconventional setting of the space group was chosen to enable direct comparison with $\alpha\text{-VPO}_5$.

The diffraction pattern of VAsO_5 shows streaks through the Bragg spots parallel to \underline{c}^* , and, in addition, shows some diffraction spots slightly displaced along \underline{c}^* from the Bragg positions (figure 8-1). These features introduce errors in the measured intensities. Thus the structure refinement was not expected to give a low R-factor although the intensities were accurate enough to provide the basic structure. Intensities for displaced reflections were assigned to the nearest Bragg point in the structure determination.

The positions of the arsenic and vanadium atoms were readily determined from the Patterson function. A difference map, based on the least squares refined positions of these two atoms, showed peaks with maxima up to $\frac{1}{2}\text{\AA}$ in diameter for the oxygen positions. More exact positions for the oxygen atoms within the volume from the difference map were calculated assuming approximate V-O(As) and As-O bond lengths of 1.90 and 1.68 \AA respectively. The vanadyl oxygen bond was assumed to be 1.6 \AA . Atomic positions so derived and isotropic temperature factors refined readily to an R-factor of 0.23. Anisotropic temperature coordinates refinement was

attempted but was unsuccessful.

A difference map at this point showed some residual peaks. Since the diffraction pattern indicated one dimensional disorder and the structure is layered, it was assumed that these peaks were due to stacking faults. A model for such faults will be described in section 8-4. Introduction of these faults into the least squares refinement, by placing atoms in positions defined by the displacement vectors of the faults relative to their "normal" positions, was attempted. The occupation number of these atoms was refined in such a way that the total occupation of any atom in the cell remained at 1. The refinement indicated that each of two stacking faults occurred 10(1) % of the time. The R-factor at this point was $R = 0.192$, and $R_w = 0.198$. Unit weights were used since it was felt that the systematic errors due to the stacking faults were much larger than the random errors and thus nothing would be gained by any other weighting scheme.

Final co-ordinates are given in table 8-1.

§ 8.2 The Basic Structure of $VAsO_5$

Crystalline $VAsO_5$ contains layers like those of α - VPO_5 containing VO_6 octahedra sharing equatorial oxygens with four different AsO_4 tetrahedra, all of which share corners with four VO_6 groups (figure 8-2). The structure differs substantially from that of α - VPO_5 in the stacking of such layers (figure 8-3). In α - VPO_5 , the layers are only displaced from each other along the c -axis, being connected at the vanadyl oxygens. In $VAsO_5$, the layers are displaced horizontally as well as along c , thereby forming double layers in which two VO_6 groups share an edge in such a way that an equatorial and a long-bonded axial oxygen of one group form a

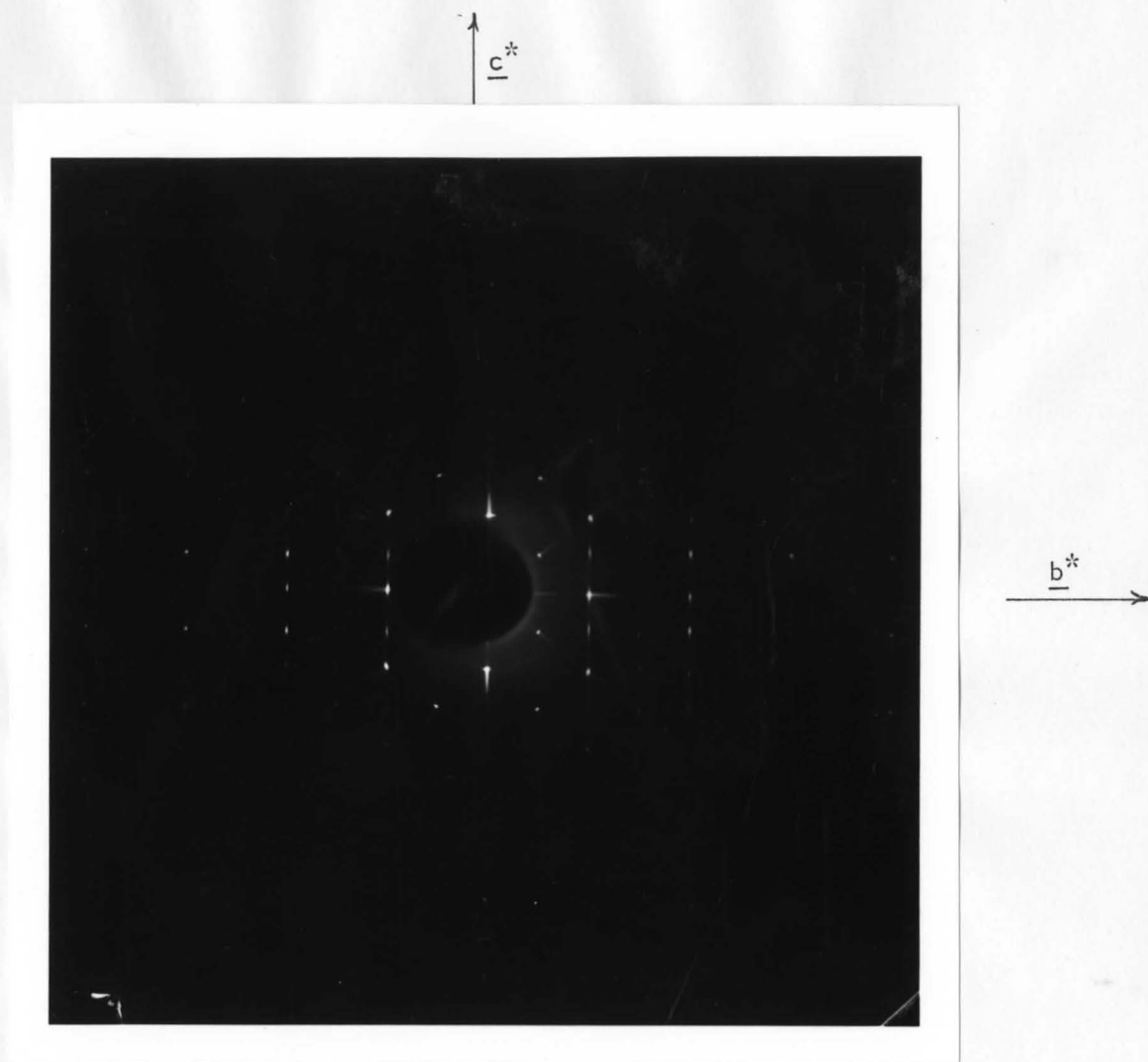


Figure 8-1. The $0kl$ diffraction pattern of $VAsO_5$, showing the diffuse streaks due to stacking faults along the c^* direction and displacement of some spots from the Bragg points (e.g. the 021 and $02\bar{1}$ spots)

Table 8-1. Positional and Thermal coordinates for VAsO_5 .
Estimated standard deviations are indicated in parentheses.

Atom	x	y	z	$U(\text{\AA}^2)$
As	0.1582(3)	0.4619(3)	0.2480(3)	0.0028(5)
V	0.1575(6)	0.9646(6)	0.3288(4)	0.0030(7)
O(1)	0.218(3)	0.259(3)	0.364(2)	0.004(3)
O(2)	0.109(3)	0.671(3)	0.369(2)	0.010(3)
O(3)	0.863(3)	0.008(3)	0.378(2)	0.002(3)
O(4)	0.446(3)	0.899(3)	0.364(2)	0.004(3)
O(V)	0.141(3)	0.949(3)	0.137(3)	0.014(4)

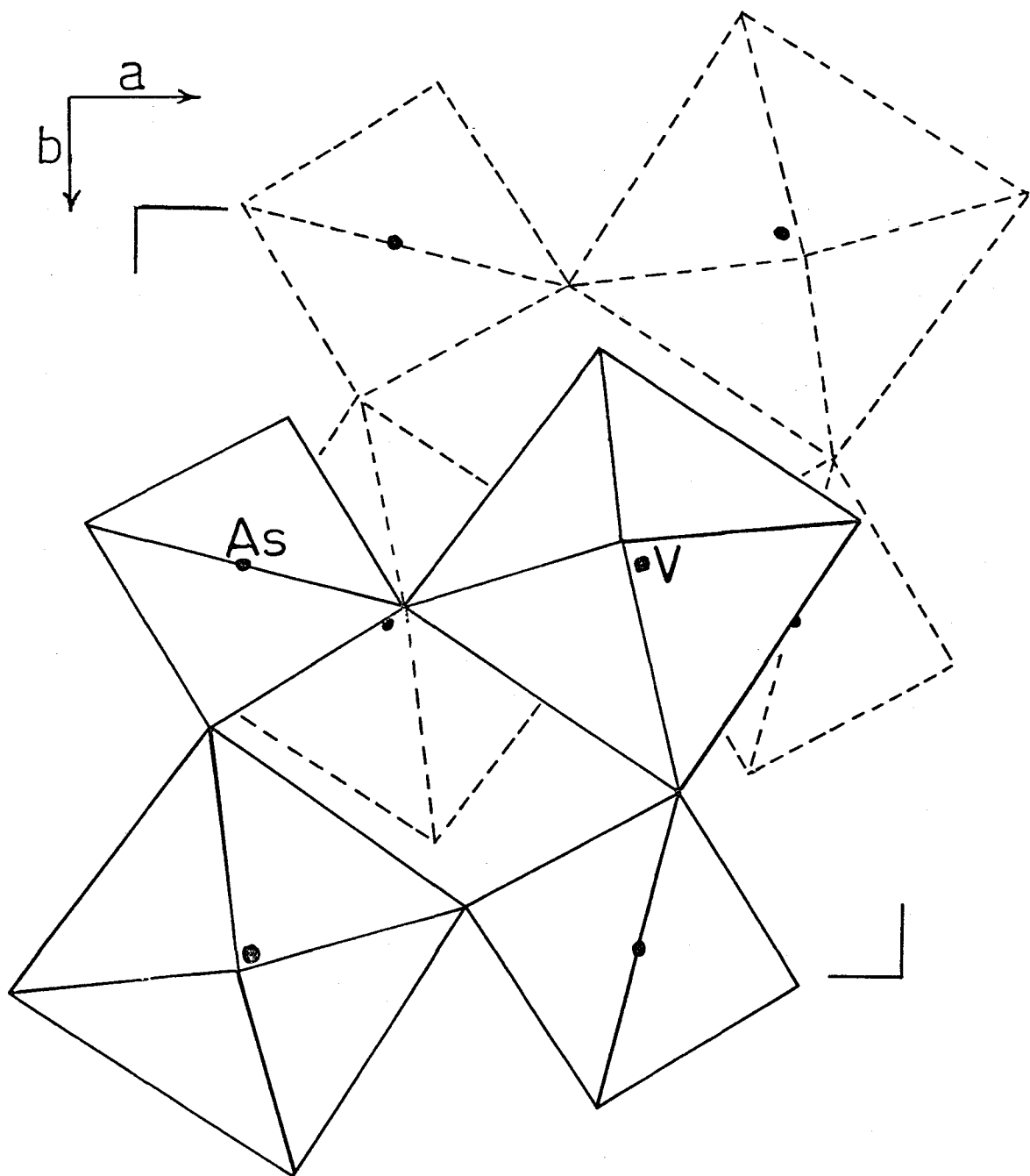


Figure 8-2. The structure of $VAsO_5$ as projected along the c axis, The dotted polyhedra are related to the others by a centre of inversion at the origin.

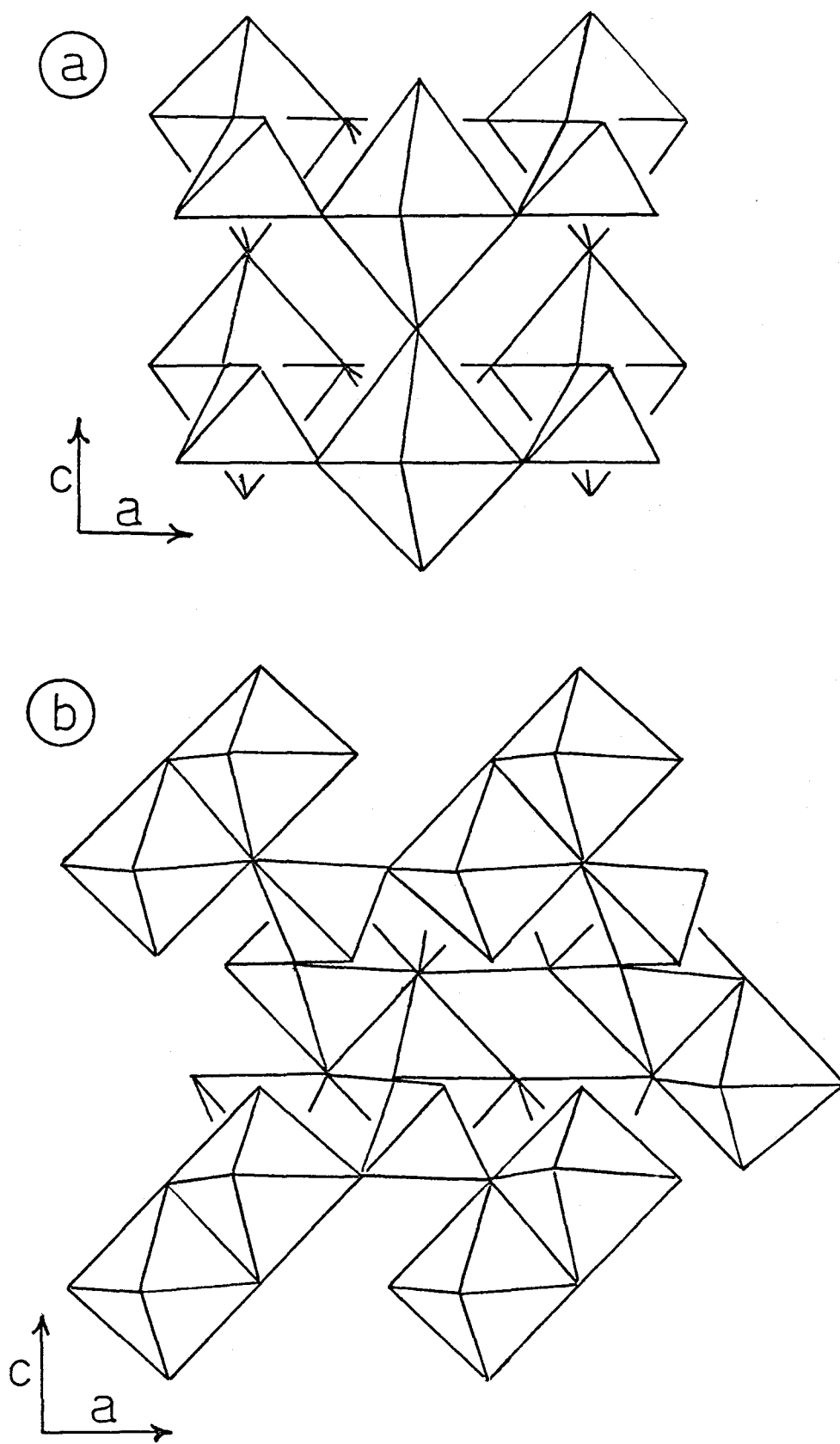


Figure 8-3. The structures of $\alpha\text{-VPO}_5$ (a) and VAsO_5 (b) as projected on the ac plane, showing the difference in the stacking of the layers. The VAsO_5 layers can be produced from the $\alpha\text{-VPO}_5$ layers by a translation of a layer perpendicular to and slightly down along \underline{c} .

long-bonded axial and equatorial oxygen respectively of the other group. The vanadyl bonds of these two edge-sharing groups point in opposite directions, and the vanadyl oxygens are uni-coordinated. Within one layer, the VO_6 groups alternately share edges with groups in the layer above and below. The formation of these edge-shared groups accounts for the $VAsO_5$ c -axis being slightly less than twice the α - VPO_5 c -axis (8.256 Å c.f. 8.868 Å).

As can be seen from table 8-2, the bond distances for the equatorial V-O bonds are slightly larger than the corresponding ones for α - VPO_5 . This is compensated for by a shorter "long" V-O bond. O-V-O and O-As-O angles do not differ greatly from the corresponding ones in α - VPO_5 , the greatest difference of 6° existing for axial-equatorial angles in VO_6 . These differences are undoubtedly due to the different stacking of the layers. It is surprising that the As-O(3) bond is no longer than the other As-O bonds as would be predicted by bond valence calculations. However, the total As valence using Brown's¹⁶ bond-valence parameters is 4.94 and that for Vanadium is 4.99; both in good agreement with the expected value.

§ 8.3 Theory of Diffraction from Stacking Faults

Although several authors have treated the topic of diffraction from stacking faults^{69,70}, the treatment given by Cowley⁷¹ lends itself most readily to computations. It will be briefly reviewed here for the case of two possible stacking faults with equal probability, which, as will be seen in section 8-4, applies to $VAsO_5$.

For convenience, and to prevent confusion later on, a layer of unit cells perpendicular to c will be called a sheet, to differentiate it

Table 8-2. Bond lengths and angles in $VAsO_5$ with standard deviations in parentheses. The corresponding bond lengths for α - $VP0_5$ have been listed for comparison.

Bond	Distance (Å)	corresponding α - $VP0_5$ distance	Bond	Distance (Å)	corresponding α - $VP0_5$ distance
V-0(1)	1.874(17)	1.858(7)	As-0(1)	1.690(16)	1.541(8)
V-0(2)	1.905(19)	1.858(7)	As-0(2)	1.690(19)	1.541(8)
V-0(3)	1.929(16)	1.858(7)	As-0(3)	1.685(15)	1.541(8)
V-0(4)	1.896(16)	1.858(7)	As-0(4)	1.680(17)	1.541(8)
V-0(V)	1.592(21)	1.580(11)			
V-0(3)x*	2.431(16)	2.853(11)			

*0(3)x refers to 0(3) when it forms a long V-0 bond

Bonds	Angle(°)	corresponding α - $VP0_5$ angle	Bonds	Angle(°)	corresponding α - $VP0_5$ angle
0(1)-V-0(2)	160.7(8)	156.7(4)	0(1)-As-0(2)	109.9(9)	109.1(4)
0(1)-V-0(3)	91.6(7)	87.7(4)	0(1)-As-0(3)	108.4(8)	109.7(4)
0(1)-V-0(4)	89.4(7)	87.7(4)	0(1)-As-0(4)	107.9(8)	109.7(4)
0(2)-V-0(3)	87.1(7)	87.7(4)	0(2)-As-0(3)	111.5(8)	109.7(4)
0(2)-V-0(4)	84.9(8)	87.7(4)	0(2)-As-0(4)	111.7(9)	109.7(4)
0(3)-V-0(4)	158.5(7)	156.7(4)	0(3)-As-0(4)	108.2(8)	109.7(4)
0(3)x-V-0(1)	77.6(6)	78.4(2)	0(V)-V-0(1)	103.3(9)	101.6(2)
0(3)x-V-0(2)	83.5(7)	78.4(2)	0(V)-V-0(2)	95.9(9)	101.6(2)
0(3)x-V-0(3)	74.4(6)	78.4(2)	0(V)-V-0(3)	99.0(9)	101.6(2)
0(3)x-V-0(4)	84.9(6)	78.4(2)	0(V)-V-0(4)	101.7(9)	101.6(2)
0(3)x-V-0(V)	173.3(9)	180(exact)			

from the structural layer as described in section 8-2. Thus, for VAsO_5 , two layers make up a sheet, and the sheet is the repeating unit in the \underline{c} direction.

When no faults occur, sheets stack along \underline{c} with corresponding points in adjacent sheets related by the vector \underline{c} . If a fault of type 1 occurs, these points in the layer immediately before and immediately after the fault will be related by $\underline{c} + \underline{S}_1$, or by $\underline{c} + \underline{S}_2$ for a fault of type 2, where \underline{S}_1 and \underline{S}_2 are the displacement vectors of the faults. The electron density distribution of the two kinds of faults will be denoted by Δ_1 and Δ_2 and will have Fourier transforms denoted by G_1 and G_2 . The electron density of the sheet and its Fourier transform will be ρ and F respectively. When a fault of type 1 or 2 occurs, the crystal will have the environment shown in figure 8-4. If the probability of either type of fault occurring is α (i.e. both faults have equal probability, α), then the probability of no fault occurring after any layer is $1 - 2\alpha$ ($=A$).

Following the general calculations by Cowley⁷¹ for this specific case, the zeroth component of the generalized Patterson function involves only the intra-sheet vectors and is,

$$P_0(\underline{u}) = N \{ A\rho(\underline{u}) * \rho(-\underline{u}) + \alpha(\rho(\underline{u}) + \Delta_1(\underline{u})) * (\rho(-\underline{u}) + \Delta_1(-\underline{u})) + \alpha(\rho(\underline{u}) + \Delta_2(\underline{u})) * (\rho(-\underline{u}) + \Delta_2(-\underline{u})) \}, \quad (8-1)$$

where N is the number of sheets and \underline{u} is a real space vector.

The Fourier transform of this expression gives the zeroth intensity component:

$$I_0 = N \{ A|F|^2 + \alpha|F + G_1|^2 + \alpha|F + G_2|^2 \}. \quad (8-2)$$

The first component of the Patterson function involves vectors between nearest neighbour sheets. Since the first sheet can be faulted by \underline{S}_1 or \underline{S}_2 or unfaulted, and its neighbour can also be faulted by \underline{S}_1 or \underline{S}_2 or unfaulted, the possible

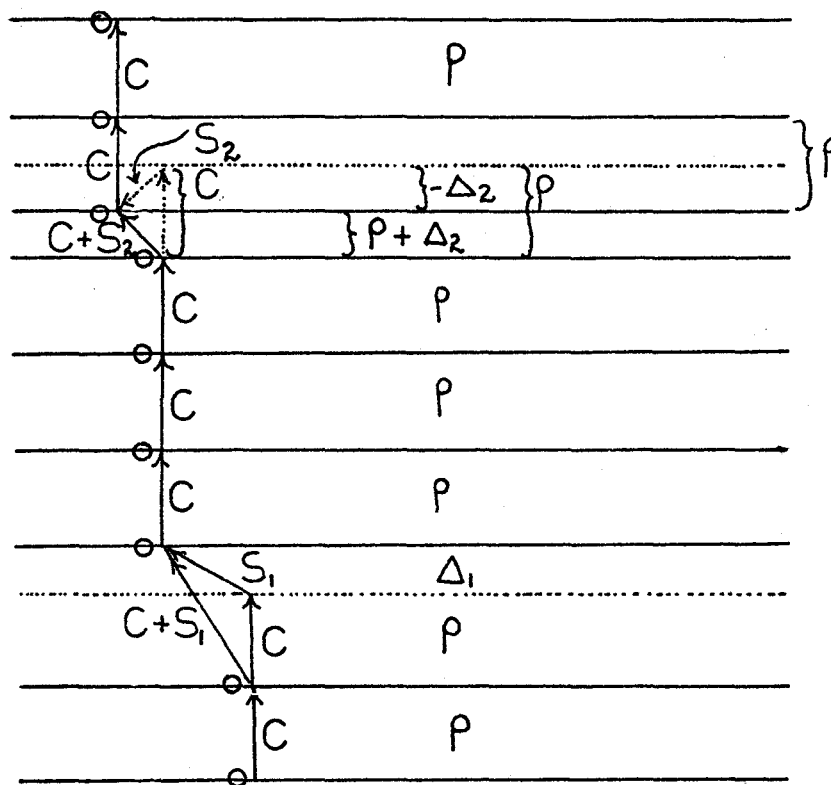


Figure 8-4. The arrangement of layers with two different kinds of stacking faults. The stacking fault with displacement vector S_1 adds electron density to the normal sheet, and the one with displacement vector S_2 subtracts electron density from the normal sheet.

combinations of two sheets is unfaulted-unfaulted, unfaulted-faulted(1), unfaulted-faulted(2), faulted(1)-unfaulted, faulted(1)-faulted(1), faulted(1)-faulted(2), faulted(2)-unfaulted, faulted(2)-faulted(1), and faulted(2)-faulted(2), where the number in brackets indicates the kind of fault. If the probability of finding a faulted layer is α and an unfaulted one is A , then the probability of finding a faulted one followed by a faulted one is α^2 , two unfaulted ones is A^2 , and a faulted one with an unfaulted one is $A\alpha$. The first component of the Patterson function thus becomes

$$\begin{aligned}
 P_1(\underline{u}) = N \{ & \delta(\underline{u}-\underline{c})A^2\rho(\underline{u}) * \rho(-\underline{u}) + \delta(\underline{u}-\underline{c})A\alpha\rho(\underline{u}) * (\rho(-\underline{u}) + \Delta_1(-\underline{u})) \\
 & + \delta(\underline{u}-\underline{c})A\alpha\rho(\underline{u}) * (\rho(-\underline{u}) + \Delta_2(-\underline{u})) + \delta(\underline{u}-(\underline{c}+\underline{S}_1))\alpha A(\rho(\underline{u}) + \Delta_1(\underline{u})) * \rho(-\underline{u}) \\
 & + \delta(\underline{u}-(\underline{c}+\underline{S}_1))\alpha^2(\rho(\underline{u}) + \Delta_1(\underline{u})) * (\rho(-\underline{u}) + \Delta_1(-\underline{u})) \\
 & + \delta(\underline{u}-(\underline{c}+\underline{S}_1))\alpha^2(\rho(\underline{u}) + \Delta_1(\underline{u})) * (\rho(-\underline{u}) + \Delta_2(-\underline{u})) \\
 & + \delta(\underline{u}-(\underline{c}+\underline{S}_2))\alpha A(\rho(\underline{u}) + \Delta_2(\underline{u})) * (\rho(-\underline{u})) \\
 & + \delta(\underline{u}-(\underline{c}+\underline{S}_2))\alpha^2(\rho(\underline{u}) + \Delta_2(\underline{u})) * (\rho(-\underline{u}) + \Delta_1(-\underline{u})) \\
 & + \delta(\underline{u}-(\underline{c}+\underline{S}_2))\alpha^2(\rho(\underline{u}) + \Delta_2(\underline{u})) * (\rho(-\underline{u}) + \Delta_2(-\underline{u})) \} \quad (8-3)
 \end{aligned}$$

which Fourier transforms to give

$$\begin{aligned}
 I_1 = N \{ & \exp(2\pi i \underline{h} \cdot \underline{c}) \{ A^2 |F|^2 + \alpha A F^* (F+G_1) + \alpha A F^* (F+G_2) \} \\
 & + \exp(2\pi i \underline{h} \cdot (\underline{c}+\underline{S}_1)) \{ \alpha A (F+G_1)^* F + \alpha^2 |F+G_1|^2 + \alpha^2 (F+G_1)^* (F+G_2) \} \\
 & + \exp(2\pi i \underline{h} \cdot (\underline{c}+\underline{S}_2)) \{ \alpha A (F+G_2)^* F + \alpha^2 (F+G_2)^* (F+G_1) + \alpha^2 |F+G_2|^2 \} \}, \quad (8-4)
 \end{aligned}$$

where \underline{h} is a reciprocal space vector which need not be integral.

In general, the interaction of sheets, n sheets apart, will give rise to the n^{th} Patterson component which Fourier transforms to give the n^{th} intensity component. When considering sheets, n sheets apart, there are a total of $n+1$ sheets, and the probability of various faulted and unfaulted arrangements must be calculated. Since the interaction is only

between the first and last sheet, there are several arrangements which will give rise to the same term in the intensity. For instance, the arrangement UF_1UU and UUF_1U where U stands for unfaulted and F_1 stands for a faulted sheet of type 1 will give rise to identical terms in the intensity expression. The different kinds of terms have been summarized in table 8-3. The probability part contains not only the probability of finding the particular type of layers but also takes into account the number of arrangements possible giving the same term as described above. The full n^{th} component of the intensity can thus be found by multiplying the exponential, probability and structure factor parts for each term and then summing the terms.

The total intensity is the sum of all the intensities for both positive and negative n . In practice n runs from $-\infty$ to $+\infty$ since crystals are usually large enough to neglect termination effects of the series. The $-n^{\text{th}}$ component of the intensity is mainly the complex conjugate of the n^{th} component, and can thus readily be evaluated.

Upon summing all the components of intensity, factoring the sums and performing subsequent simplifications, the final intensity becomes

$$I = \sum_{n=-\infty}^{\infty} I_n$$

$$= T/D + X \quad (8-5)$$

where

$$D = 1 + A^2 + 2\alpha^2 - 2A\cos(2\pi h \cdot \underline{c}) - 2\alpha\cos(2\pi h \cdot (\underline{c} + \underline{S}_1))$$

$$- 2\alpha\cos(2\pi h \cdot (\underline{c} + \underline{S}_2)) + 2\alpha A\cos(2\pi h \cdot \underline{S}_1) + 2\alpha A\cos(2\pi h \cdot \underline{S}_2)$$

$$+ 2\alpha^2\cos(2\pi h \cdot (\underline{S}_1 - \underline{S}_2)) \quad (8-6)$$

Table 8-3. Terms in the generalized expression for the n^{th} intensity component when considering two kinds of stacking faults.

exponential	probability	structure factor	explanation
$\exp(2\pi i h \cdot n c)$	A^n	$ F ^2$	no faults in any sheets
"	αA^{n-1}	$F^*(F+G_1)$	faults of type 1 in the last (i.e. $(n+1)^{\text{th}}$) sheet
"	αA^{n-1}	$F^*(F+G_2)$	faults of type 2 in the last sheet
$\exp(2\pi i h \cdot (n c + x S_1))$ $x < n$	$\frac{(n-1)! \alpha^x A^{n-x}}{(n-x-1)! x!}$	$ F ^2$	x faults of type 1 in the inner (i.e. 2^{nd} to n^{th}) sheets
"	$\frac{(n-1)! \alpha^{x+1} A^{n-x-1}}{(n-x-1)! x!}$	$F^*(F+G_1)$	x faults of type 1 in the inner sheets and one in the last sheet
"	$\frac{(n-1)! \alpha^{x+1} A^{n-x-1}}{(n-x-1)! x!}$	$F^*(F+G_2)$	x faults of type 1 in the inner sheets and one of type 2 in the last sheet
"	$\frac{(n-1)! \alpha^x A^{n-x}}{(n-x)! (x-1)!}$	$(F+G_1)^* F$	$(x-1)$ faults of type 1 in the inner sheets and one in the first sheet
"	$\frac{(n-x)! \alpha^{x+1} A^{n-x-1}}{(n-x)! (x-1)!}$	$ F+G_1 ^2$	$(x-1)$ faults of type 1 in the inner sheets and one each in the first and last sheets
"	$\frac{(n-x)! \alpha^{x+1} A^{n-x+1}}{(n-x)! (x-1)!}$	$(F+G_1)^* (F+G_2)$	$(x-1)$ faults of type 1 in the inner sheets, one of type 1 in the first sheet and one of type 2 in the last sheet

Table 8-3 cont.

exponential	probability	structure factor	explanation
$\exp(2\pi i h \cdot (n(\underline{c} + \underline{S}_1)))$	$\alpha^n A$	$(F+G_1)^* F$	a fault of type 1 in each layer except the last one
"	α^{n+1}	$ F+G_1 ^2$	a fault of type 1 in all layers
"	α^{n+1}	$(F+G_1)^* (F+G_2)$	a fault of type 2 in the last layer and of type 1 in all the others
$\exp(2\pi i h \cdot (n\underline{c} + x\underline{S}_1 + y\underline{S}_2))$ $(x+y) < n$	$\frac{(n-1)! \alpha^{x+y} A^{n-x-y}}{(n-x-y-1)! x! y!}$	$ F ^2$	x faults of type 1 and y faults of type 2 in the inner layers
"	$\frac{(n-1)! \alpha^{x+y+1} A^{n-x-y-1}}{(n-x-y-1)! x! y!}$	$F^* (F+G_1)$	a fault of type 1 in the last layer and x of type 1 y of type 2 in the inner layers
"	$\frac{(n-1)! \alpha^{x+y+1} A^{n-x-y-1}}{(n-x-y-1)! x! y!}$	$F^* (F+G_2)$	a fault of type 2 in the last layer and x of type 1 y of type 2 in the inner layers
"	$\frac{(n-1)! \alpha^{x+y} A^{n-x-y}}{(n-x-y)! (x-1)! y!}$	$(F+G_1)^* F$	a fault of type 1 in the first layer and x-1 of type 1 y of type 2 in the inner layers
"	$\frac{(n-1)! \alpha^{x+y+1} A^{n-x-y-1}}{(n-x-y)! (x-1)! y!}$	$ F+G_1 ^2$	faults of type 1 in the first and last layers and x-1 of type 1 y of type 2 in the inner layers

Table 8-3 cont.

exponential	probability	structure factor	explanation
$\exp(2\pi i h \cdot (n\underline{c} + x\underline{S}_1 + y\underline{S}_2))$ $(x+y) < n$	$\frac{(n-1)! \alpha^{x+y+1} A^{n-x-y-1}}{(n-x-y)! (x-1)! y!}$	$(F+G_1)^* (F+G_2)$	faults of type 1 in the first and type 2 in the last layers. x-1 fault of type 1 and y of type 2 in the inner layers
"	$\frac{(n-1)! \alpha^{x+y} A^{n-x-y}}{(n-x-y)! (y-1)! x!}$	$(F+G_2)^* F$	a fault of type 2 in the first layer and x of type 1 y-1 of type 2 in the inner layers
"	$\frac{(n-1)! \alpha^{x+y+1} A^{n-x-y-1}}{(n-x-y)! (y-1)! x!}$	$(F+G_2)^* (F+G_1)$	a fault of type 2 in the first and type 1 in the last layers. x faults of type 1 and y-1 of type 2 in the inner layers
"	$\frac{(n-1)! \alpha^{x+y+1} A^{n-x-y-1}}{(n-x-y)! (y-1)! x!}$	$ F+G_2 ^2$	faults of type 2 in the first and last layers and x of type 1 y-1 of type 2 in the inner layers
$\exp(2\pi i h \cdot (n\underline{c} + x\underline{S}_1 + (n-x)\underline{S}_2))$	$\frac{(n-1)! \alpha^n A}{(n-x-1)! x!}$	$(F+G_2)^* F$	fault of type 2 in the first layer and x of type 1 and n-x-1 of type 2 in the inner layers
"	$\frac{(n-1)! \alpha^n A}{(n-x)! (x-1)!}$	$(F+G_1)^* F$	fault of type 1 in the first layer and x-1 of type 1 and n-x of type 2 in the inner layers
"	$\frac{(n-1)! \alpha^{n+1}}{(n-x)! (x-1)!}$	$ F+G_1 ^2$	faults of type 1 in the first and last layers and x-1 of type 1, n-x of type 2 in the inner layers

Table 8-3 cont.

exponential	probability	structure factor	explanation
$\exp(2\pi i h \cdot (n \underline{c} + x \underline{S}_1 + (n-x) \underline{S}_2))$	$\frac{(n-1)! \alpha^{n+1}}{(n-x)! (x-1)!}$	$(F+G_1)^* (F+G_2)$	x-1 faults of type 1 and n-x of type 2 in the inner layers, and a fault of type 1 in the first and type 2 in the last layers
"	$\frac{(n-1)! \alpha^{n+1}}{(n-x-1)! x!}$	$(F+G_2)^* (F+G_1)$	x faults of type 1 and n-x-1 of type 2 in the inner layers, and a fault of type 2 in the first and type 1 in the last layers
"	$\frac{(n-1)! \alpha^{n+1}}{(n-x-1)! x!}$	$ F+G_2 ^2$	faults of type 2 in the first and last layers and x of type 1 n-x-1 of type 2 in the inner layers
$\exp(2\pi i h \cdot (n \underline{c} + y \underline{S}_2))$ y < n			same as for $\exp(2\pi i h \cdot (n \underline{c} + x \underline{S}_1))$ but with subscripts 1 and 2 reversed and y instead of x
$\exp(2\pi i h \cdot (n \underline{c} + \underline{S}_2))$			same as for $\exp(2\pi i h \cdot (n \underline{c} + \underline{S}_1))$ but with subscripts 1 and 2 reversed

$$T = 2\text{Re}\{\exp(2\pi i h \cdot \underline{c}) \{1 - A \exp(-2\pi i h \cdot \underline{c}) - \alpha \exp(-2\pi i h \cdot (\underline{c} + \underline{S}_1)) - \alpha \exp(2\pi i h \cdot (\underline{c} + \underline{S}_2))\} \\ \cdot \{F + \alpha G_1 + \alpha G_2\} \{AF^* + \alpha(F^* + G_1^*) \exp(2\pi i h \cdot \underline{S}_1) + \alpha(F^* + G_2^*) \exp(2\pi i h \cdot \underline{S}_2)\}\} \quad (8-7)$$

$$\text{and} \quad X = |F|^2 + 2\alpha \text{Re}F^*G_1 + 2\alpha \text{Re}F^*G_2 + \alpha|G_1|^2 + \alpha|G_2|^2 \quad (8-8)$$

§ 8.4 Stacking Faults of VAsO₅

Two possible models for stacking faults were considered. Since expression VIII-5 has the greatest value at points where D is a minimum, D was calculated for both models to see if the minima for D fell at points where the intensity was a maximum in the diffraction pattern.

Model I:

VAsO₅ and α -VPO₅ appear to form solid solutions over the full composition range (see section 8-5) and hence it would seem possible that, once in a while, a stacking arrangement as in α -VPO₅ can be found rather than the edge-sharing arrangement. There are four possible arrangements of such faults (figure 8-5). Figure 8-5(a) and (c) and also (b) and (d) are mirror images of each other, and these faults would thus be expected to occur with the same probability. The denominator for an expression like equation 8-5 was found for the case of four faults with two each of equal probability, and this denominator was evaluated for 0k ℓ points. The minima of the denominator did not fall at k and ℓ values for which the intensity was a maximum, and hence this model was discarded.

Model II:

The VO₆ octahedra in VAsO₅ alternately share one of two edges. The difference map in the final stages of refinement showed residual electron density in places which suggest that, once in a while, a "mistake" is made and octahedra in two subsequent layers share edges in the same

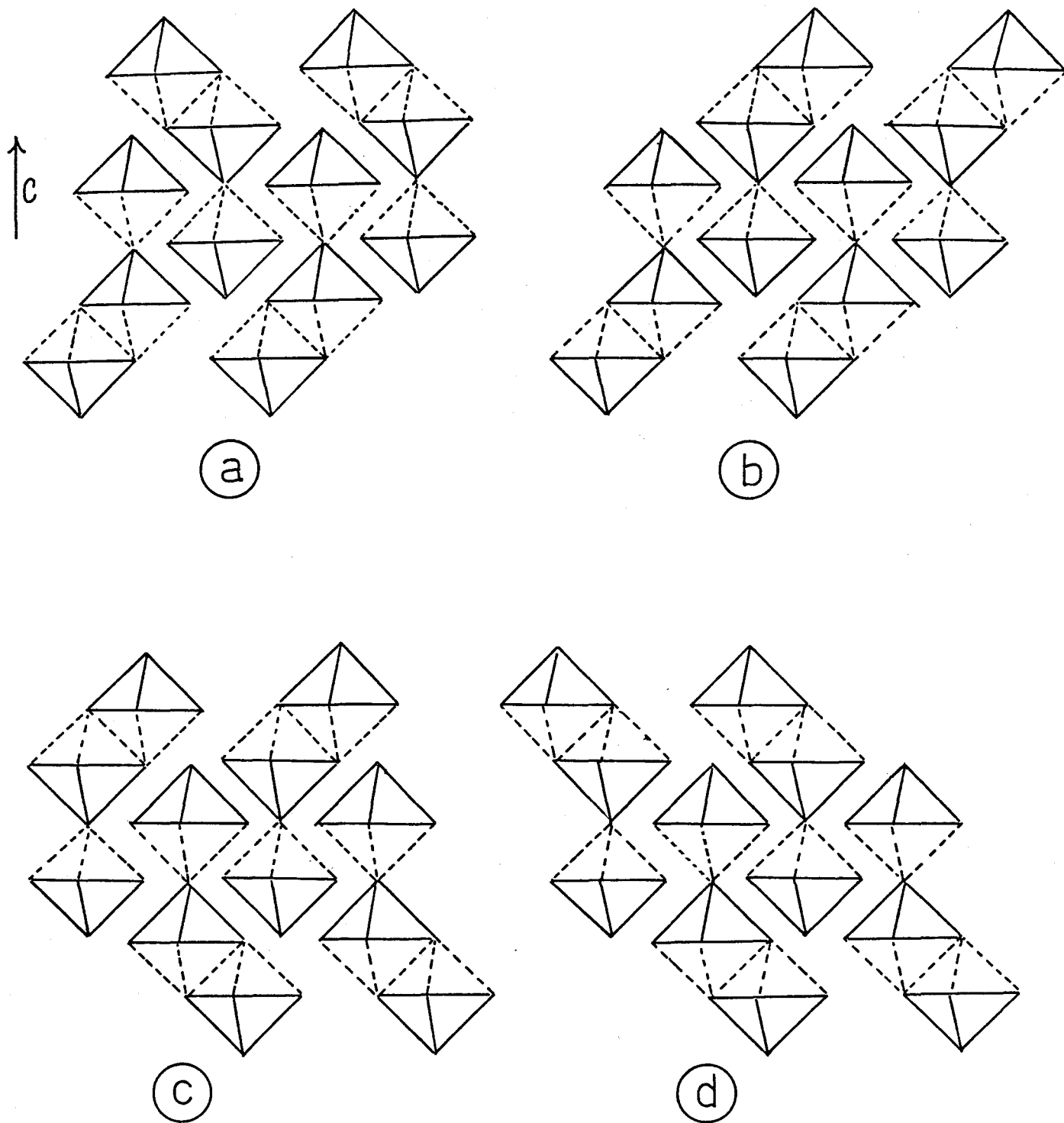


Figure 8-5. Four possible stacking faults for $VAsO_5$, Model I. The VO_6 octahedra are idealized with the long oxygen bonds shown by the dotted lines. For clarity, the phosphate tetrahedra have been omitted.

direction. Two possible faults can be formed as shown in figure 8-6. These faults can be formed geometrically by the removal of an A layer (figure 8-6(b)) or a B layer (figure 8-6(c)) and a shift of the following layers which will give the fault structures indicated. Since the two possible faults are mirror images of each other, and since there is no a priori reason to assume one more probable than the other, each fault is considered to have equal probability. The expressions in the preceding section consider \underline{S}_1 and \underline{S}_2 to have the same origin with respect to the unit cell, and hence it is more convenient to consider the fault in fig.8-6(b) to be formed by the addition of a B layer (rather than removal of an A layer). The net result is the same, and vectors \underline{S}_1 and \underline{S}_2 now have a common origin with \underline{c} components of $+\frac{1}{2}$ and $-\frac{1}{2}$ and \underline{b} components of about -0.45 and $+0.45$ respectively. This model gave shifted positions from the Bragg peaks of about the right size and in the right direction for $0k\ell$ points. The best fit appeared to fall at about $\alpha=0.23$. Smaller values of α gave too small a deviation from the Bragg position and much larger values gave deviations that were too large. Small changes in the coordinates of the fault vectors changed the size of the minima in the denominator and the value of the intensities. The full intensity was calculated for 02ℓ points over the range $-4.1 \leq \ell \leq 4.1$ for $\alpha=0.23$ and various \underline{b} and \underline{c} components of the fault vectors ranging in absolute value from $0.42-0.48$ and $0.48-0.52$ respectively. The best fit for the intensity for the 02ℓ points was found at the \underline{b} and \underline{c} components for \underline{S}_1 of $(-0.43, 0.5)$ and $(0.43, -0.5)$ for \underline{S}_2 . Experimental and calculated values are shown in figure 8-7. The experimental intensities were obtained from a 02 precession photograph (fig.8-1) using an optical microdensitometer and were corrected for Lorentz and

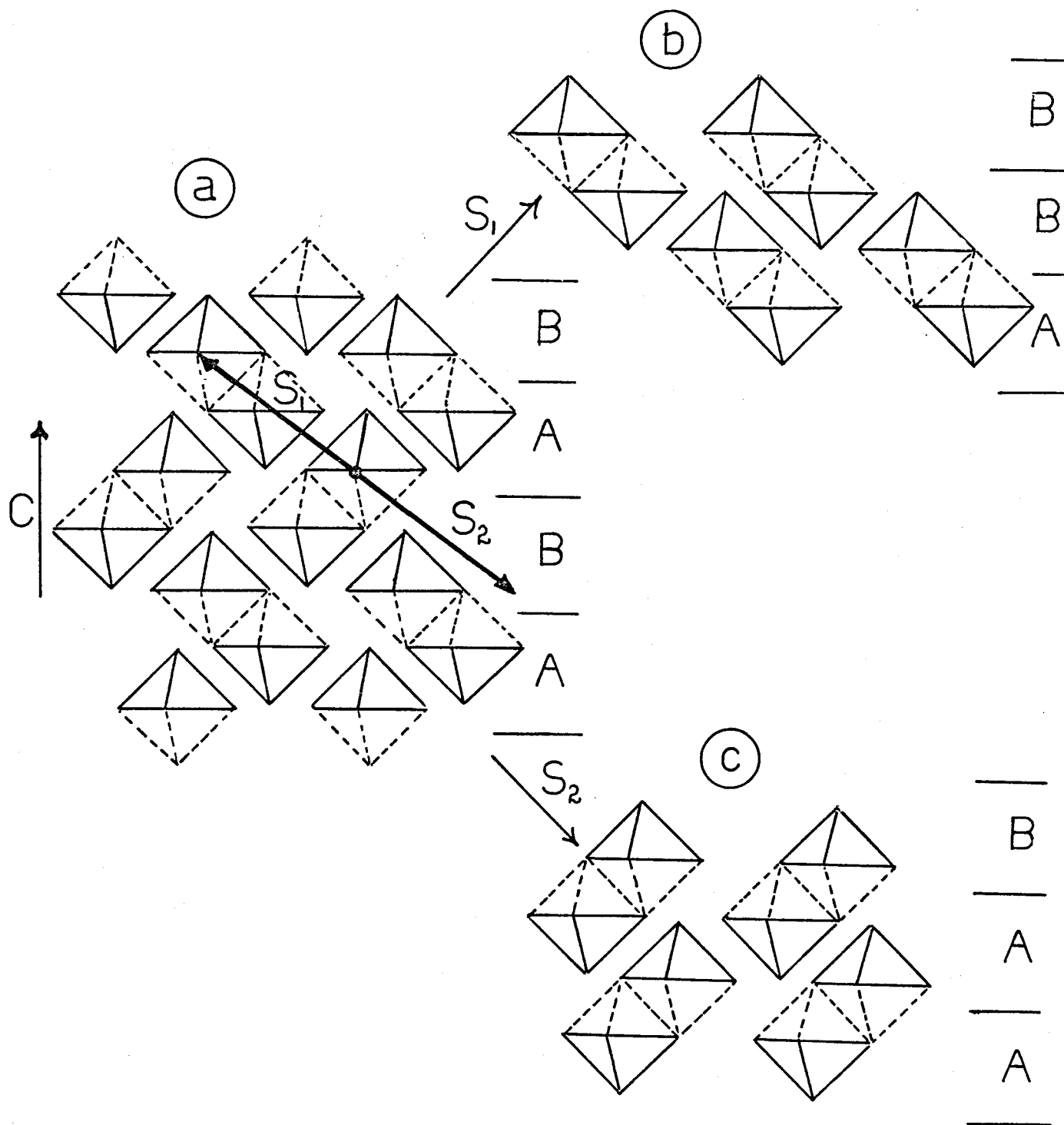


Figure 8-6. Model II stacking faults for VAsO_5 . (a) shows the two possible fault vectors, and (b) and (c) show the appearance of each of the faults.

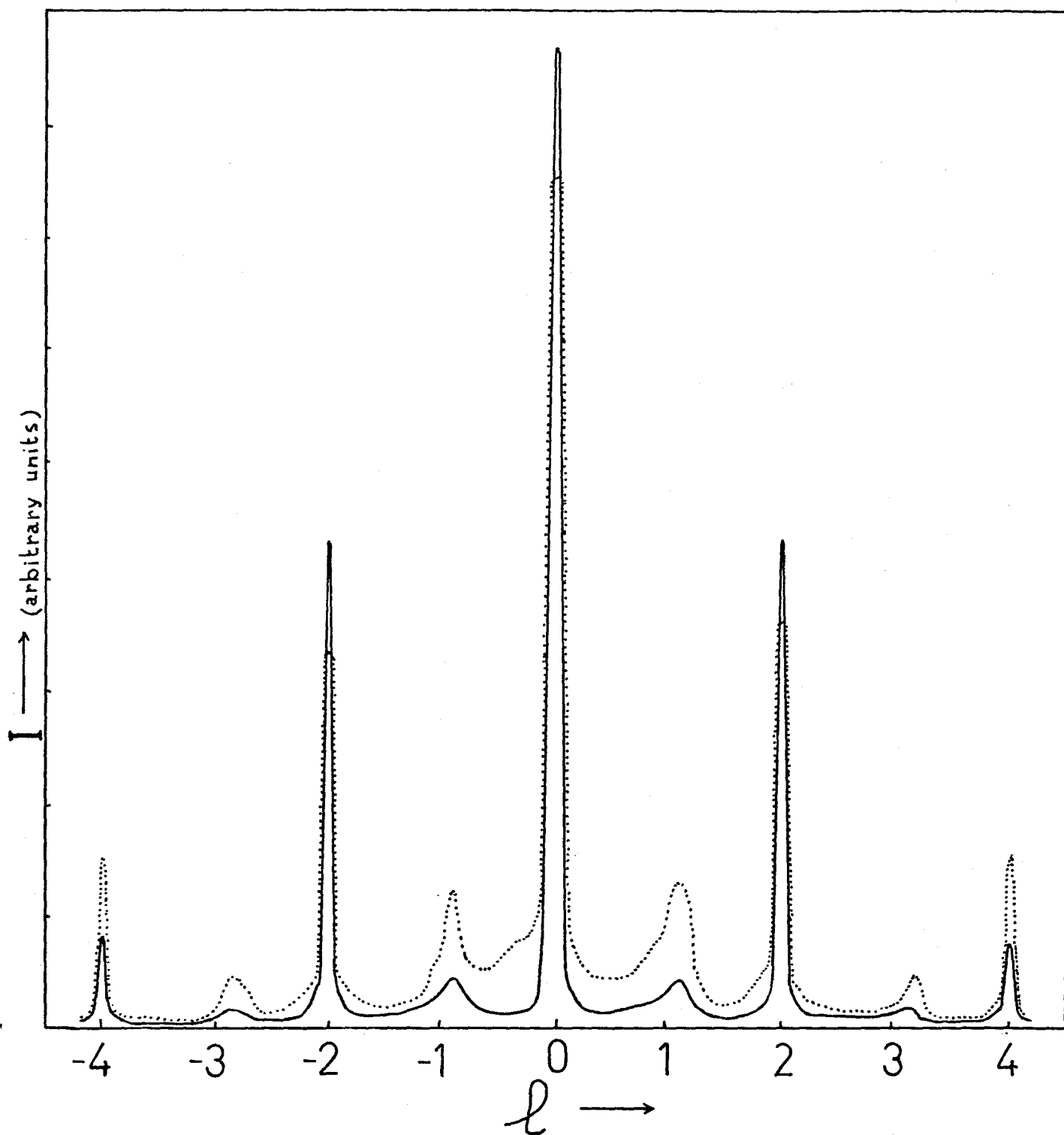


Figure 8-7. Observed (.....) and calculated (—) intensities for the 02ℓ line. Observed intensities have been corrected for Lorentz and polarization effects.

polarization effects. The background was estimated from optical density measurements immediately adjacent to the 02 ℓ line and this background was subtracted from the measured intensities. The fit, though far from perfect, seems good enough to indicate that this model must represent the major stacking faults that occur. When the intensities were calculated using formula 8-5 with G_1 and G_2 both equal to zero (i.e. making no correction for the density modification at the faults) the intensity profile differed by at most and usually considerably less than 10% from that for the model containing the G-values. This shows that the modification of the electron density at the faults does not significantly affect the intensity profile, and hence a least-squares refinement of α when fitting $F + \alpha G_1 + \alpha G_2$ to the observed structure factor is likely to underestimate its value. This is in agreement with the results ($\alpha = 0.1$ from least-squares and 0.23 from the intensity profile calculation). Cowley⁹⁹ observed this effect as well for stacking faults in magnesium fluorogermanate. The probability of a stacking fault occurring is very high (there is only a 54% probability of no fault occurring) and it is surprising that the refinement of the basic structure yielded an R-value as low as 0.2.

§ 8.5 The Solid Solution V(As,P)O₅

Bordes and Courtine⁴⁰ have found that α -VPO₅ and VAsO₅ form a solid solution of the form $VAs_{1-x}P_xO_5$ over the whole range of $0 \leq x \leq 1$. This result has been confirmed by us. Samples of composition $x = 0.1, 0.5$ and 0.75 were prepared by the procedure outlined in chapter 3. All of the crystals were yellow, mica-like sheets similar to those of the end members of the solution range. Single crystals suitable for x-ray analysis were not found, but a and c parameters were determined from powder diffraction

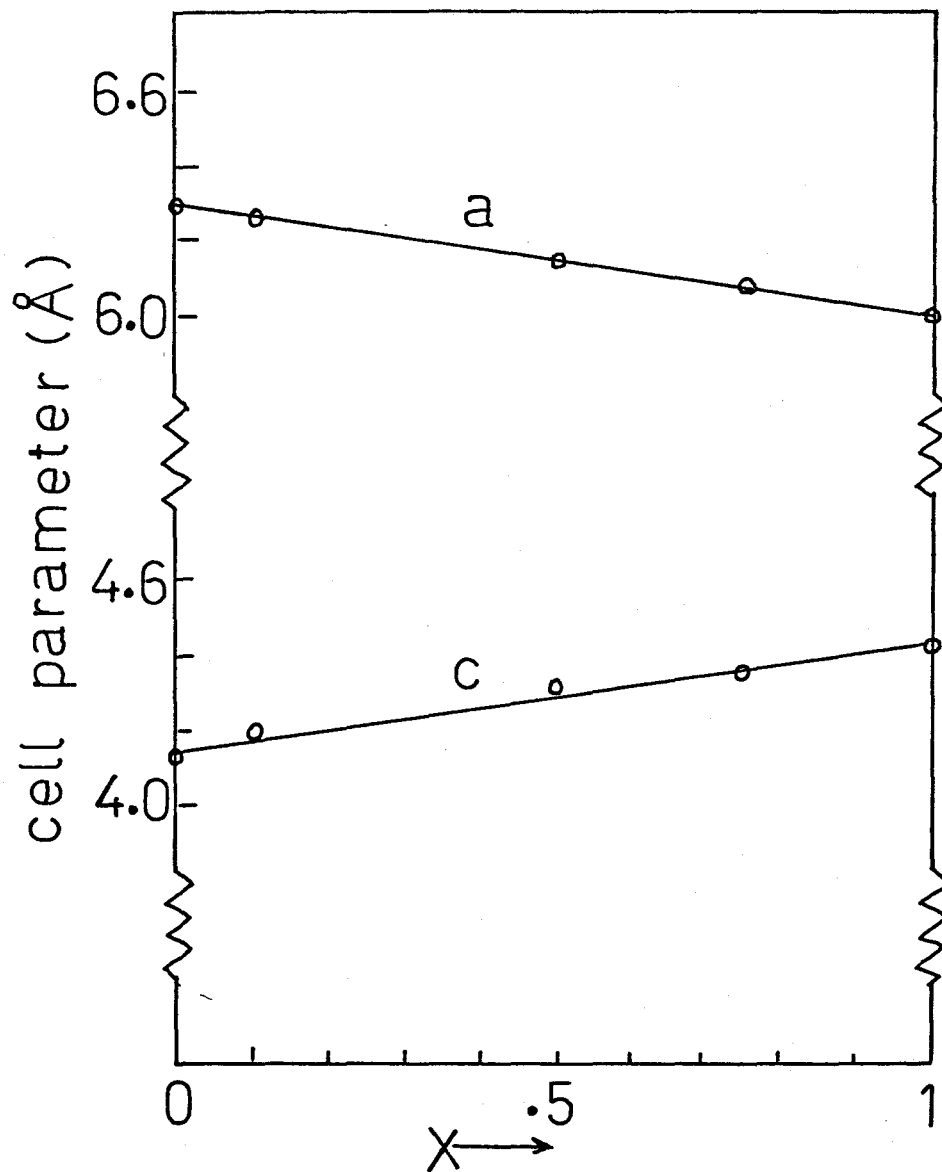


Figure 8-8. Cell parameters for $VAs_xP_{1-x}O_5$

data. The results are shown in figure 8-8. The parameters for α -VPO₅ were obtained from Jordan, et al.¹¹ and the VAsO₅ parameters are those determined from single crystal diffraction, with the c-axis divided by two to correspond to the layer length rather than the actual axis length in order to make comparisons with α -VPO₅ possible. The a parameters fall nicely on a straight line reflecting the change in size of the tetrahedral cation. The c parameters do not fit as well on a straight line, although the trend is suggestive of a gradual change from VAsO₅-like stacking to α -VPO₅-like stacking as x increases. Perhaps this could be accomplished by stacking faults as in model 1 section 4, of increasing frequency as x increases. Single crystal intensities will have to be considered in order to determine the actual change in structure over the whole range of x.

§ 8.6 Thermal Behaviour of VAsO₅

A DTA analysis of VAsO₅ shows a strong endotherm at about 560°C on heating, following which the specimen gradually volatilizes until all is gone before the melting point estimated at about 800°C. When single crystals of VAsO₅ are gradually heated, the diffraction pattern does not change significantly until about 560°C, when the crystal invariably crumbles. The nature of the structure of VAsO₅ remains to be determined above 560°C, although it seems evident that a structural phase transition takes place at this temperature. Materials such as the H-form of P₂O₅²⁸ which volatilize readily often contain discrete molecular units in the crystalline phase. The molecular units are held together by forces which are weaker than those in extended bonded networks. The energy required to remove molecules from molecular crystals is therefore smaller than

that required for network crystals. The molecular crystals can, therefore, be expected to volatilize more readily. Since VAsO_5 in the high temperature form does readily volatilize, it might contain molecular units rather than consisting of a network of bonds like the low temperature form.

CHAPTER 9

Discussion and Conclusion

§ 9.1 The V-P-As-O System

The crystals in this study are all of the type $M_n O_{2n+1}$ with $n=2,3$, or 4, and M a combination of any of V, P, As or Si.

The $n=2$ compound, $VAsO_5$, with $M_2=VAs$, is structurally related to other M_2O_5 compounds in the V-P-As-O system. Vanadium is always found octahedrally coordinated with one long V-O bond trans to a short vanadyl bond. The vanadyl oxygen is sometimes uni-coordinated ($VAsO_5$ and $\beta-V_2O_5$ ¹⁷) and sometimes forms a long V-O bond to another VO_6 group ($\alpha-V_2O_5$ ², α and $\beta-VPO_5$ ^{11,12}). Some of the compounds form layers ($\alpha-VPO_5$ ¹¹, $VAsO_5$, α and $\beta-V_2O_5$ ^{2,17}), which, except for $\beta-V_2O_5$, (see p.5) are held together by long V-O bonds. These layers form stacking faults easily, and evidence for such disorder has been found for all except $\alpha-V_2O_5$. $\alpha-VPO_5$ and $VAsO_5$ vary only in the stacking arrangement of the layers. A solid solution of the form $VAs_xP_{1-x}O_5$ exists over the full range $0 \leq x \leq 1$, and crystals throughout this range have the same layer structure as the end members but, presumably, the stacking arrangement changes with composition.

The H form of P_2O_5 ²⁸ is composed of molecular groups and the other forms of P_2O_5 ^{29,30} and As_2O_5 ³⁵ are network crystals which readily rearrange to yield molecular units when volatilizing at increased temperatures. The high temperature form of $VAsO_5$, as well as the above phosphorus and arsenic oxides, readily volatilizes. Thus the high temperature $VAsO_5$ is probably more closely related in structure to these oxides than to the layered oxides.

All the M_2O_5 compounds with M a combination of any of V, As and P should have M in the +5 oxidation state. Valences, calculated from Brown's¹⁶ bond-valence parameters and experimental bond-lengths, and corresponding coordinations are given in table 9-1. The errors on these experimental valences are large since the valence is $(\underline{r}/\underline{R})^{-N}$, where N and \underline{R} are tabulated parameters and \underline{r} is the experimental bond length, and $(d\underline{r}/d\underline{R})$ is large.

$VO(PO_3)_2$ is an $n=3$ compound with $M_3=VP_2$. Like $V_3O_7^3$, it contains single chains of corner-sharing $V^{+4}O_6$ octahedra. These octahedra each have the vanadyl oxygen forming a long V-O bond to the next octahedron in the chain. $VO(PO_3)_2$ shows disorder in the position of the vanadium atom and the corresponding direction of the vanadyl bond, but no such disorder is known for V_3O_7 .

The 5 coordinate groups in the single ribbons in $V_3O_7^3$ are similar to the metaphosphate chains in $VO(PO_3)_2$. If the 5 coordinate groups are changed to tetrahedra in such a way that the removed bond is one which was formed to an edge-sharing oxygen, a metavanadate chain results (fig.9-1). The oxidation state of P in the metaphosphate chain and V in the single ribbon is +5.

Only the double octahedral $V^{+4}O_6$ chains in V_3O_7 do not have a counterpart in $VO(PO_3)_2$.

Table 9-2 lists the structural features and oxidation states of vanadium and phosphorus in the two M_3O_7 compounds. The agreement of the valences with the expected integral values is as good as for the M_2O_5 groups, and hence there is no reason to expect that any structural elements are likely to have non-integral valences.

Table 9-1. Coordinations and Experimental Valences for M_2O_5 compounds in the V-P-As-O System. Valences were calculated using the bond-valence parameters of Brown¹⁶..

Compound	M	Coordination of M	Valence of M
α - V_2O_5	V	octahedral	5.11
β - V_2O_5	V	octahedral	accurate bond lengths not available
α - VPO_5	V	octahedral	5.34
α - VPO_5	P	tetrahedral	4.98
β - VPO_5	V	octahedral	5.26
β - VPO_5	P	tetrahedral	5.16
$VAsO_5$	V	octahedral	4.99
$VAsO_5$	As	tetrahedral	4.94
As_2O_5	As	octahedral	4.78
As_2O_5	As	tetrahedral	5.02
H- P_2O_5	P	tetrahedral	4.89
O- P_2O_5	P	tetrahedral	5.20
O- P_2O_5	P	tetrahedral	5.24

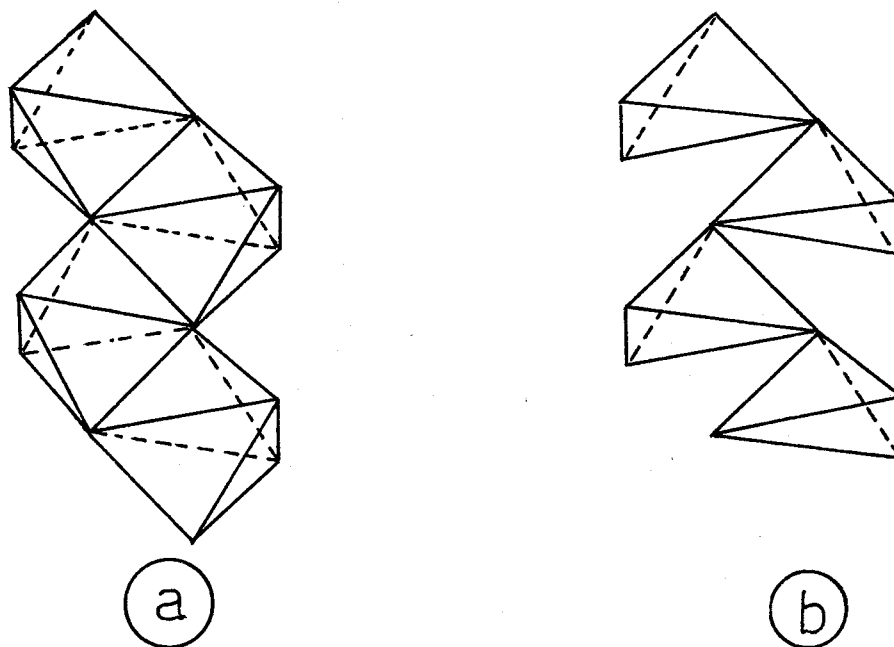


Figure 9-1. Relationship between a 5 coordinate ribbon (a) and a meta-chain (b)

Table 9-2. Structural Elements and Valences for M_3O_7 compounds in the V-P-O System. Valences were calculated using the bond valence parameters of Brown¹⁶.

Compound	M	Structural element	Valence of M
V_3O_7	V	single octahedral chain	4.17
$VO(PO_3)_2$	V	single octahedral chain	3.99
V_3O_7	V	single 5-fold coord. ribbon	4.96
"	"	"	5.17
"	"	"	5.16
$VO(PO_3)_2$	P	meta-phosphate chain	5.08
V_3O_7	V	double octahedral chain	4.24

The compounds VOP_2SiO_8 , $(VO)_2P_2O_7$ and $V(PO_3)_3$ all are of the type M_4O_9 with $M_4=VP_2Si$, V_2P_2 and VP_3 respectively. Although they are all three-dimensional network crystals, they are not as closely structurally related to each other and V_4O_9 as are the groups with $n=2$ and 3 . VOP_2SiO_8 contains $V^{+4}O_6$ corner-sharing chains, $(VO)_2P_2O_7$ contains $V^{+4}O_6$ double chains, and V_4O_9 contains double octahedral ribbons in which one of the two distinct vanadium atoms has an approximate valence of $+5$ and the other an average valence of $+4.5$. In addition, V_4O_9 contains single 5 coordinate ribbons in which two distinct atoms also have average valences of $+5$ and $+4.5$ respectively. These valences were estimated through the use of figure 9-2. Bond valences were calculated for each group based on Brown's¹⁶ bond-valence parameters for V^{+4} and also for V^{+5} . These values, when applied to the graph in figure 9-2, gave the approximate percentage of V^{+5} and V^{+4} , thereby making the evaluation of an average valence possible. Since the valences calculated for $n=2$ and $n=3$ compounds were only accurate to within about 0.2 valence units, values that deviated from $+4$ or $+5$ by less than this amount were considered to be essentially integral, as were values for P and Si. The structural elements above all contain vanadium with the typical vanadyl bond. This bond is not present in the regular isolated $V^{+3}O_6$ octahedra of $V(PO_3)_3$.

$P^{+5}O_4$ tetrahedra are isolated in VOP_2SiO_8 (each connecting to two VO_6 and two SiO_4 groups), exist as pyrophosphate groups in $(VO)_2P_2O_7$ and as metaphosphate chains in $V(PO_3)_3$. VOP_2SiO_8 also contains isolated SiO_4 tetrahedra. The single ribbons of V_4O_9 are similar to the metaphosphate chains in $V(PO_3)_3$, but do not have much resemblance to the

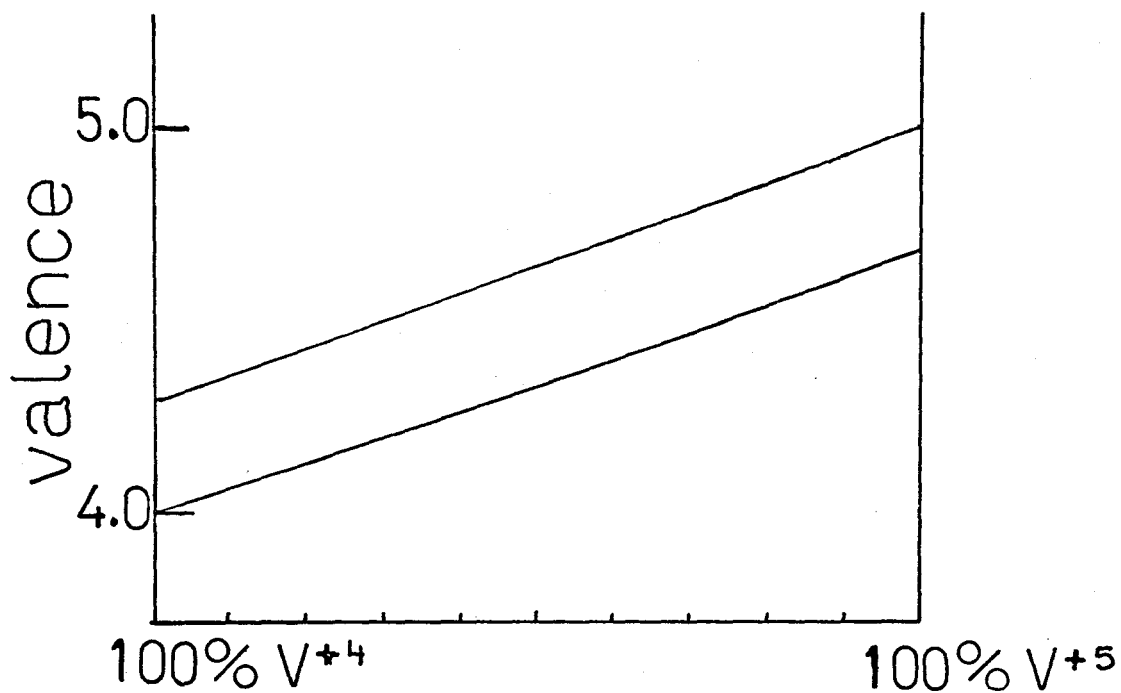


Figure 9-2. Valence for mixtures of V⁺⁴ and V⁺⁵ when calculated using bond-valence parameters for V⁺⁵ (a) and V⁺⁴ (b). The values were calculated assuming octahedral coordination.

other tetrahedral groups in M_4O_9 compounds. Valences and structural elements for these compounds are summarized in table 9-3. Bond lengths for $(VO)_2P_2O_7$ and $V(PO_3)_3$ are numerous and not very accurate, and the valences for the same structural elements in each of these compounds were averaged before inclusion in the table.

$V_6O_{13}^5$ is the only $n=6$ compound known in the V-P-As-O system. It contains single ribbons with V^{+4} and double ribbons with the two distinct vanadium atoms having average valences of +5 and +4.5. The valences and structural elements are summarized in table 9-4.

§ 9.2 Reduction of VPO_5

Like the $V_2O_5 \rightarrow V_6O_{13} \rightarrow VO_2$ transition described in chapter 1, the reduction of VPO_5 (both α and β forms) to $(VO)_2P_2O_7$ can readily be accomplished by the formation of shear planes. These shear planes can form in every second, every third, ... or every n^{th} layer, thereby producing a variety of structures intermediate in composition between VPO_5 and $VPO_{4.5}$.

Figure 9-3 shows how α - VPO_5 can form shear planes leading eventually to the $(VO)_2P_2O_7$ structure by a cooperative movement of VO_6 octahedra along the $1\bar{1}0$ direction. During this shift, the phosphate tetrahedra rotate in such a way that the corner, previously shared with one of the octahedra which are to be joined together, points up or down to share an oxygen with a PO_4 group in the layer above or below. This requires that the corresponding phosphate tetrahedra in adjacent α - VPO_5 layers must rotate in opposite directions in order to be able to form P_2O_7 groups. Since the VPO_5 layers are all identical, there is no a priori reason why one phosphate should rotate differently from any

Table 9-3. Valences and structural elements of M_4O_9 compounds in the V-P-Si-O system. Valences were calculated using Brown's¹⁶ valence-bond parameters and average valences were estimated from calculated ones using figure 9-2.

Compound	M	Structural Element	Valence based on V^{+4} parameters	Valence based on V^{+5} parameters	Average valence
VOP_2SiO_8	V	octahedral chains	4.20		
$(VO)_2P_2O_7$	V	double octahedral chains	4.0*		4.0*
V_4O_9	V	double octahedral ribbons	4.37	4.66	4.5
"	"	"		4.86	
"	"	single 5 coord. ribbon	4.43	4.70	4.5
"	"	"	4.02		
VOP_2SiO_8	P	isolated tetrahedra			5.24
"	Si	isolated tetrahedra			4.20
$(VO)_2P_2O_7$	P	pyrophosphate groups			5.20*
$V(PO_3)_3$	P	metaphosphate chains			5.20*
"	V	isolated regular octahedra			3.18*

* value based on the average for structural units of the same kind.

Table 9-4. Valences and structural elements of V_6O_{13} .

Structural Element	Valence based on V^{+4} parameters	Valence based on V^{+5} parameters	Average valence
single octahedral ribbons	4.06		
double octahedral ribbons		4.82	
double octahedral ribbons	4.30	4.56	4.5

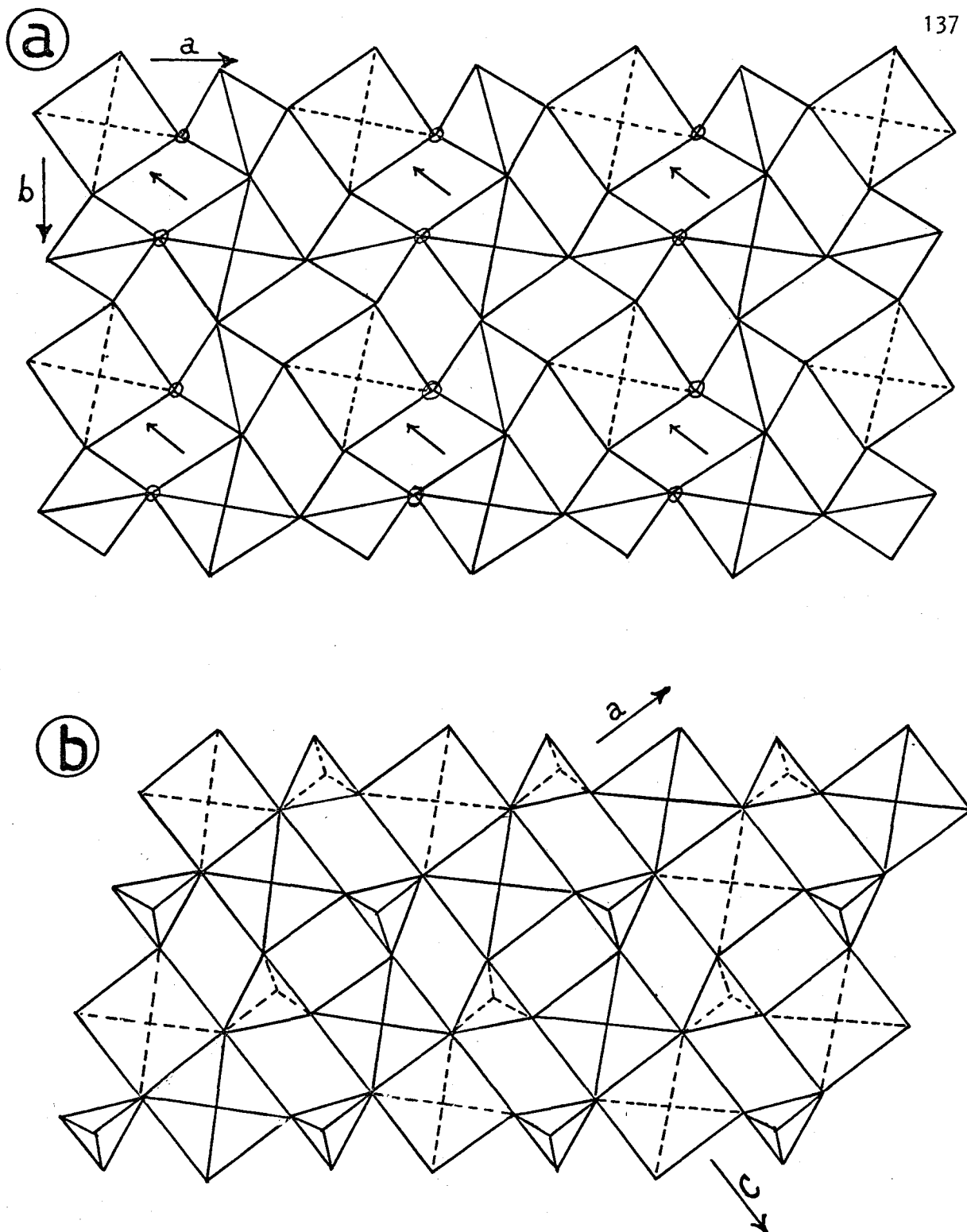


Figure 9-3. Reduction of $\alpha\text{-VPO}_5$ (a) to $(\text{VO})_2\text{P}_2\text{O}_7$ (b) through the cooperative movement of octahedra along the a direction indicated by the arrows. Phosphate tetrahedra twist to form pyrophosphate groups in the directions shown in (b). (o) indicate possible vacancy sites. Only $\frac{1}{2}$ of these need be formed for the layer to shift.

other, and, hence, it is reasonable to expect that the P_2O_7 groups can be found either above or below the ac plane of $(VO)_2P_2O_7$. Such disorder has, in fact, been found (chapter 7). The direction of the vanadyl bond in every second row of double octahedra is reversed from that in $\alpha\text{-VPO}_5$. This is likely a result of the rotation of the phosphate groups which now have three corners essentially in the ac plane of $(VO)_2P_2O_7$.

The proposed transition of $\beta\text{-VPO}_5$ to $(VO)_2P_2O_7$ is shown in figure 9-4. As for the case above, a cooperative movement of octahedra is required, this time in the $\bar{1}\bar{1}\bar{1}$ direction. The shift involves the joining of two octahedra that are not connected by phosphate groups, one being at an a coordinate near 0 and the other at an a coordinate near $\frac{1}{2}$. The phosphate groups rotate to form pyrophosphate groups with phosphate groups above (or below). In $\beta\text{-VPO}_5$ the phosphate groups share two corners with two octahedra in one chain, and it is one of these corners that most likely shifts to form the P_2O_7 group. The polyhedra in $\beta\text{-VPO}_5$ are all linked in a plane perpendicular to a, but because of the likely shift explained above (and shown in diagram 9-4), the shear will form at a 45° angle to this plane.

The production of $(VO)_2P_2O_7$ can occur in stages starting with the formation of vacancies, and following with the gradual collapse or shearing of planes. The intermediate compositions VPO_x , $4.5 \leq x \leq 5$, will have partially a VPO_5 structure and partially a $(VO)_2P_2O_7$ structure. The cell dimensions of the two end members of the composition range are sufficiently commensurate that these kinds of domains can readily be formed. Titanium, niobium and tungsten oxides are known to form similar

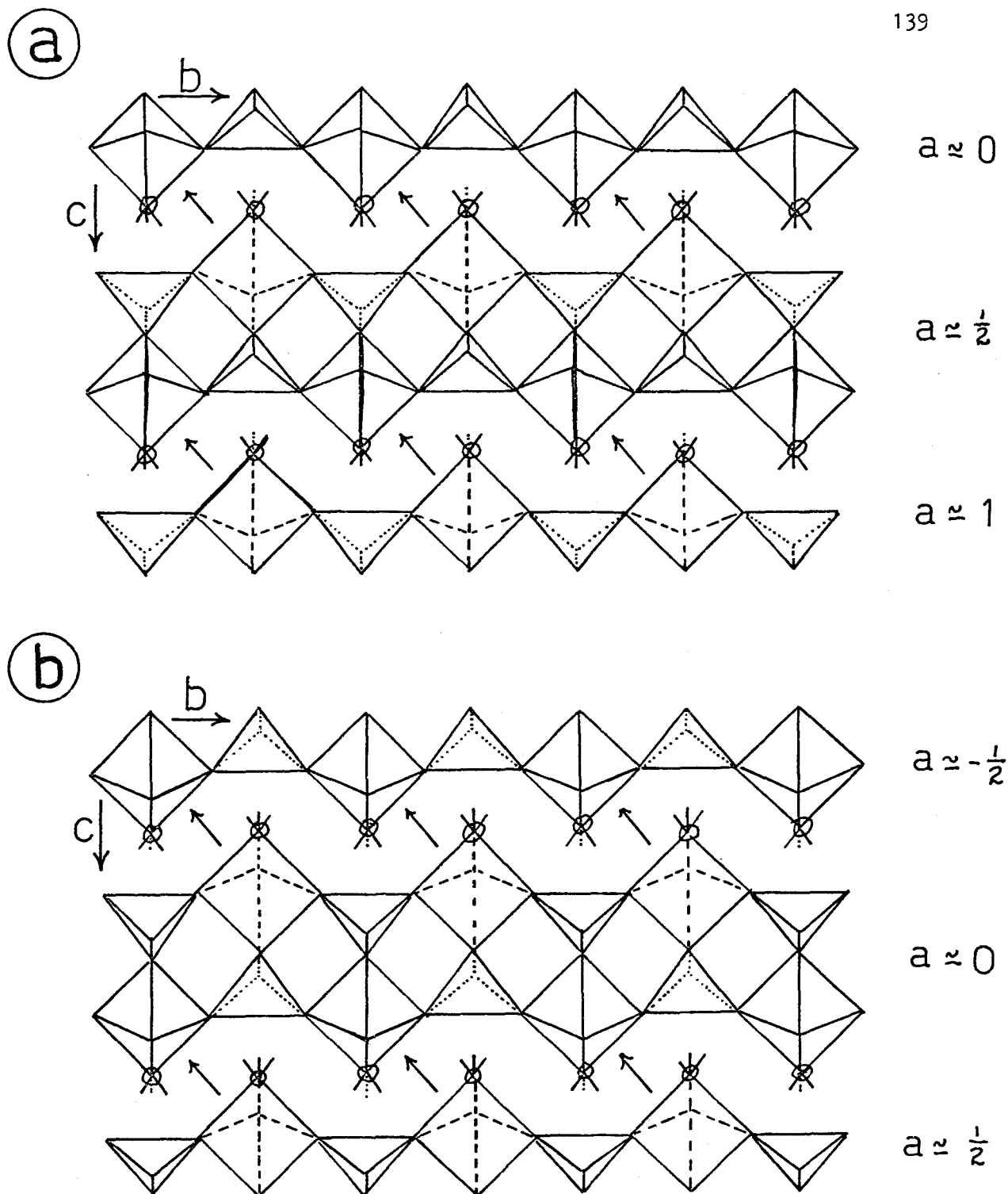


Figure 9-4. Reduction of $\beta\text{-VO}_5$ to $(\text{VO})_2\text{P}_2\text{O}_7$. (a) and (b) show the cooperative movements of octahedra required in two halves of the unit cells. The end product is as in figure 9-3(b). (a) indicates possible vacancy formation during catalysis. Only $\frac{1}{2}$ of these vacancies must be formed for the layers to shift. Although all polyhedra are connected in the bc plane, part of layers at different levels along a have been shown to facilitate illustrating the octahedral shifts.

shear structures, and models for these structures have been proposed by comparing the electron microscope images to theoretically calculated ones^{100,101,102}. This technique is still in its infancy, but could be useful in determining the exact defect structure of $(VO)_2P_2O_7$.

The structure of the intermediate $VPO_{4.75}$ found by Bordes and Courtine⁴⁰ at high temperature (about 750-800°C) during the incomplete reduction of both forms of VPO_5 , can readily be predicted by joining every other two rows of octahedra in either form of VPO_5 . The structures produced from α and β - VPO_5 respectively are shown in figures 9-5 and 9-6. Note that of necessity, this model requires polymorphism of $VPO_{4.75}$.

§ 9.3 Vanadium Phosphate Catalysts

When VPO_5 is used as a catalyst in the oxidation of butene to maleic anhydride, $(VO)_2P_2O_7$ is known to be produced^{40,59,60}. The catalyst reduction could produce vacancies at the surface which can then migrate into the bulk of the material, and, when they become sufficiently concentrated and are situated at the appropriate places (such as those marked on diagrams 9-3 and 9-4), the movement of octahedra can occur to produce $(VO)_2P_2O_7$. One scheme for the diffusion of vacancies through the double octahedral vanadate chains is shown in figure 9-7. A vanadyl oxygen is removed during catalysis, and this is replaced by an equatorial oxygen which is replaced by a vanadyl oxygen and so on, until sufficient vacancies are created at the equatorial oxygens for collapse of the structure. This mechanism can produce intermediate stoichiometries as well.

Other structures in this study, with the exception of $VAsO_5$, cannot readily undergo a similar rearrangement. $V(PO_3)_3$ has vanadium in the +3 oxidation state and reduction is thus not likely. In addition,

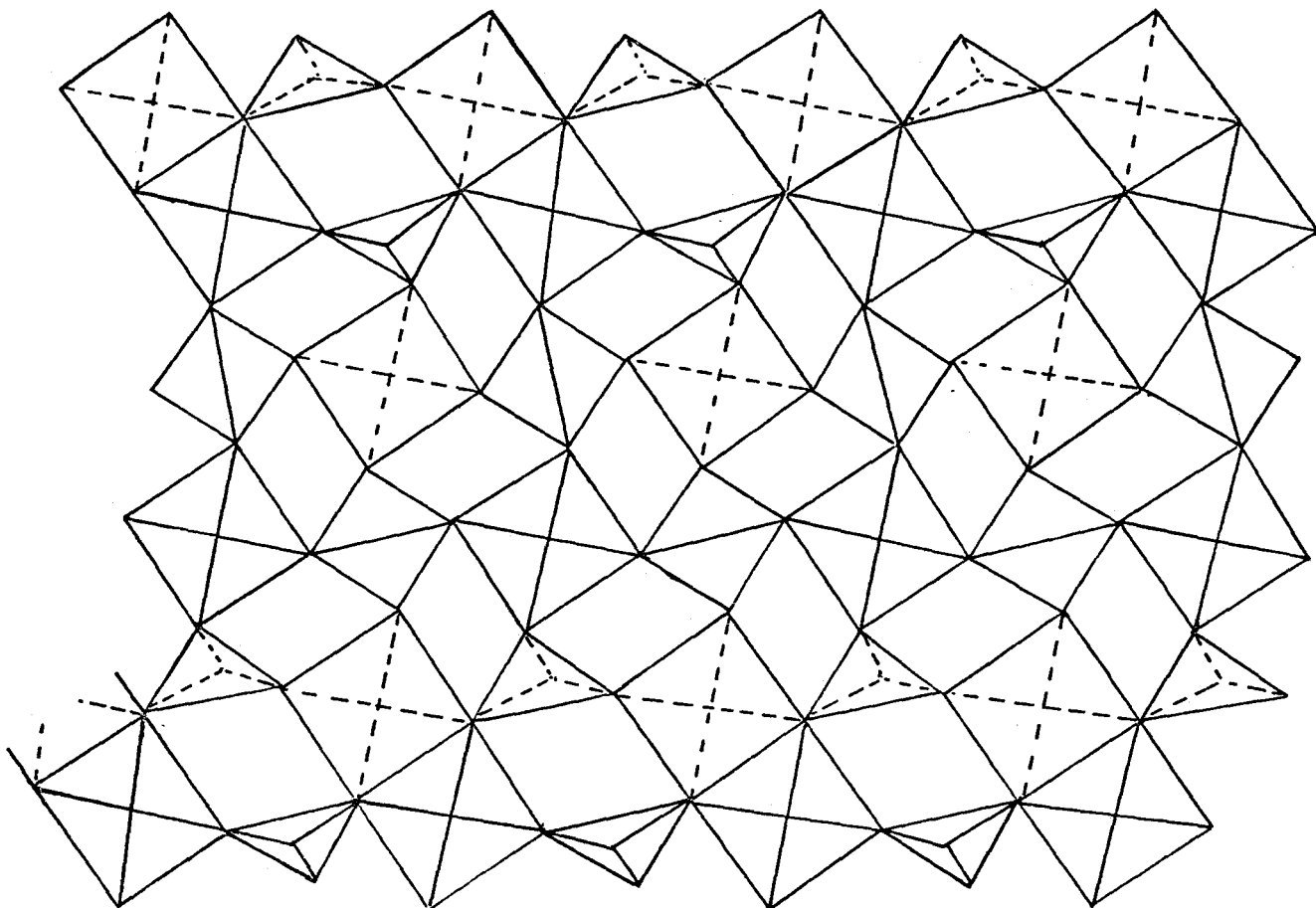


Figure 9-5. Proposed structure of $\text{VP}_{4.75}\text{O}_{17}$ derived from the incomplete reduction of $\alpha\text{-VP}_{5}\text{O}_{20}$. The second layer is the same as this one with the direction of the phosphate groups forming P_{2}O_{7} groups reversed.

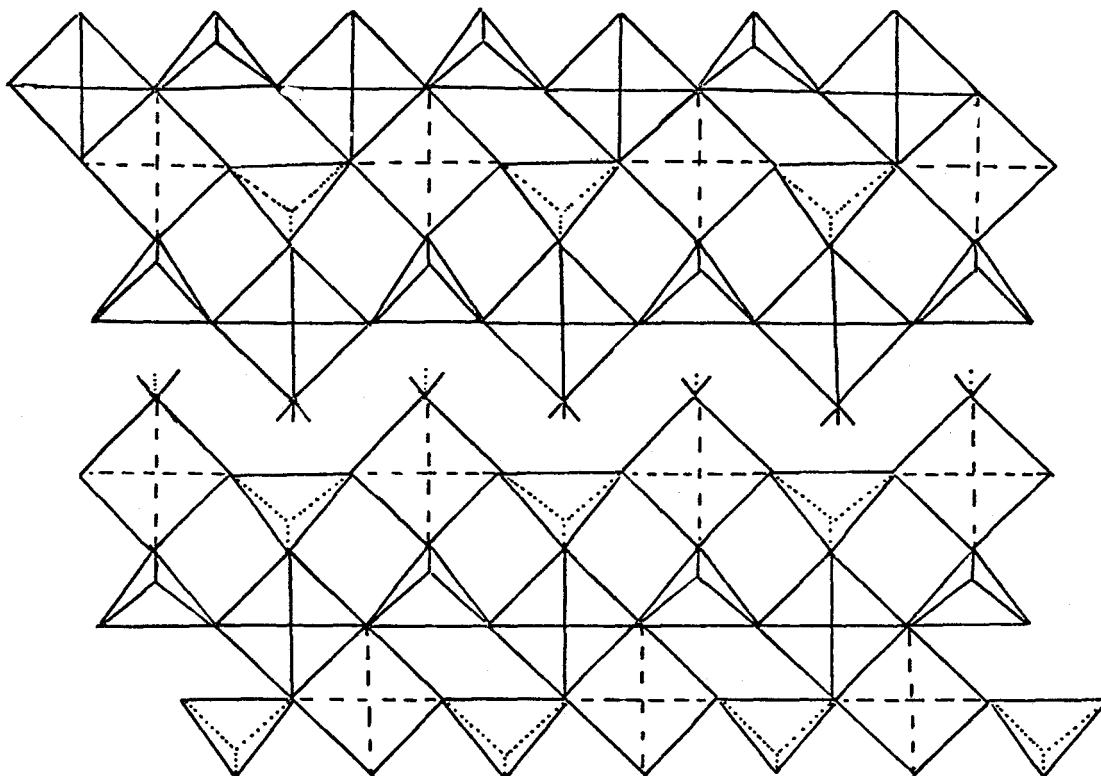


Figure 9-6. Proposed structure of $\text{VPO}_{4.75}$ derived from the incomplete reduction of $\beta\text{-VPO}_5$. The second layer consists of the second layer of $\beta\text{-VPO}_5$ joining rows of essentially $(\text{VO})_2\text{P}_2\text{O}_7$ -like groups.

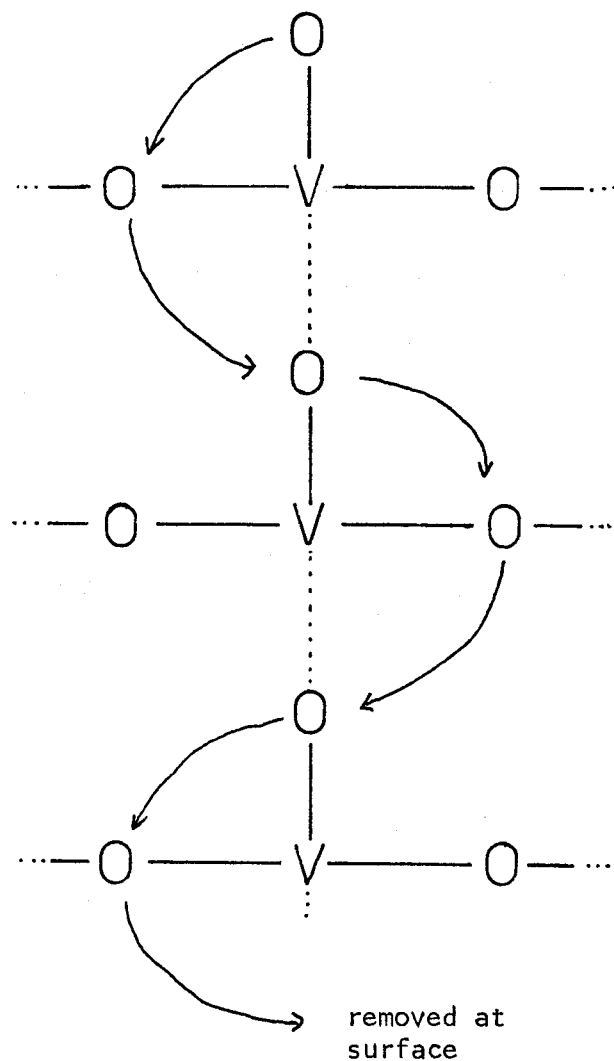


Figure 9-7. Suggested mechanism for the diffusion of oxygen vacancies during catalysis. Only the vanadate chain is shown, and only two oxygen atoms in the equatorial positions are shown. The mechanism only involves the two equatorial oxygen atoms as indicated on figure 9-3.

the vanadate octahedra are too far apart to make their condensation and the diffusion of vacancies possible. Both VOP_2SiO_8 and $VO(PO_3)_2$ contain octahedral VO_6 chains connected by $PO_4-SiO_4-PO_4-\dots$ tetrahedral chains in the former and meta-phosphate chains in the latter. Neither of these connective chains can readily condense to allow the edge-sharing of VO_6 groups, since neighbouring connective chains are too far away, and edge-sharing of tetrahedra is unlikely. Bordes and Courtine⁴⁰ report that $VO(PO_3)_2$ is catalytically inactive and it seems likely (although not confirmed) that VOP_2SiO_8 is also inactive. If this is in fact the case, care must be taken when supporting vanadium phosphate catalysts on silica, that no reaction occurs between the silica and the catalyst to produce VOP_2SiO_8 . $VAsO_5$ can undergo a reduction with a mechanism like that of $\alpha-VPO_5$ in principle, although a shifting of layers is required. It is not known if $VAsO_5$ is catalytically active.

Nakamura⁶¹ found that a V:P=1:2 catalyst was most selective and proposed the mechanism shown in figure 1-8. If his catalyst was in fact $VO(PO_3)_2$ (in contradiction to the results of Bordes and Courtine⁴⁰) his mechanism seems plausible in view of the structure for $VO(PO_3)_2$. The VO_6 chains are disordered in the vanadium and vanadyl bond positions and oxygen can thus be readily added to (or removed from) one of these chains at the surface, thereby reversing the vanadyl bond direction. This would of necessity be a surface reaction only, since migration into the bulk is unlikely.

The increase in selectivity with phosphorus concentration suggests a catalytic mechanism involving equatorial oxygens in the VO_6 groups which are bonded to phosphate groups rather than a mechanism which

involves shears at the vanadyl oxygens since the latter do not change significantly in environment from V_2O_5 to $VP O_5$. Since the V-O bonds are longer than P-O bonds, one might logically expect the P-O bond energy to be greater, and more energy is involved in the removal of an oxygen atom bonded to one V and one P atom than an oxygen bonded to two vanadium atoms. If the activation energy of the main reaction in the catalytic process is smaller than that of the side reactions, it follows that the vanadium phosphate catalysts will catalyze fewer side reactions. The decrease in activity of the vanadium phosphate catalysts compared to the vanadium oxide catalysts could be due to the migration of vacancies being "easier" (i.e. energetically more favourable) in the vanadium oxides.

§ 9.4 Conclusions

The structures in the V-P-As-O system are difficult to determine since vanadium can exist in a variety of condensations, coordinations and oxidation states, and can readily change from one of these to any other. It is therefore not surprising that most of the crystalline phases of this system exhibit structural disorders and many exhibit polymorphism. Also, the ready formation of glasses (an extreme structural disorder of the crystal) is to be expected.

APPENDIX

Observed (F0) and calculated (FC) structure factor amplitudes.

A.1 VOP₂SiO₈ Crystal 1
 All values are multiplied by 10.

H	K	F ₀	F _C	H	k	F ₀	F _C	H	K	F ₀	F _C	H	K	F ₀	F _C
L=0				L=2				L=3				L=4			
1	1	111	933	0	0	1140	11336	2	1	216	237	0	0	0	0
2	1	1784	775	1	1	820	820	3	1	45	35	1	1	33	33
3	1	1741	1742	2	2	593	587	4	1	76	64	2	2	61	61
4	1	618	644	3	3	277	277	5	1	115	94	3	3	93	93
5	1	772	743	4	4	693	693	6	2	23	21	4	4	124	124
6	1	86	137	5	5	334	334	7	3	66	55	5	5	155	155
7	1	180	168	6	6	122	122	8	4	111	94	6	6	206	206
8	1	112	116	7	7	480	480	9	5	33	33	7	7	277	277
9	1	474	408	8	8	133	133	10	6	114	94	8	8	366	366
10	1	660	670	9	9	607	607	11	7	34	33	9	9	444	444
11	1	1133	129	10	10	145	145	12	8	111	94	10	10	533	533
12	1	470	481	11	11	480	480	13	9	33	33	11	11	622	622
13	1	660	581	12	12	133	133	14	10	114	94	12	12	711	711
14	1	1133	190	13	13	607	607	15	11	33	33	13	13	800	800
15	1	470	581	14	14	145	145	16	12	114	94	14	14	888	888
16	1	660	670	15	15	480	480	17	13	33	33	15	15	977	977
17	1	1133	129	16	16	133	133	18	14	114	94	16	16	1066	1066
18	1	470	481	17	17	607	607	19	15	33	33	17	17	1155	1155
19	1	660	581	18	18	145	145	20	16	114	94	18	18	1244	1244
20	1	1133	190	19	19	480	480	21	17	33	33	19	19	1333	1333
21	1	470	581	20	20	133	133	22	18	114	94	20	20	1422	1422
22	1	660	670	21	21	607	607	23	19	33	33	21	21	1511	1511
23	1	1133	129	22	22	145	145	24	20	114	94	22	22	1600	1600
24	1	470	481	23	23	480	480	25	21	33	33	23	23	1688	1688
25	1	660	581	24	24	133	133	26	22	114	94	24	24	1777	1777
26	1	1133	190	25	25	607	607	27	23	33	33	25	25	1866	1866
27	1	470	581	26	26	145	145	28	24	114	94	26	26	1955	1955
28	1	660	670	27	27	480	480	29	25	33	33	27	27	2044	2044
29	1	1133	129	28	28	133	133	30	26	114	94	28	28	2133	2133
30	1	470	481	29	29	607	607	31	27	33	33	29	29	2222	2222
31	1	660	581	30	30	145	145	32	28	114	94	30	30	2311	2311
32	1	1133	190	31	31	480	480	33	29	33	33	31	31	2400	2400
33	1	470	581	32	32	133	133	34	30	114	94	32	32	2488	2488
34	1	660	670	33	33	607	607	35	31	33	33	33	33	2577	2577
35	1	1133	129	34	34	145	145	36	32	114	94	34	34	2666	2666
36	1	470	481	35	35	480	480	37	33	33	33	35	35	2755	2755
37	1	660	581	36	36	133	133	38	34	114	94	36	36	2844	2844
38	1	1133	190	37	37	607	607	39	35	33	33	37	37	2933	2933
39	1	470	581	38	38	145	145	40	36	114	94	38	38	3022	3022
40	1	660	670	39	39	480	480	41	37	33	33	39	39	3111	3111
41	1	1133	129	40	40	133	133	42	38	114	94	40	40	3200	3200
42	1	470	481	41	41	607	607	43	39	33	33	41	41	3288	3288
43	1	660	581	42	42	145	145	44	40	114	94	42	42	3377	3377
44	1	1133	190	43	43	480	480	45	41	33	33	43	43	3466	3466
45	1	470	581	44	44	133	133	46	42	114	94	44	44	3555	3555
46	1	660	670	45	45	607	607	47	43	33	33	45	45	3644	3644
47	1	1133	129	46	46	145	145	48	44	114	94	46	46	3733	3733
48	1	470	481	47	47	480	480	49	45	33	33	47	47	3822	3822
49	1	660	581	48	48	133	133	50	46	114	94	48	48	3911	3911
50	1	1133	190	49	49	607	607	51	47	33	33	49	49	4000	4000
51	1	470	581	50	50	145	145	52	48	114	94	50	50	4088	4088
52	1	660	670	51	51	480	480	53	49	33	33	51	51	4177	4177
53	1	1133	129	52	52	133	133	54	50	114	94	52	52	4266	4266
54	1	470	481	53	53	607	607	55	51	33	33	53	53	4355	4355
55	1	660	581	54	54	145	145	56	52	114	94	54	54	4444	4444
56	1	1133	190	55	55	480	480	57	53	33	33	55	55	4533	4533
57	1	470	581	56	56	133	133	58	54	114	94	56	56	4622	4622
58	1	660	670	57	57	607	607	59	55	33	33	57	57	4711	4711
59	1	1133	129	58	58	145	145	60	56	114	94	58	58	4800	4800
60	1	470	481	59	59	480	480	61	57	33	33	59	59	4888	4888
61	1	660	581	60	60	133	133	62	58	114	94	60	60	4977	4977
62	1	1133	190	61	61	607	607	63	59	33	33	61	61	5066	5066
63	1	470	581	62	62	145	145	64	60	114	94	62	62	5155	5155
64	1	660	670	63	63	480	480	65	61	33	33	63	63	5244	5244
65	1	1133	129	64	64	133	133	66	62	114	94	64	64	5333	5333
66	1	470	481	65	65	607	607	67	63	33	33	65	65	5422	5422
67	1	660	581	66	66	145	145	68	64	114	94	66	66	5511	5511
68	1	1133	190	67	67	480	480	69	65	33	33	67	67	5600	5600
69	1	470	581	68	68	133	133	70	66	114	94	68	68	5688	5688
70	1	660	670	69	69	607	607	71	67	33	33	69	69	5777	5777
71	1	1133	129	70	70	145	145	72	68	114	94	70	70	5866	5866
72	1	470	481	71	71	480	480	73	69	33	33	71	71	5955	5955
73	1	660	581	72	72	133	133	74	70	114	94	72	72	6044	6044
74	1	1133	190	73	73	607	607	75	71	33	33	73	73	6133	6133
75	1	470	581	74	74	145	145	76	72	114	94	74	74	6222	6222
76	1	660	670	75	75	480	480	77	73	33	33	75	75	6311	6311
77	1	1133	129	76	76	133	133	78	74	114	94	76	76	6400	6400
78	1	470	481	77	77	607	607	79	75	33	33	77	77	6488	6488
79	1	660	581	78	78	145	145	80	76	114	94	78	78	6577	6577
80	1	1133	190	79	79	480	480	81	77	33	33	79	79	6666	6666
81	1	470	581	80	80	133	133	82	78	114	94	80	80	6755	6755
82	1	660	670	81	81	607	607	83	79	33	33	81	81	6844	6844
83	1	1133	129	82	82	145	145	84	80	114	94	82	82	6933	6933
84	1	470	481	83	83	480	480	85	81	33	33	83	83	7022	7022
85	1	660	581	84	84	133	133	86	82	114	94	84	84	7111	7111
86	1	1133	190	85	85	607	607	87	83	33	33	85	85	7200	7200
87	1	470	581	86	86	145	145	88	84	114	94	86	86	7288	7288
88	1	660	670	87	87	480	480	89	85	33	33	87	87	7377	7377
89	1	1133	129	88	88	133	133	90	86	114	94	88	88	7466	7466
90	1	470	481	89	89	607	607	91	87	33	33	89	89	7555	7555
91	1	660	581	90	90	145	145	92	88	114	94	90	90	7644	7644
92	1	1133	190	91	91	480	480	93	89	33	33	91	91	7733	7733
93	1	470	581	92	92	133	133								

H	K	Fo	Fc
12	0	175	182
12	1	225	220
12	2	145	152
12	3	27	39
L=5			
	1	354	349
	1	1149	1152
	1	2199	2222
	1	5633	5699
	1	204	205
	1	99	87
	1	180	180
	1	2268	2277
	1	3335	3400
	1	1111	1111
	1	2209	2209
	1	220	222
	1	33	33
	1	57	61
	1	39	39
	1	15	16
	1	33	33
	1	38	38
	1	41	41
	1	214	21
	1	14	13
	1	44	55
	1	56	56
	1	104	103
	1	81	79
	1	117	113
	1	46	25
	1	100	10
	1	177	171
	1	129	125
	1	33	33
	1	62	64
	1	33	32
	1	141	145
	1	273	279
	1	28	33
	1	40	44
	1	55	55
	1	55	54
	1	59	62
	1	43	48
L=6			
	0	150	26
	0	330	336
	0	786	776
	0	578	585
	0	392	400
	0	466	462
	0	382	383
	0	162	160
	0	558	555
	0	771	774
	0	546	546
	0	191	194
	0	505	502
	0	268	265
	0	168	170

H	K	Fo	Fc
5	5	289	289
5	5	374	374
5	5	288	288
5	5	290	290
5	5	194	194
5	5	77	77
5	5	601	604
5	5	352	352
5	5	207	207
5	5	318	318
5	5	86	86
5	5	395	395
5	5	18	18
5	5	270	270
5	5	339	339
5	5	96	96
5	5	51	51
5	5	737	737
5	5	111	111
5	5	112	112
5	5	289	289
5	5	254	254
5	5	54	54
5	5	183	183
5	5	72	72
5	5	44	44
5	5	195	195
5	5	160	160
5	5	421	421
5	5	28	28
5	5	176	176
5	5	225	225
5	5	56	56
5	5	218	218
5	5	501	501
5	5	111	111
5	5	138	138
5	5	326	326
5	5	223	223
5	5	173	173
5	5	120	120
5	5	126	126
5	5	237	237
L=7			
	1	494	500
	1	337	337
	1	126	126
	1	339	339
	1	39	39
	1	106	106
	1	24	24
	1	180	180
	1	23	23
	1	110	110
	1	238	238
	1	61	61
	1	397	397
	1	16	16
	1	285	285
	1	300	300
	1	27	27
	1	366	366
	1	31	31
	1	141	141
	1	164	164
	1	8	8
	1	52	52
	1	42	42

H	K	Fo	Fc
5	5	36	36
5	5	23	23
5	5	30	30
5	5	119	119
5	5	24	24
5	5	90	90
5	5	8	8
5	5	12	12
5	5	253	253
5	5	29	29
5	5	194	194
5	5	26	26
5	5	72	72
5	5	8	8
L=8			
	1	757	755
	1	246	243
	1	418	418
	1	195	193
	1	202	198
	1	418	418
	1	412	412
	1	250	250
	1	0	0
	1	377	373
	1	651	653
	1	278	286
	1	188	188
	1	205	205
	1	151	151
	1	172	180
	1	207	206
	1	214	222
	1	242	237
	1	34	36
	1	233	233
	1	111	111
	1	258	255
	1	158	152
	1	221	221
	1	336	336
	1	29	28
	1	185	188
	1	172	177
	1	4	35
	1	26	273
	1	18	101
	1	149	154
	1	34	36
	1	247	258
	1	455	456
	1	154	154
	1	320	314
	1	144	145
	1	78	87
	1	165	168
	1	151	149
	1	16	183
	1	433	446
	1	288	193
	1	176	174
L=9			
	1	270	270
	1	72	69
	1	71	54
	1	340	70
	1	129	124
	1	79	77
	1	107	108

H	K	Fo	Fc
5	5	166	162
5	5	149	141
5	5	221	220
5	5	167	165
5	5	141	144
5	5	50	31
5	5	49	41
5	5	108	111
5	5	36	26
5	5	280	283
5	5	40	8
5	5	74	77
5	5	130	133
5	5	36	47
L=10			
	0	180	169
	0	25	25
	0	469	458
	0	74	77
	0	116	102
	0	279	266
	0	649	633
	0	6	6
	0	27	26
	0	40	39
	0	127	125
	0	185	179
	0	37	34
	0	78	74
	0	48	48
	0	268	266
	0	608	608
	0	455	455
	0	222	222
	0	279	288
	0	44	42
	0	33	32
	0	116	111
	0	118	114
	0	90	85
	0	344	344
	0	531	533
	0	1070	1082
L=11			
	1	130	134
	1	39	1
	1	588	566
	1	38	38
	1	599	599
	1	38	44
	1	157	15
	1	46	6
L=12			
	0	256	254
	0	144	145
	0	164	169
	0	70	69
	0	171	159
	0	209	210
	0	379	388

H	K	FO	FC
11		119	10
111		183	24
1111		234	44
11111		144	36
111111		68	8
L=5			
1	1	351	34
11	11	147	19
111	111	203	14
1111	1111	550	55
11111	11111	209	26
111111	111111	107	9
1111111	1111111	177	16
11111111	11111111	268	24
111111111	111111111	227	19
1111111111	1111111111	364	34
11111111111	11111111111	212	12
111111111111	111111111111	235	22
1111111111111	1111111111111	34	3
11111111111111	11111111111111	17	1
111111111111111	111111111111111	311	31
1111111111111111	1111111111111111	225	22
11111111111111111	11111111111111111	392	39
111111111111111111	111111111111111111	216	21
1111111111111111111	1111111111111111111	116	11
11111111111111111111	11111111111111111111	54	5
111111111111111111111	111111111111111111111	19	1
1111111111111111111111	1111111111111111111111	49	4
11111111111111111111111	11111111111111111111111	3	0
111111111111111111111111	111111111111111111111111	115	11
1111111111111111111111111	1111111111111111111111111	41	4
11111111111111111111111111	11111111111111111111111111	266	26
111111111111111111111111111	111111111111111111111111111	110	11
1111111111111111111111111111	1111111111111111111111111111	186	18
11111111111111111111111111111	11111111111111111111111111111	84	8
111111111111111111111111111111	111111111111111111111111111111	147	14
1111111111111111111111111111111	1111111111111111111111111111111	32	3
11111111111111111111111111111111	11111111111111111111111111111111	49	4
111111111111111111111111111111111	111111111111111111111111111111111	334	33
1111111111111111111111111111111111	1111111111111111111111111111111111	139	13
11111111111111111111111111111111111	11111111111111111111111111111111111	57	5
111111111111111111111111111111111111	111111111111111111111111111111111111	151	15
1111111111111111111111111111111111111	1111111111111111111111111111111111111	46	4
11111111111111111111111111111111111111	11111111111111111111111111111111111111	25	2
111111111111111111111111111111111111111	111111111111111111111111111111111111111	32	3
11	11	20	2
111	111	50	5
11	11	73	7
111	111	255	25
L=6			
1	1	141	15
11	11	308	31
111	111	766	78
1111	1111	568	57
11111	11111	402	40
111111	111111	457	45
1111111	1111111	393	39
11111111	11111111	155	15
111111111	111111111	597	59
1111111111	1111111111	570	56
11111111111	11111111111	594	58
111111111111	111111111111	542	52
1111111111111	1111111111111	180	18
11111111111111	11111111111111	500	50
111111111111111	111111111111111	257	25
1111111111111111	1111111111111111	150	15
11111111111111111	11111111111111111	389	38

H	K	FO	FC
5	4	284	282
55	45	292	290
555	455	187	186
5555	4555	592	588
55555	45555	497	492
555555	455555	354	352
5555555	4555555	245	244
55555555	45555555	201	199
555555555	455555555	306	307
5555555555	4555555555	69	78
55555555555	45555555555	379	390
555555555555	455555555555	335	333
5555555555555	4555555555555	263	268
55555555555555	45555555555555	91	20
555555555555555	455555555555555	61	72
5555555555555555	4555555555555555	25	18
55555555555555555	45555555555555555	730	751
555555555555555555	455555555555555555	127	111
5555555555555555555	4555555555555555555	114	117
55555555555555555555	45555555555555555555	280	288
555555555555555555555	455555555555555555555	247	255
5555555555555555555555	4555555555555555555555	608	609
55555555555555555555555	45555555555555555555555	180	182
555555555555555555555555	455555555555555555555555	68	80
5555555555555555555555555	4555555555555555555555555	437	458
55555555555555555555555555	45555555555555555555555555	186	187
555555555555555555555555555	455555555555555555555555555	152	152
5555555555555555555555555555	4555555555555555555555555555	387	388
55555555555555555555555555555	45555555555555555555555555555	49	39
555555555555555555555555555555	455555555555555555555555555555	166	171
5555555555555555555555555555555	4555555555555555555555555555555	324	333
55555555555555555555555555555555	45555555555555555555555555555555	49	50
555555555555555555555555555555555	455555555555555555555555555555555	206	215
5555555555555555555555555555555555	4555555555555555555555555555555555	306	299
55555555555555555555555555555555555	45555555555555555555555555555555555	419	433
555555555555555555555555555555555555	455555555555555555555555555555555555	121	111
5555555555555555555555555555555555555	4555555555555555555555555555555555555	327	333
55555555555555555555555555555555555555	45555555555555555555555555555555555555	204	217
555555555555555555555555555555555555555	455555555555555555555555555555555555555	167	172
55	4555555555555555555555555555555555555555	108	112
555	455	115	115
55	4555	235	238
L=7			
1	1	503	500
11	11	60	18
111	111	119	129
1111	1111	336	336
11111	11111	35	22
111111	111111	101	108
1111111	1111111	41	26
11111111	11111111	171	173
111111111	111111111	64	38
1111111111	1111111111	114	106
11111111111	11111111111	234	236
111111111111	111111111111	38	46
1111111111111	1111111111111	106	97
11111111111111	11111111111111	30	8
111111111111111	111111111111111	281	283
1111111111111111	1111111111111111	53	88
11111111111111111	11111111111111111	289	297
111111111111111111	111111111111111111	42	14
1111111111111111111	1111111111111111111	367	368
11111111111111111111	11111111111111111111	41	5
111111111111111111111	111111111111111111111	146	136
1111111111111111111111	1111111111111111111111	160	154
11111111111111111111111	11111111111111111111111	66	43
111111111111111111111111	111111111111111111111111	29	7
1111111111111111111111111	1111111111111111111111111	54	26
11111111111111111111111111	11111111111111111111111111	37	23
111111111111111111111111111	111111111111111111111111111	118	111

H	K	FO	FC
9	1	43	5
99	11	11	100
999	111	13	13
9999	1111	26	28
99999	11111	17	28
999999	111111	16	7
9999999	1111111	31	15
99999999	11111111	48	26
999999999	111111111	62	73
L=8			
0	0	72	761
00	00	22	223
000	000	42	444
0000	0000	20	195
00000	00000	19	190
000000	000000	43	423
0000000	0000000	40	407
00000000	00000000	23	236
000000000	000000000	25	255
0000000000	0000000000	66	655
00000000000	00000000000	88	733
000000000000	000000000000	22	207
0000000000000	0000000000000	11	135
00000000000000	00000000000000	20	184
000000000000000	000000000000000	18	188
0000000000000000	0000000000000000	22	233
00000000000000000	00000000000000000	33	327
000000000000000000	000000000000000000	22	220
0000000000000000000	0000000000000000000	33	330
00000000000000000000	00000000000000000000	55	550
000000000000000000000	000000000000000000000	40	406
0000000000000000000000	0000000000000000000000	22	240
00000000000000000000000	00000000000000000000000	41	410
000000000000000000000000	000000000000000000000000	15	157
0000000000000000000000000	0000000000000000000000000	21	210
00000000000000000000000000	00000000000000000000000000	33	333
000000000000000000000000000	000000000000000000000000000	55	555
0000000000000000000000000000	0000000000000000000000000000	40	406
00000000000000000000000000000	00000000000000000000000000000	22	240
000000000000000000000000000000	000000000000000000000000000000	41	410
0000000000000000000000000000000	0000000000000000000000000000000	15	157
00000000000000000000000000000000	00000000000000000000000000000000	21	210
000000000000000000000000000000000	000000000000000000000000000000000	33	333
0000000000000000000000000000000000	0000000000000000000000000000000000	55	555
00000000000000000000000000000000000	00000000000000000000000000000000000	40	406
000000000000000000000000000000000000	000000000000000000000000000000000000	22	240
0000000000000000000000000000000000000	0000000000000000000000000000000000000	41	410
00000000000000000000000000000000000000	00000000000000000000000000000000000000	15	157
000000000000000000000000000000000000000	000000000000000000000000000000000000000	21	210
00	00	33	333
000	00000		

H	K	F0	F1
1	8	25	27
1	0	12	11
1	2	14	14
1	3	33	34
2	5	23	24
2	7	20	20
2	9	28	29
1	4	14	18
5	6	13	15
6		20	21
		6	9

H	K	F0	F1
3	10	27	28
5	7	23	25
4	7	33	35
4	9	10	9
4	11	16	15
4	6	13	14
5	6	20	21
5	7	15	16
6	8	10	9
7	8	21	20
		26	25

H	K	F0	F1
8	9	6	6
	L =	6	
0	2	10	11
0	6	22	21
0	4	18	20
1	1	16	17
1	3	22	23
5	5	14	17
		16	15

H	K	F0	F1
1	7	13	12
2	4	16	17
2	8	18	20
2	9	9	12
3	8	14	14
3	5	14	15
4	7	14	14
5	7	11	11
5		23	23
5		22	21

H	K	FQ	FC
1		13	14
1		22	25
1		10	11
1		14	15
1		29	33
2		20	33
2		19	21
2		25	19
2		17	17
2		11	14
2		16	18

H	K	FQ	FC
3		8	11
3		25	26
3		30	27
3		10	10
3		13	13
3		13	10
3		18	21
3		15	16
3		10	10
3		17	18

H	K	FQ	FC
7		24	24
8		6	5
	L = 6		
0	2	10	10
0	4	19	20
0	6	17	18
0	8	18	17
1	3	16	17

H	K	FQ	FC
1	5	17	16
1	7	14	15
2	6	15	15
2	8	17	18
2	11	11	10
3	15	15	16
3	15	15	17
3	14	14	16
4	10	10	10
4	20	20	20
4	21	21	20

A.5 V(P0₃)₃

H	L	FC	FC	H	L	FO	FC	H	L	FO	FC	H	L	FO	FC
K=0				K=1				K=2							
11	11	14	14	11	11	45	46	6	11	17	26	11	11	27	31
11	12	13	14	11	11	55	57	6	11	22	24	11	11	18	12
11	10	11	11	11	11	74	76	6	11	31	33	11	11	18	11
11	12	11	11	11	11	32	35	6	11	42	42	11	11	35	44
11	11	11	11	11	11	44	48	6	11	35	39	11	11	26	35
11	11	11	11	11	11	41	48	6	11	50	55	11	11	18	18
11	11	11	11	11	11	22	22	6	11	23	23	11	11	55	55
11	11	11	11	11	11	11	14	6	11	5	20	11	11	20	33
11	11	11	11	11	11	73	77	6	11	5	45	11	11	67	21
11	11	11	11	11	11	12	13	6	11	96	97	11	11	67	67
11	11	11	11	11	11	44	52	6	11	64	64	11	11	52	52
11	11	11	11	11	11	37	55	6	11	114	126	11	11	65	76
11	11	11	11	11	11	66	66	6	11	39	37	11	11	71	71
11	11	11	11	11	11	55	80	6	11	37	50	11	11	34	34
11	11	11	11	11	11	55	80	6	11	37	17	11	11	99	99
11	11	11	11	11	11	40	40	6	11	104	105	11	11	22	22
11	11	11	11	11	11	44	44	6	11	54	60	11	11	99	99
11	11	11	11	11	11	21	21	6	11	103	104	11	11	22	22
11	11	11	11	11	11	73	78	6	11	110	112	11	11	25	26
11	11	11	11	11	11	27	27	6	11	47	55	11	11	11	11
11	11	11	11	11	11	55	55	6	11	33	33	11	11	40	40
11	11	11	11	11	11	20	20	6	11	19	19	11	11	25	25
11	11	11	11	11	11	33	33	6	11	34	34	11	11	44	44
11	11	11	11	11	11	33	33	6	11	10	10	11	11	66	66
11	11	11	11	11	11	44	44	6	11	7	7	11	11	66	66
11	11	11	11	11	11	44	44	6	11	10	10	11	11	66	66
11	11	11	11	11	11	15	15	6	11	36	48	11	11	31	31
11	11	11	11	11	11	66	66	6	11	12	20	11	11	15	15
11	11	11	11	11	11	79	79	6	11	51	46	11	11	30	30
11	11	11	11	11	11	13	20	6	11	94	94	11	11	14	14
11	11	11	11	11	11	27	27	6	11	30	33	11	11	47	47
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11	11	11	11	11	11	51	51	6	11	40	33	11	11	27	27
11	11	11	11	11	11	26	26	6	11	41	48	11	11	14	14
11	11	11	11	11	11	33	33	6	11	67	62	11	11	30	30
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11	11	11	11	11	11	33	33	6	11	77	83	11	11	48	48
11	11	11	11	11	11	33	33	6	11	33	48	11	11	34	34
11	11	11	11	11	11	33	33	6	11	78	78	11	11	36	36
11	11	11	11	11	11	33	33	6	11	76	76	11	11	22	22
11	11	11	11	11	11	33	33	6	11	42	42	11	11	99	99
11	11	11	11	11	11	33	33	6	11	42	68	11	11	26	26
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11	11	11	11	11	11	33	33	6	11	27	27	11	11	26	26
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